

QorlQ Integrated Processor Hardware Specifications

Datasheet DS1073



The following list provides an overview of the P2020 feature Set:

- Dual High-performance Power Architecture[®] e500 Cores
- · 36-bit Physical Addressing
 - Double-precision Floating-point Support
 - 32-Kbyte L1 instruction Cache and 32-Kbyte L1 Data Cache for each Core
 - 800-MHz to 1.33-GHz Clock Frequency
- 512 Kbyte L2 Cache with ECC. Also Configurable as SRAM and Stashing Memory
- Three 10/100/1000 Mbps Enhanced three-speed Ethernet Controllers (eTSECs)
 - TCP/IP Acceleration, Quality of Service, and Classification Capabilities
 - IEEE Std 1588™ Support
 - Lossless Flow Control
 - R/G/MII, R/TBI, SGMII
- High-speed Interfaces Supporting Various Multiplexing Options:
 - Four SerDes to 3.125 GHz Multiplexed Across Controllers
 - Three PCI Express Interfaces
 - Two Serial RapidIO Interfaces
 - Two SGMII Interfaces
- High-Speed USB Controller (USB 2.0)
 - Host and Device Support
 - Enhanced Host Controller Interface (EHCI)
 - ULPI Interface to PHY
- Enhanced Secure Digital Host Controller (SD/MMC)

Enhanced Serial Peripheral Interface (eSPI)

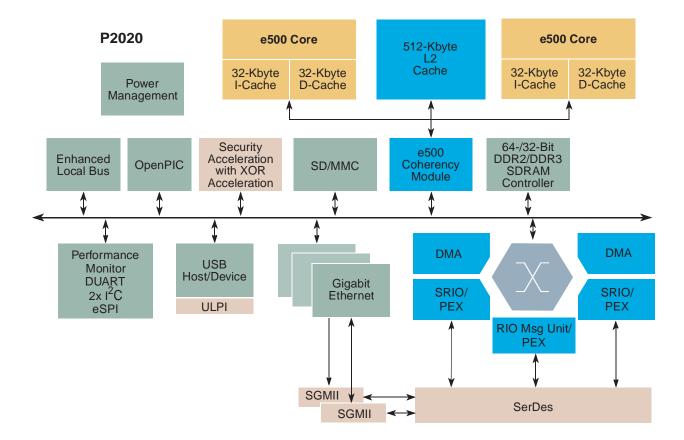
- · Integrated Security Engine
 - Protocol Support Includes SNOW, ARC4, 3DES, AES, RSA/ECC, RNG, Single-pass SSL/TLS, Kasumi
 - XOR Acceleration
- 64-bit DDR2/DDR3 SDRAM Memory Controller with ECC Support
- Programmable Interrupt Controller (PIC) Compliant with OpenPIC Standard
- Two Four-channel DMA Controllers
- Two I²C Controllers, DUART, Timers
- Enhanced Local Bus Controller (eLBC)
- 16 General-purpose I/O Signals
- Operating Junction Temperature
- 31 x 31 mm 689-pin WB-TePBGA II (Wire Bond Temperatureenhanced Plastic BGA)

An Important Notice at the end of this datasheet addresses availability, warranty, changes, use in critical applications, intellectual property matters and other important disclaimers

Block Diagram

Figure 0-1 shows the major functional units within the device.

Figure 0-1. P2020 Block Diagram



1. Pinout Assignments and Reset States

1.1 Ball Layout Diagrams

Figure 1-1 shows the top view of the P2020 689-pin BGA ball map diagram.

Figure 1-1. P2020 Top View Ballmap

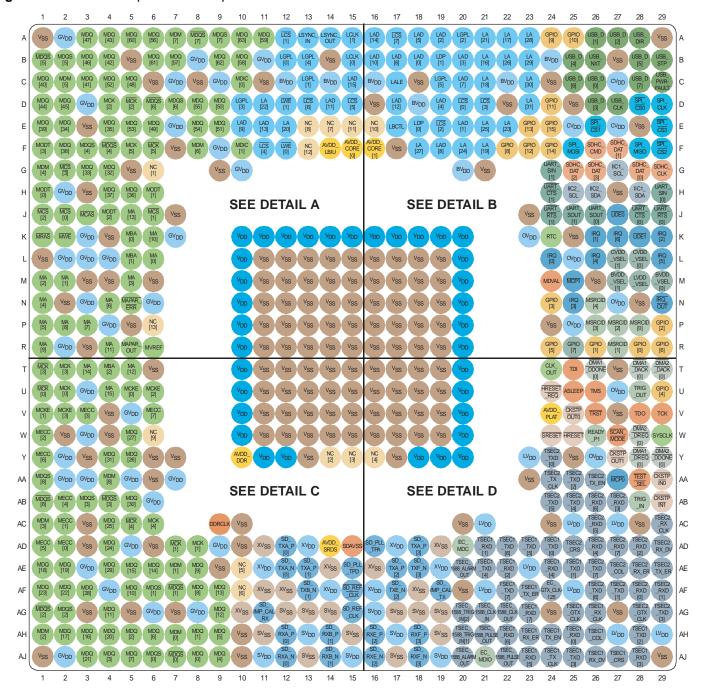


Figure 1-2. P2020 Ball Map-Detail A

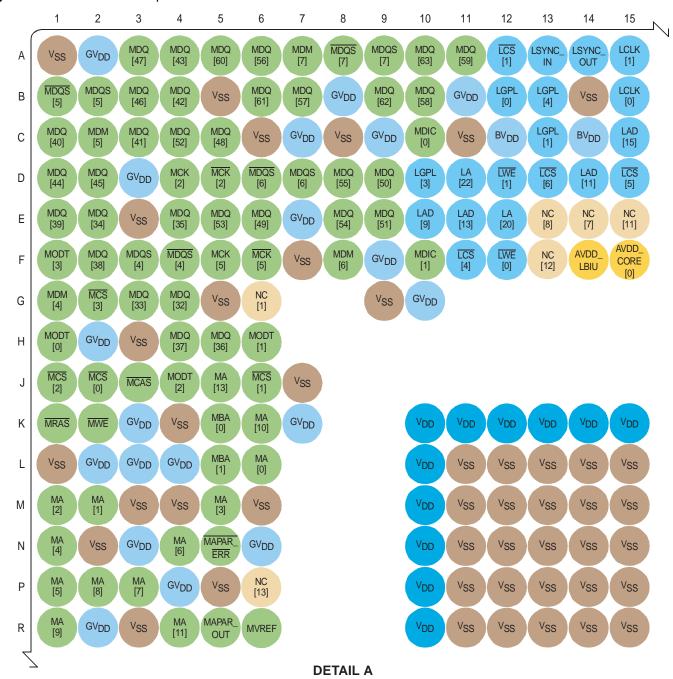


Figure 1-3. P2020 Ball Map-Detail B

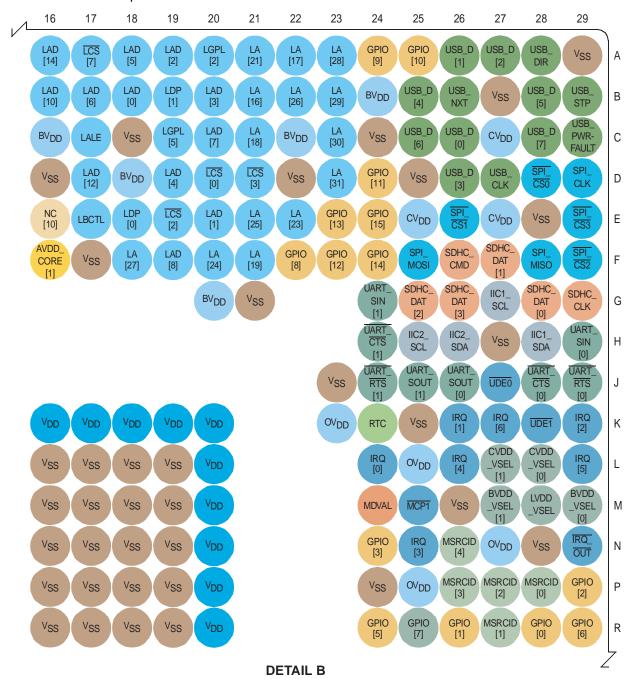


Figure 1-4. P2020 Ball Map-Detail C

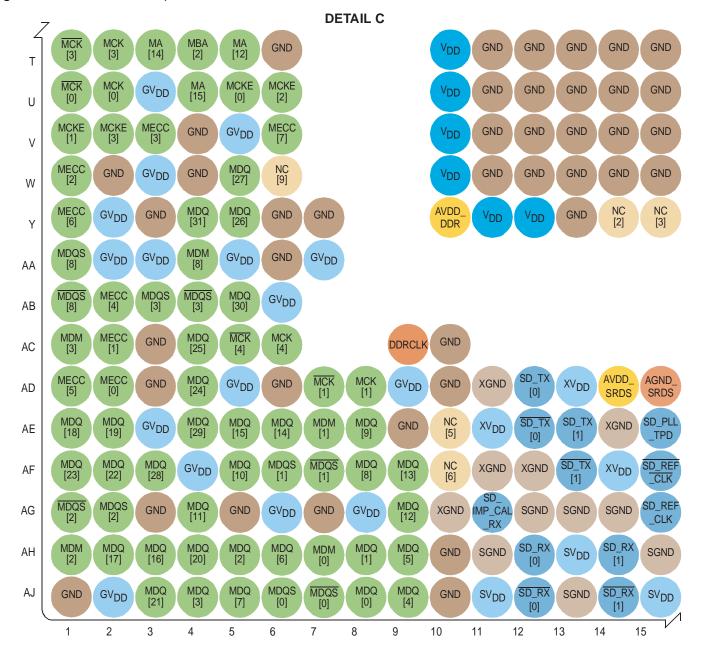


Figure 1-5. P2020 Ball Map-Detail D

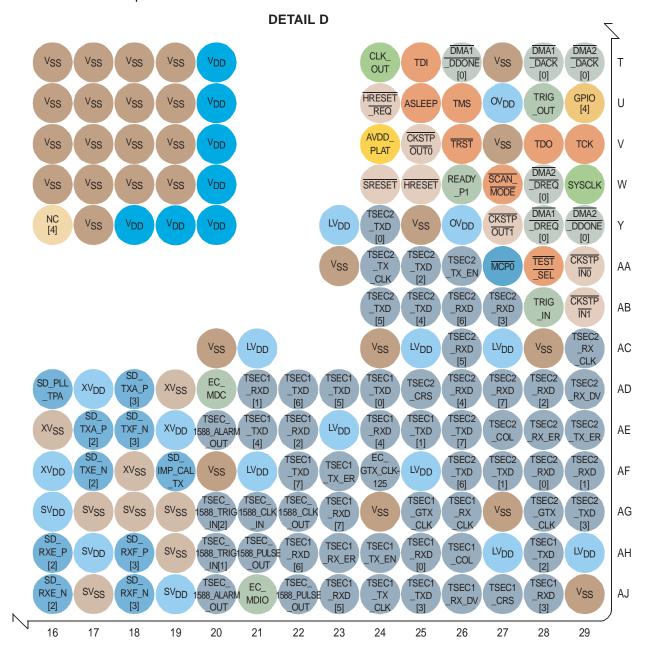


Table 1-1 provides the pinout listing for the device.

Table 1-1. P2020 Pinout Listing⁽¹⁾

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|-------------|--------------------|----------|------------------|-------|
| | DDR SDRA | M Memory Interface | | | |
| MDQ00 | Data | AJ8 | Ю | GV _{DD} | - |
| MDQ01 | Data | AH8 | 10 | GV _{DD} | _ |
| MDQ02 | Data | AH5 | 10 | GV _{DD} | _ |
| MDQ03 | Data | AJ4 | Ю | GV _{DD} | _ |
| MDQ04 | Data | AJ9 | 10 | GV _{DD} | _ |
| MDQ05 | Data | AH9 | 10 | GV _{DD} | _ |
| MDQ06 | Data | AH6 | Ю | GV _{DD} | _ |
| MDQ07 | Data | AJ5 | 10 | GV _{DD} | _ |
| MDQ08 | Data | AF8 | 10 | GV _{DD} | _ |
| MDQ09 | Data | AE8 | 10 | GV _{DD} | _ |
| MDQ10 | Data | AF5 | Ю | GV _{DD} | _ |
| MDQ11 | Data | AG4 | Ю | GV _{DD} | _ |
| MDQ12 | Data | AG9 | Ю | GV _{DD} | _ |
| MDQ13 | Data | AF9 | Ю | GV _{DD} | - |
| MDQ14 | Data | AE6 | Ю | GV _{DD} | _ |
| MDQ15 | Data | AE5 | Ю | GV _{DD} | _ |
| MDQ16 | Data | AH3 | Ю | GV _{DD} | _ |
| MDQ17 | Data | AH2 | Ю | GV _{DD} | - |
| MDQ18 | Data | AE1 | Ю | GV _{DD} | _ |
| MDQ19 | Data | AE2 | Ю | GV _{DD} | _ |
| MDQ20 | Data | AH4 | Ю | GV _{DD} | _ |
| MDQ21 | Data | AJ3 | Ю | GV _{DD} | _ |
| MDQ22 | Data | AF2 | Ю | GV _{DD} | _ |
| MDQ23 | Data | AF1 | 10 | GV _{DD} | _ |
| MDQ24 | Data | AD4 | 10 | GV _{DD} | _ |
| MDQ25 | Data | AC4 | Ю | GV _{DD} | _ |
| MDQ26 | Data | Y5 | Ю | GV _{DD} | _ |
| MDQ27 | Data | W5 | Ю | GV _{DD} | _ |
| MDQ28 | Data | AF3 | Ю | GV _{DD} | - |
| MDQ29 | Data | AE4 | Ю | GV _{DD} | - |
| MDQ30 | Data | AB5 | Ю | GV _{DD} | _ |
| MDQ31 | Data | Y4 | Ю | GV _{DD} | _ |
| MDQ32 | Data | G4 | Ю | GV _{DD} | _ |
| MDQ33 | Data | G3 | Ю | GV _{DD} | _ |
| MDQ34 | Data | E2 | Ю | GV _{DD} | _ |

 Table 1-1.
 P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------|-----------------------|--------------------|----------|------------------|-------|
| MDQ35 | Data | E4 | Ю | GV _{DD} | _ |
| MDQ36 | Data | H5 | Ю | GV _{DD} | _ |
| MDQ37 | Data | H4 | Ю | GV _{DD} | _ |
| MDQ38 | Data | F2 | Ю | GV _{DD} | _ |
| MDQ39 | Data | E1 | Ю | GV _{DD} | _ |
| MDQ40 | Data | C1 | Ю | GV _{DD} | _ |
| MDQ41 | Data | C3 | Ю | GV _{DD} | _ |
| MDQ42 | Data | B4 | Ю | GV _{DD} | _ |
| MDQ43 | Data | A4 | Ю | GV _{DD} | _ |
| MDQ44 | Data | D1 | 10 | GV _{DD} | _ |
| MDQ45 | Data | D2 | 10 | GV _{DD} | _ |
| MDQ46 | Data | B3 | 10 | GV _{DD} | _ |
| MDQ47 | Data | A3 | 10 | GV _{DD} | _ |
| MDQ48 | Data | C5 | Ю | GV _{DD} | _ |
| MDQ49 | Data | E6 | Ю | GV _{DD} | _ |
| MDQ50 | Data | D9 | Ю | GV _{DD} | - |
| MDQ51 | Data | E9 | Ю | GV _{DD} | _ |
| MDQ52 | Data | C4 | Ю | GV _{DD} | _ |
| MDQ53 | Data | E5 | Ю | GV _{DD} | - |
| MDQ54 | Data | E8 | Ю | GV _{DD} | _ |
| MDQ55 | Data | D8 | Ю | GV _{DD} | _ |
| MDQ56 | Data | A6 | Ю | GV _{DD} | _ |
| MDQ57 | Data | B7 | Ю | GV _{DD} | _ |
| MDQ58 | Data | B10 | Ю | GV _{DD} | _ |
| MDQ59 | Data | A11 | Ю | GV _{DD} | _ |
| MDQ60 | Data | A5 | Ю | GV _{DD} | _ |
| MDQ61 | Data | B6 | Ю | GV _{DD} | _ |
| MDQ62 | Data | B9 | Ю | GV _{DD} | _ |
| MDQ63 | Data | A10 | Ю | GV _{DD} | _ |
| MECC[00] | Error Correcting Code | AD2 | Ю | GV _{DD} | (36) |
| MECC[01] | Error Correcting Code | AC2 | Ю | GV _{DD} | (36) |
| MECC[02] | Error Correcting Code | W1 | Ю | GV _{DD} | (36) |
| MECC[03] | Error Correcting Code | V3 | Ю | GV _{DD} | (36) |
| MECC[04] | Error Correcting Code | AB2 | Ю | GV _{DD} | (36) |
| MECC[05] | Error Correcting Code | AD1 | Ю | GV _{DD} | (36) |
| MECC[06] | Error Correcting Code | Y1 | Ю | GV _{DD} | (36) |
| MECC[07] | Error Correcting Code | V6 | Ю | GV _{DD} | (36) |
| MAPAR_ERR | Address Parity Error | N5 | ı | GV _{DD} | (37) |

P2020

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Note |
|-----------|----------------------|--------------------|----------|------------------|------|
| MAPAR_OUT | Address Parity Error | R5 | 0 | GV _{DD} | _ |
| MDM[00] | Data Mask | AH7 | 0 | GV _{DD} | _ |
| MDM[01] | Data Mask | AE7 | 0 | GV _{DD} | _ |
| MDM[02] | Data Mask | AH1 | 0 | GV _{DD} | _ |
| MDM[03] | Data Mask | AC1 | 0 | GV _{DD} | _ |
| MDM[04] | Data Mask | G1 | 0 | GV _{DD} | _ |
| MDM[05] | Data Mask | C2 | 0 | GV _{DD} | _ |
| MDM[06] | Data Mask | F8 | 0 | GV _{DD} | _ |
| MDM[07] | Data Mask | A7 | 0 | GV _{DD} | _ |
| MDM[08] | Data Mask | AA4 | 0 | GV _{DD} | _ |
| MDQS[00] | Data Strobe | AJ6 | Ю | GV _{DD} | _ |
| MDQS[01] | Data Strobe | AF6 | Ю | GV _{DD} | _ |
| MDQS[02] | Data Strobe | AG2 | Ю | GV _{DD} | _ |
| MDQS[03] | Data Strobe | AB3 | Ю | GV _{DD} | _ |
| MDQS[04] | Data Strobe | F3 | Ю | GV _{DD} | - |
| MDQS[05] | Data Strobe | B2 | Ю | GV _{DD} | _ |
| MDQS[06] | Data Strobe | D7 | Ю | GV _{DD} | _ |
| MDQS[07] | Data Strobe | A9 | Ю | GV _{DD} | _ |
| MDQS[08] | Data Strobe | AA1 | Ю | GV _{DD} | _ |
| MDQS[00] | Data Strobe | AJ7 | Ю | GV _{DD} | _ |
| MDQS[01] | Data Strobe | AF7 | Ю | GV _{DD} | _ |
| MDQS[02] | Data Strobe | AG1 | Ю | GV _{DD} | _ |
| MDQS[03] | Data Strobe | AB4 | 10 | GV _{DD} | _ |
| MDQS[04] | Data Strobe | F4 | 10 | GV _{DD} | _ |
| MDQS[05] | Data Strobe | B1 | Ю | GV _{DD} | _ |
| MDQS[06] | Data Strobe | D6 | 10 | GV _{DD} | _ |
| MDQS[07] | Data Strobe | A8 | 10 | GV _{DD} | _ |
| MDQS[08] | Data Strobe | AB1 | 10 | GV _{DD} | _ |
| MBA[00] | Bank Select | K5 | 0 | GV _{DD} | _ |
| MBA[01] | Bank Select | L5 | 0 | GV _{DD} | _ |
| MBA[02] | Bank Select | T4 | 0 | GV _{DD} | _ |
| MA[00] | Address | L6 | 0 | GV _{DD} | _ |
| MA[01] | Address | M2 | 0 | GV _{DD} | _ |
| MA[02] | Address | M1 | 0 | GV _{DD} | _ |
| MA[03] | Address | M5 | 0 | GV _{DD} | _ |
| MA[04] | Address | N1 | 0 | GV _{DD} | _ |
| MA[05] | Address | P1 | 0 | GV _{DD} | _ |
| MA[06] | Address | N4 | 0 | GV _{DD} | _ |

 Table 1-1.
 P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|----------|---------------------------------|--------------------|----------|------------------|-------|
| MA[07] | Address | P3 | 0 | GV _{DD} | _ |
| MA[08] | Address | P2 | 0 | GV _{DD} | _ |
| MA[09] | Address | R1 | 0 | GV _{DD} | _ |
| MA[10] | Address | K6 | 0 | GV _{DD} | - |
| MA[11] | Address | R4 | 0 | GV _{DD} | - |
| MA[12] | Address | T5 | 0 | GV _{DD} | - |
| MA[13] | Address | J5 | 0 | GV _{DD} | _ |
| MA[14] | Address | Т3 | 0 | GV _{DD} | - |
| MA[15] | Address | U4 | 0 | GV _{DD} | _ |
| MWE | Write Enable | K2 | 0 | GV _{DD} | - |
| MRAS | Row Address Strobe | K1 | 0 | GV _{DD} | _ |
| MCAS | Column Address Strobe | J3 | 0 | GV _{DD} | - |
| MCS[00] | Chip Select | J2 | 0 | GV _{DD} | _ |
| MCS[01] | Chip Select | J6 | 0 | GV _{DD} | - |
| MCS[02] | Chip Select | J1 | 0 | GV _{DD} | _ |
| MCS[03] | Chip Select | G2 | 0 | GV _{DD} | - |
| MCKE[00] | Clock Enable | U5 | 0 | GV _{DD} | |
| MCKE[01] | Clock Enable | V1 | 0 | GV _{DD} | |
| MCKE[02] | Clock Enable | U6 | 0 | GV _{DD} | |
| MCKE[03] | Clock Enable | V2 | 0 | GV _{DD} | (9) |
| MCK[00] | Clock | U2 | 0 | GV _{DD} | (32) |
| MCK[01] | Clock | AD8 | 0 | GV _{DD} | (32) |
| MCK[02] | Clock | D4 | 0 | GV _{DD} | (32) |
| MCK[03] | Clock | T2 | 0 | GV _{DD} | (32) |
| MCK[04] | Clock | AC6 | 0 | GV _{DD} | (32) |
| MCK[05] | Clock | F5 | 0 | GV _{DD} | (32) |
| MCK[00] | Clock Complements | U1 | 0 | GV _{DD} | (32) |
| MCK[01] | Clock Complements | AD7 | 0 | GV _{DD} | (32) |
| MCK[02] | Clock Complements | D5 | 0 | GV _{DD} | (32) |
| MCK[03] | Clock Complements | T1 | 0 | GV _{DD} | (32) |
| MCK[04] | Clock Complements | AC5 | 0 | GV _{DD} | (32) |
| MCK[05] | Clock Complements | F6 | 0 | GV _{DD} | (32) |
| MODT[00] | On Die Termination | H1 | 0 | GV _{DD} | _ |
| MODT[01] | On Die Termination | H6 | 0 | GV _{DD} | _ |
| MODT[02] | On Die Termination | J4 | 0 | GV _{DD} | _ |
| MODT[03] | On Die Termination | F1 | 0 | GV _{DD} | _ |
| MDIC[00] | Driver Impedance Calibration | C10 | Ю | GV _{DD} | (18) |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|------------|-----------------------------------|-------------------------|----------|------------------|---------|
| MDIC[01] | Driver Impedance Calibration | F10 | Ю | GV _{DD} | (18) |
| | S | erDes | | | |
| SD_TX[03] | Transmit Data (positive) | AD18 | 0 | XV_{DD} | _ |
| SD_TX[02] | Transmit Data (positive) | AE17 | 0 | XV_{DD} | _ |
| SD_TX[01] | Transmit Data (positive) | AE13 | 0 | XV _{DD} | _ |
| SD_TX[00] | Transmit Data (positive) | AD12 | 0 | XV_{DD} | _ |
| SD_TX[03] | Transmit Data (negative) | AE18 | 0 | XV _{DD} | _ |
| SD_TX[02] | Transmit Data (negative) | AF17 | 0 | XV_{DD} | _ |
| SD_TX[01] | Transmit Data (negative) | AF13 | 0 | XV_{DD} | _ |
| SD_TX[00] | Transmit Data (negative) | AE12 | 0 | XV _{DD} | _ |
| SD_RX[03] | Receive Data (positive) | AH18 | I | XV_{DD} | _ |
| SD_RX[02] | Receive Data (positive) | AH16 | I | XV_{DD} | _ |
| SD_RX[01] | Receive Data (positive) | AH14 | I | XV_{DD} | _ |
| SD_RX[00] | Receive Data (positive) | AH12 | I | XV_{DD} | _ |
| SD_RX[03] | Receive Data (negative) | AJ18 | I | XV_{DD} | _ |
| SD_RX[02] | Receive Data (negative) | AJ16 | I | XV_{DD} | - |
| SD_RX[01] | Receive Data (negative) | AJ14 | 1 | XV _{DD} | _ |
| SD_RX[00] | Receive Data (negative) | AJ12 | 1 | XV _{DD} | _ |
| SD_REF_CLK | PLL Reference Clock | AG15 | I | XV_{DD} | _ |
| SD_REF_CLK | PLL Reference Clock Complement | AF15 | I | XV _{DD} | _ |
| | Enhanced Local B | us Controller Interface | • | | |
| LAD[00] | Muxed Data/Address | B18 | Ю | BV _{DD} | (4)(23) |
| LAD[01] | Muxed Data/Address | E20 | Ю | BV _{DD} | (4)(23) |
| LAD[02] | Muxed Data/Address | A19 | Ю | BV _{DD} | (4)(23) |
| LAD[03] | Muxed Data/Address | B20 | Ю | BV _{DD} | (4)(23) |
| LAD[04] | Muxed Data/Address | D19 | Ю | BV _{DD} | (4)(23) |
| LAD[05] | Muxed Data/Address | A18 | Ю | BV _{DD} | (4)(23) |
| LAD[06] | Muxed Data/Address | B17 | Ю | BV _{DD} | (4)(23) |
| LAD[07] | Muxed Data/Address | C20 | Ю | BV _{DD} | (4)(23) |
| LAD[08] | Muxed Data/Address | F19 | 10 | BV _{DD} | (4)(23) |
| LAD[09] | Muxed Data/Address | E10 | 10 | BV _{DD} | (4)(23) |
| LAD[10] | Muxed Data/Address | B16 | 10 | BV _{DD} | (4)(23) |
| LAD[11] | Muxed Data/Address | D14 | Ю | BV _{DD} | (4)(23) |
| LAD[12] | Muxed Data/Address | D17 | 10 | BV _{DD} | (4)(23 |
| LAD[13] | Muxed Data/Address | E11 | 10 | BV _{DD} | (4)(23) |
| LAD[14] | Muxed Data/Address | A16 | 10 | BV _{DD} | (4)(23) |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------|---|--------------------|----------|------------------|----------|
| LAD[15] | Muxed Data/Address | C15 | Ю | BV _{DD} | (4)(23) |
| LDP[00] | Data Parity | E18 | Ю | BV _{DD} | _ |
| LDP[01] | Data Parity | B19 | Ю | BV _{DD} | _ |
| LA[16] | Address | B21 | 0 | BV _{DD} | (7)(25) |
| LA[17] | Address | A22 | 0 | BV _{DD} | (15) |
| LA[18] | Address | C21 | 0 | BV _{DD} | (4)(7) |
| LA[19] | Address | F21 | 0 | BV _{DD} | (4)(7) |
| LA[20] | Address | E12 | 0 | BV _{DD} | (4)(7)(2 |
| LA[21] | Address | A21 | 0 | BV _{DD} | (4)(7)(2 |
| LA[22] | Address | D11 | 0 | BV _{DD} | (4)(7)(2 |
| LA[23] | Address | E22 | 0 | BV _{DD} | (4)(7) |
| LA[24] | Address | F20 | 0 | BV _{DD} | (4)(7) |
| LA[25] | Address | E21 | 0 | BV _{DD} | (4)(7) |
| LA[26] | Address | B22 | 0 | BV _{DD} | (4)(7) |
| LA[27] | Address | F18 | 0 | BV _{DD} | (7)(25 |
| LA[28] | Address | A23 | 0 | BV _{DD} | (4)(7) |
| LA[29] | Address | B23 | 0 | BV _{DD} | (5)(7) |
| LA[30] | Address | C23 | 0 | BV _{DD} | (5)(7) |
| LA[31] | Address | D23 | 0 | BV _{DD} | (5)(7) |
| LCS[00] | Chip Selects | D20 | 0 | BV _{DD} | (8) |
| LCS[01] | Chip Selects | A12 | 0 | BV _{DD} | (8) |
| LCS[02] | Chip Selects | E19 | 0 | BV _{DD} | (8) |
| LCS[03] | Chip Selects | D21 | 0 | BV _{DD} | (8) |
| LCS[04] | Chip Selects | F11 | 0 | BV _{DD} | (8) |
| LCS[05]/DMA2_DREQ[01] | Chip Selects | D15 | 0 | BV _{DD} | (8) |
| LCS[06]/DMA2_DACK[01] | Chip Selects | D13 | 0 | BV _{DD} | (8) |
| LCS[07]/DMA2_DDONE[01] | Chip Selects | A17 | 0 | BV _{DD} | (8) |
| LWE[00]/LBS[00] | Write Enable | F12 | 0 | BV _{DD} | (6)(7) |
| LWE[01]/LBS[01] | Write Enable | D12 | 0 | BV _{DD} | (4)(7) |
| LBCTL | Buffer Control | E17 | 0 | BV _{DD} | (6) |
| LALE | Address Latch Enable | C17 | 0 | BV _{DD} | (6) |
| LGPL[00]/LFCLE | UPM General Purpose Line 0/Flash Command Latch Enable | B12 | 0 | BV _{DD} | (4) |
| LGPL[01]/LFALE | UPM General Purpose Line 1/Flash Addr Latch Enable | C13 | 0 | BV_{DD} | (4) |
| LGPL[02]/LOE/LFRE | UPM General Purpose Line 2/Output Enable/ Flash Read Enable | A20 | 0 | BV _{DD} | (6) |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Note |
|--------------------------------------|---|----------------------|----------|------------------|------|
| LGPL[03]/LFWP | UPM General Purpose Line 3/Flash Write Protect | D10 | 0 | BV _{DD} | (4 |
| LGPL[04]/LGTA/LFRB/ LUPWAIT/LPBSE | UPM General Purpose Line 4/Txn Termination/ Wait/Flash Ready-Busy | B13 | 0 | BV _{DD} | (34 |
| LGPL[05] | UPM General Purpose Line 5/Addr mux | C19 | 0 | BV _{DD} | (4 |
| LCLK[00] | Local Bus Clock | B15 | 0 | BV _{DD} | _ |
| LCLK[01] | Local Bus Clock | A15 | 0 | BV _{DD} | _ |
| LSYNC_IN | Local Bus DLL Synchronization | A13 | 1 | BV _{DD} | - |
| LSYNC_OUT | Local Bus DLL Synchronization | A14 | 0 | BV _{DD} | _ |
| | | DMA | | | • |
| DMA1_DREQ | DMA1 Channel 0 Request | Y28 | I | OV_{DD} | _ |
| DMA2_DREQ | DMA2 Channel 0 Request | W28 | ı | OV _{DD} | _ |
| DMA1_DACK | DMA1 Channel 0 Acknowledge | T28 | 0 | OV _{DD} | (1: |
| DMA2_DACK | DMA2 Channel 0 Acknowledge | T29 | 0 | OV _{DD} | (4) |
| DMA1_DDONE | DMA1 Channel 0 Done | T26 | 0 | OV _{DD} | (7)(|
| DMA2_DDONE | DMA2 Channel 0 Done | Y29 | 0 | OV_{DD} | (4) |
| | Programmable | Interrupt Controller | | | |
| UDE0 | Unconditional Debug Event Proc 0 | J27 | 1 | OV_{DD} | _ |
| UDE1 | Unconditional Debug Event Proc 1 | K28 | 1 | OV _{DD} | - |
| MCP0 | Machine Check Processor 0 | AA27 | I | OV_{DD} | _ |
| MCP1 | Machine Check Processor 1 | M25 | 1 | OV_{DD} | - |
| IRQ[00] | External Interrupts | L24 | I | OV_{DD} | - |
| IRQ[01] | External Interrupts | K26 | I | OV_{DD} | - |
| IRQ[02] | External Interrupts | K29 | I | OV_{DD} | _ |
| IRQ[03] | External Interrupts | N25 | I | OV_{DD} | - |
| IRQ[04] | External Interrupts | L26 | I | OV_{DD} | - |
| IRQ[05] | External Interrupts | L29 | 1 | OV_{DD} | - |
| IRQ[06] | External Interrupts | K27 | I | OV_{DD} | _ |
| IRQ_OUT | Interrupt Output | N29 | 0 | OV_{DD} | (2) |
| | Volta | ige Select | | | |
| LVDD_VSEL | Voltage Select | M28 | I | OV _{DD} | (22 |
| BVDD_VSEL[00] | Voltage Select | M29 | ı | OV _{DD} | (2: |
| BVDD_VSEL[01] | Voltage Select | M27 | I | OV_{DD} | (2: |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------------|------------------------|----------------------|----------|------------------|--------|
| CVDD_VSEL[00] | Voltage Select | L28 | 1 | OV_{DD} | (22) |
| CVDD_VSEL[01] | Voltage Select | L27 | 1 | OV_{DD} | (22) |
| | | 1588 | | | |
| TSEC_1588_CLK_IN | Clock In | AG21 | 1 | LV _{DD} | _ |
| TSEC_1588_TRIG_IN1 | Trigger In 1 | AH20 | I | LV_DD | _ |
| TSEC_1588_TRIG_IN2 | Trigger In 2 | AG20 | 1 | LV _{DD} | _ |
| TSEC_1588_ALARM_OUT01 | Trigger Out 1 | AE20 | 0 | LV _{DD} | (4)(7) |
| TSEC_1588_ALARM_OUT02 | Trigger Out 2 | AJ20 | 0 | LV _{DD} | (4)(7) |
| TSEC_1588_CLK_OUT | Clock Out | AG22 | 0 | LV _{DD} | (24) |
| TSEC_1588_PULSE_OUT[01] | Pulse Out 1 | AH21 | 0 | LV _{DD} | (24) |
| TSEC_1588_PULSE_OUT[02] | Pulse Out 2 | AJ22 | 0 | LV_DD | (24) |
| | Ethernet Man | agement Interface | I | l | |
| EC_MDC | Management Data Clock | AD20 | 0 | LV _{DD} | (4)(7) |
| EC_MDIO | Management Data In/Out | AJ21 | Ю | LV _{DD} | _ |
| | Gigabit Etherr | net Reference Clock | I | | 1 |
| EC_GTX_CLK125 | Reference Clock | AF24 | 1 | LV _{DD} | (20) |
| | Three Speed E | thernet Controller 1 | I | | 1 |
| TSEC1_TXD[07]/TSEC3_TXD [03] | Transmit Data | AF22 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[06]/TSEC3_TXD [02] | Transmit Data | AD22 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[05]/TSEC3_TXD [01] | Transmit Data | AD23 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[04]/TSEC3_TXD [00] | Transmit Data | AE21 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[03] | Transmit Data | AJ25 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[02] | Transmit Data | AH28 | 0 | LV_DD | (4)(7) |
| TSEC1_TXD[01] | Transmit Data | AE25 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TXD[00] | Transmit Data | AD24 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TX_EN | Transmit Enable | AH24 | 0 | LV_DD | (16) |
| TSEC1_TX_ER | Transmit Error | AF23 | 0 | LV _{DD} | (4)(7) |
| TSEC1_TX_CLK | Transmit Clock | AJ24 | Ţ | LV _{DD} | _ |
| TSEC1_GTX_CLK | Transmit Clock Out | AG25 | 0 | LV_DD | _ |
| TSEC1_CRS/TSEC3_RX_DV | Carrier Sense | AJ27 | Ю | LV _{DD} | _ |
| TSEC1_COL/TSEC3_RX_CLK | Collision Detect | AH26 | Ţ | LV _{DD} | _ |
| TSEC1_RXD[07]/TSEC3_RXD [03] | Receive Data | AG23 | 1 | LV_DD | _ |
| TSEC1_RXD[06]/TSEC3_RXD [02] | Receive Data | AH22 | 1 | LV _{DD} | _ |
| TSEC1_RXD[05]/TSEC3_RXD [01] | Receive Data | AJ23 | 1 | LV _{DD} | _ |
| TSEC1_RXD[04]/TSEC3_RXD [00] | Receive Data | AE24 | 1 | LV _{DD} | _ |
| TSEC1_RXD[03] | Receive Data | AJ28 | 1 | LV _{DD} | _ |
| TSEC1_RXD[02] | Receive Data | AE22 | 1 | LV _{DD} | _ |
| TSEC1_RXD[01] | Receive Data | AD21 | ı | LV _{DD} | _ |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------------------------|--------------------|-----------------------|----------|--------------------|------------|
| TSEC1_RXD[00] | Receive Data | AH25 | I | LV _{DD} | _ |
| TSEC1_RX_DV | Receive Data Valid | AJ26 | I | LV _{DD} | _ |
| TSEC1_RX_ER | Receive Error | AH23 | I | LV _{DD} | _ |
| TSEC1_RX_CLK | Receive Clock | AG26 | I | LV _{DD} | _ |
| | Three Speed I | Ethernet Controller 2 | | | |
| TSEC2_TXD[07] | Transmit Data | AE26 | 0 | LV _{DD} | (4)(7) |
| TSEC2_TXD[06] | Transmit Data | AF26 | 0 | LV _{DD} | (15) |
| TSEC2_TXD[05]/TSEC3_TX_ EN | Transmit Data | AB24 | 0 | LV _{DD} | (4)(7)(16) |
| TSEC2_TXD[04]/TSEC3_GTX_CLK | Transmit Data | AB25 | 0 | LV _{DD} | (4)(7) |
| TSEC2_TXD[03] | Transmit Data | AG29 | 0 | LV _{DD} | (4)(7) |
| TSEC2_TXD[02] | Transmit Data | AA25 | 0 | LV _{DD} | (4)(7) |
| TSEC2_TXD[01] | Transmit Data | AF27 | 0 | LV _{DD} | (4)(7)(17) |
| TSEC2_TXD[00] | Transmit Data | Y24 | 0 | LV _{DD} | (4)(7) |
| TSEC2_TX_EN | Transmit Enable | AA26 | 0 | LV _{DD} | (16) |
| TSEC2_TX_ER | Transmit Error | AE29 | 0 | LV_DD | (4)(7) |
| TSEC2_TX_CLK | Transmit Clock In | AA24 | I | LV _{DD} | _ |
| TSEC2_GTX_CLK | Transmit Clock Out | AG28 | 0 | LV_DD | _ |
| TSEC2_CRS/TSE3_RX_ER | Carrier Sense | AD25 | Ю | LV_DD | _ |
| TSEC2_COL/TSEC3_TX_CLK | Collision Detect | AE27 | I | LV_DD | _ |
| TSEC2_RXD[07] | Receive Data | AD27 | I | LV _{DD} | _ |
| TSEC2_RXD[06] | Receive Data | AB26 | I | LV _{DD} | _ |
| TSEC2_RXD[05] | Receive Data | AC26 | I | LV _{DD} | _ |
| TSEC2_RXD[04] | Receive Data | AD26 | I | LV _{DD} | _ |
| TSEC2_RXD[03] | Receive Data | AB27 | I | LV _{DD} | _ |
| TSEC2_RXD[02] | Receive Data | AD28 | I | LV _{DD} | _ |
| TSEC2_RXD[01] | Receive Data | AF29 | I | LV _{DD} | _ |
| TSEC2_RXD[00] | Receive Data | AF28 | I | LV _{DD} | _ |
| TSEC2_RX_DV | Receive Data Valid | AD29 | I | LV _{DD} | _ |
| TSEC2_RX_ER | Receive Error | AE28 | I | LV _{DD} | _ |
| TSEC2_RX_CLK | Transmit Clock In | AC29 | I | LV _{DD} | _ |
| <u>.</u> | | DUART | | | |
| UART0_SOUT | Transmit Data | J26 | 0 | OV_{DD} | (21) |
| UART1_SOUT | Transmit Data | J25 | 0 | OV _{DD} | (6) |
| UARTO_SIN | Receive Data | H29 | I | OV _{DD} | _ |
| UART1_SIN | Receive Data | G24 | I | $OV_{\mathtt{DD}}$ | _ |
| UARTO_CTS | Clear to Send | J28 | I | OV _{DD} | _ |
| UART1_CTS | Clear to Send | H24 | I | OV _{DD} | _ |
| UARTO_RTS | Ready to Send | J29 | 0 | OV_{DD} | (4) |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Note |
|--------------------------|----------------------------------|--------------------|----------|------------------|--------|
| UART1_RTS | Ready to Send | J24 | 0 | OV_{DD} | (4) |
| | | I2C | | | |
| IIC1_SDA | Serial Data | H28 | Ю | OV_{DD} | (3)(14 |
| IIC1_SCL | Serial Clock | G27 | 10 | OV_{DD} | (3)(1 |
| IIC2_SDA | Serial Data | H26 | 10 | OV_{DD} | (3)(1 |
| IIC2_SCL | Serial Clock | H25 | 10 | OV _{DD} | (3)(1 |
| | е | SDHC | | | |
| SDHC_DATA[00] | Data | G28 | Ю | CV _{DD} | _ |
| SDHC_DATA[01] | Data | F27 | 10 | CV _{DD} | _ |
| SDHC_DATA[02] | Data | G25 | Ю | CV _{DD} | _ |
| SDHC_DATA[03] | Data | G26 | Ю | CV _{DD} | _ |
| SDHC_CMD | Command/Response | F26 | Ю | CV _{DD} | _ |
| SDHC_CLK | Host to Card Clock | G29 | Ю | CV _{DD} | _ |
| | | eSPI | | | |
| SPI_MISO | Master In Slave Out | F28 | I | CV _{DD} | _ |
| SPI_MOSI | Master Out Slave In | F25 | Ю | CV _{DD} | _ |
| SPI_CS[00]/SDHC_DATA[04] | eSPI chip select | D28 | Ю | CV _{DD} | _ |
| SPI_CS[01]/SDHC_DATA[05] | eSPI chip select | E26 | 10 | CV _{DD} | _ |
| SPI_CS[02]/SDHC_DATA[06] | eSPI chip select | F29 | Ю | CV _{DD} | - |
| SPI_CS[03]/SDHC_DATA[07] | eSPI chip select | E29 | Ю | CV _{DD} | _ |
| SPI_CLK | eSPI clock | D29 | 0 | CV _{DD} | - |
| | | USB | | | |
| USB_NXT | USB Next data | B26 | I | CV _{DD} | _ |
| USB_DIR | USB Data Direction | A28 | I | CV _{DD} | - |
| USB_STP | USB Stop | B29 | 0 | CV _{DD} | (15 |
| USB_PWRFAULT | Power Fault | C29 | ļ | CV _{DD} | ı |
| USB_CLK | USB Bus Clock | D27 | I | CV _{DD} | _ |
| USB_D[07] | USB Data Bits | C28 | I/O | CV _{DD} | - |
| USB_D[06] | USB Data Bits | C25 | I/O | CV _{DD} | ı |
| USB_D[05] | USB Data Bits | B28 | I/O | CV _{DD} | - |
| USB_D[04] | USB Data Bits | B25 | I/O | CV _{DD} | _ |
| USB_D[03] | USB Data Bits | D26 | I/O | CV _{DD} | ı |
| USB_D[02] | USB Data Bits | A27 | I/O | CV _{DD} | ı |
| USB_D[01] | USB Data Bits | A26 | I/O | CV _{DD} | ı |
| USB_D[00] | USB Data Bits | C26 | I/O | CV _{DD} | ı |
| | General-Purp | oose Input/Output | | | |
| GPIO[00]/IRQ[07] | General-Purpose Input/ Output | R28 | Ю | OV_{DD} | _ |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|--------------------|----------------------------------|--------------------|----------|------------------|-------|
| GPIO[01]/IRQ[08] | General-Purpose Input/ Output | R26 | Ю | OV _{DD} | - |
| GPIO[02]/IRQ[09] | General-Purpose Input/ Output | P29 | Ю | OV_{DD} | ı |
| GPIO[03]/IRQ[10] | General-Purpose Input/ Output | N24 | Ю | OV _{DD} | - |
| GPIO[04]/IRQ[11] | General-Purpose Input/ Output | U29 | Ю | OV _{DD} | - |
| GPIO[05] | General-Purpose Input/ Output | R24 | 10 | OV_{DD} | _ |
| GPIO[06] | General-Purpose Input/ Output | R29 | 10 | OV _{DD} | - |
| GPIO[07] | General-Purpose Input/ Output | R25 | Ю | OV _{DD} | _ |
| GPIO[08]/SDHC_CD | General-Purpose Input/ Output | F22 | Ю | BV _{DD} | (31) |
| GPIO[09]/SDHC_WP | General-Purpose Input/ Output | A24 | Ю | BV _{DD} | _ |
| GPIO[10]/USB_PCTL0 | General-Purpose Input/ Output | A25 | Ю | BV _{DD} | _ |
| GPIO[11]/USB_PCTL1 | General-Purpose Input/ Output | D24 | Ю | BV _{DD} | - |
| GPIO[12] | General-Purpose Input/ Output | F23 | Ю | BV _{DD} | - |
| GPIO[13] | General-Purpose Input/ Output | E23 | Ю | BV _{DD} | - |
| GPIO[14] | General-Purpose Input/ Output | F24 | Ю | BV _{DD} | - |
| GPIO[15] | General-Purpose Input/ Output | E24 | Ю | BV _{DD} | _ |
| | Sys | tem Control | | | |
| HRESET | Hard Reset | W25 | I | OV _{DD} | _ |
| HRESET_REQ | Reset Request | U24 | 0 | OV_{DD} | (15) |
| SRESET | Soft Reset | W24 | I | OV_{DD} | _ |
| CKSTP_IN0 | Checkstop In | AA29 | I | OV_{DD} | (2) |
| CKSTP_IN1 | Checkstop In | AB29 | ı | OV _{DD} | (2) |
| CKSTP_OUT[00] | Checkstop Out | V25 | 0 | OV_{DD} | (2)(3 |
| CKSTP_OUT[01] | Checkstop Out | Y27 | 0 | OV_{DD} | (2)(3 |
| | | Debug | | | |
| TRIG_IN | Trigger In | AB28 | I | OV _{DD} | _ |
| TRIG_OUT | Trigger Out | U28 | 0 | OV _{DD} | (7) |
| READY_P1 | READY | W26 | 0 | OV _{DD} | (6)(7 |
| MSRCID[00] | Debug Source ID 0 | P28 | 0 | OV_{DD} | (4) |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|------------|-------------------|--------------------|----------|-------------------------|-----------|
| MSRCID[01] | Debug Source ID 1 | R27 | 0 | OV_{DD} | (21) |
| MSRCID[02] | Debug Source ID 2 | P27 | 0 | OV_{DD} | (15) |
| MSRCID[03] | Debug Source ID 3 | P26 | 0 | OV _{DD} | (15) |
| MSRCID[04] | Debug Source ID 4 | N26 | 0 | OV_{DD} | (21) |
| MDVAL | Debug Data Valid | M24 | 0 | OV_{DD} | (15) |
| | · | Clocks | | | |
| CLK_OUT | Clock Out | T24 | 0 | OV_{DD} | _ |
| RTC | Real Time Clock | K24 | 1 | OV_{DD} | _ |
| DDRCLK | DDR Clock | AC9 | I | OV_{DD} | (19) |
| SYSCLK | System Clock | W29 | I | OV_{DD} | _ |
| | | DFT | l . | l | I |
| SCAN_MODE | Scan Mode | W27 | 1 | OV_{DD} | (33) |
| TEST SEL | Test Select | AA28 | I | OV _{DD} | (29) |
| | | JTAG | | | l |
| TCK | Test Clock | V29 | 1 | OV _{DD} | _ |
| TDI | Test Data In | T25 | I | OV _{DD} | (10) |
| TDO | Test Data Out | V28 | 0 | OV _{DD} | (9) |
| TMS | Test Mode Select | U26 | 1 | OV _{DD} | (10) |
| TRST | Test Reset | V26 | 1 | OV _{DD} | (10) |
| | Power | · Management | | | l |
| ASLEEP | Asleep | U25 | 0 | OV_{DD} | (7)(11)(1 |
| | • | Connect | | | |
| NC1 | No Connection | AE10 | NC | OV_{DD} | _ |
| NC2 | No Connection | AF10 | NC | OV _{DD} | _ |
| NC3 | No Connection | E13 | NC | OV _{DD} | _ |
| NC4 | No Connection | E14 | NC | OV _{DD} | _ |
| NC5 | No Connection | W6 | NC | OV _{DD} | _ |
| NC6 | No Connection | Y14 | NC | OV _{DD} | _ |
| NC7 | No Connection | Y15 | NC | OV _{DD} | _ |
| NC8 | No Connection | Y16 | NC | OV _{DD} | _ |
| NC9 | No Connection | G6 | NC | OV _{DD} | _ |
| NC12 | No Connection | F13 | NC | _ | _ |
| NC13 | No Connection | P6 | NC | _ | _ |
| | Power and | d Ground Signals | | <u> </u> | |
| AGND_SRDS | SerDes PLL GND | AD15 | _ | _ | _ |
| AVDD_CORE0 | Core PLL0 Supply | F15 | _ | AV _{DD} _core0 | (13)(26 |
| AVDD_CORE1 | Core PLL1 Supply | F16 | _ | AV _{DD} _core1 | (13)(26 |
| AVDD_DDR | DDR PLL Supply | Y10 | _ | AV _{DD} _DDR | (13) |

P2020

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------|------------------------|--------------------|----------|------------------------|-------|
| AVDD_LBIU | Local Bus PLL Supply | F14 | - | AV _{DD} _LBIU | (13) |
| AVDD_PLAT | Platform PLL Supply | V24 | _ | AV _{DD} _PLAT | (13) |
| AVDD_SRDS | SerDes PLL Supply | AD14 | _ | AV _{DD} _SRDS | (13) |
| BVDD | Local Bus, GPIO Supply | B24 | _ | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | C12 | - | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | C14 | _ | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | C16 | _ | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | C22 | _ | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | D18 | _ | BV _{DD} | _ |
| BVDD | Local Bus, GPIO Supply | G20 | _ | BV _{DD} | _ |
| CVDD | SPI, eSDHC, USB Supply | C27 | _ | CV _{DD} | _ |
| CVDD | SPI, eSDHC, USB Supply | E25 | _ | CV _{DD} | _ |
| CVDD | SPI, eSDHC, USB Supply | E27 | _ | CV _{DD} | _ |
| GVDD | DDR Supply | A2 | - | GV _{DD} | _ |
| GVDD | DDR Supply | B8 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | B11 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | C7 | - | GV _{DD} | _ |
| GVDD | DDR Supply | C9 | - | GV _{DD} | - |
| GVDD | DDR Supply | D3 | - | GV _{DD} | _ |
| GVDD | DDR Supply | E7 | - | GV _{DD} | _ |
| GVDD | DDR Supply | F9 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | G10 | - | GV _{DD} | - |
| GVDD | DDR Supply | H2 | - | GV _{DD} | _ |
| GVDD | DDR Supply | K3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | K7 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | L2 | - | GV _{DD} | _ |
| GVDD | DDR Supply | L3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | L4 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | N3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | N6 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | P4 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | R2 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | U3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | V5 | - | GV _{DD} | - |
| GVDD | DDR Supply | W3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | Y2 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AA2 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AA3 | _ | GV _{DD} | _ |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------|---------------------------|--------------------|----------|-----------------------|-------|
| GVDD | DDR Supply | AA5 | _ | GV _{DD} | ı |
| GVDD | DDR Supply | AA7 | - | GV _{DD} | 1 |
| GVDD | DDR Supply | AB6 | _ | GV _{DD} | - |
| GVDD | DDR Supply | AD5 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AD9 | _ | GV _{DD} | - |
| GVDD | DDR Supply | AE3 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AF4 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AG6 | _ | GV _{DD} | - |
| GVDD | DDR Supply | AG8 | _ | GV _{DD} | _ |
| GVDD | DDR Supply | AJ2 | - | GV _{DD} | _ |
| LVDD | TSEC I/O Supply | Y23 | _ | LV _{DD} | _ |
| LVDD | TSEC I/O Supply | AC21 | _ | LV _{DD} | _ |
| LVDD | TSEC I/O Supply | AC25 | - | LV_DD | - |
| LVDD | TSEC I/O Supply | AC27 | _ | LV_DD | - |
| LVDD | TSEC I/O Supply | AE23 | - | LV _{DD} | - |
| LVDD | TSEC I/O Supply | AF21 | _ | LV _{DD} | _ |
| LVDD | TSEC I/O Supply | AF25 | _ | LV_DD | - |
| LVDD | TSEC I/O Supply | AH27 | _ | LV _{DD} | _ |
| LVDD | TSEC I/O Supply | AH29 | _ | LV _{DD} | _ |
| SVDD_SRDS | SerDes Core Logic Supply | AG16 | _ | SV _{DD_SRDS} | _ |
| SVDD_SRDS | SerDes Core Logic Supply | AH13 | - | SV _{DD_SRDS} | - |
| SVDD_SRDS | SerDes Core Logic Supply | AH17 | - | SV _{DD_SRDS} | - |
| SVDD_SRDS | SerDes Core Logic Supply | AJ11 | _ | SV _{DD_SRDS} | _ |
| SVDD_SRDS | SerDes Core Logic Supply | AJ15 | _ | SV _{DD_SRDS} | _ |
| SVDD_SRDS | SerDes Core Logic Supply | AJ19 | _ | SV _{DD_SRDS} | - |
| SGND_SRDS | SerDes Core Logic GND | AG12 | _ | _ | _ |
| SGND_SRDS | SerDes Core Logic GND | AG13 | _ | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AG14 | _ | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AG17 | _ | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AG18 | _ | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AG19 | _ | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AH11 | _ | _ | _ |
| SGND_SRDS | SerDes Core Logic GND | AH15 | - | _ | - |
| SGND_SRDS | SerDes Core Logic GND | AH19 | _ | _ | _ |
| SGND_SRDS | SerDes Core Logic GND | AJ13 | _ | _ | _ |
| SGND_SRDS | SerDes Core Logic GND | AJ17 | _ | _ | _ |
| XVDD_SRDS | SerDes Transceiver Supply | AD13 | _ | XV_{DD_SRDS} | _ |
| XVDD_SRDS | SerDes Transceiver Supply | AD17 | _ | XV _{DD_SRDS} | _ |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------|---------------------------|---|----------|-----------------|-------|
| XVDD_SRDS | SerDes Transceiver Supply | AE11 | - | XV_{DD_SRDS} | _ |
| XVDD_SRDS | SerDes Transceiver Supply | AE19 | _ | XV_{DD_SRDS} | _ |
| XVDD_SRDS | SerDes Transceiver Supply | AF14 | - | XV_{DD_SRDS} | ı |
| XVDD_SRDS | SerDes Transceiver Supply | AF16 | _ | XV_{DD_SRDS} | 1 |
| XGND_SRDS | SerDes Transceiver GND | AD11 | _ | _ | _ |
| XGND_SRDS | SerDes Transceiver GND | AD19 | - | _ | - |
| XGND_SRDS | SerDes Transceiver GND | AE14 | - | _ | - |
| XGND_SRDS | SerDes Transceiver GND | AE16 | _ | _ | _ |
| XGND_SRDS | SerDes Transceiver GND | AF11 | - | _ | - |
| XGND_SRDS | SerDes Transceiver GND | AF12 | _ | _ | _ |
| XGND_SRDS | SerDes Transceiver GND | AF18 | - | _ | _ |
| XGND_SRDS | SerDes Transceiver GND | AG10 | - | _ | - |
| OVDD | General I/O Supply | K23 | _ | _ | _ |
| OVDD | General I/O Supply | L25 | - | _ | - |
| OVDD | General I/O Supply | N27 | - | _ | - |
| OVDD | General I/O Supply | P25 | _ | _ | 1 |
| OVDD | General I/O Supply | U27 | _ | _ | 1 |
| OVDD | General I/O Supply | Y26 | _ | _ | _ |
| VDD | Core Supply | K11, K13, K15, K17, K19, L10, K10, K12, K14, K16, L20, K18, K20, N10, N20, M10, M20, R10, R20, P10, P20, U10, U20, T10, T20, W10, V10, V20, W20, Y11,Y12, Y19, Y18, Y20 | - | - | - |
| GND | Ground | A1, A29, B5, B14, B27, C6, C8, C11, C18, C24, D16, D22, D25, E3, E28, F7, G5, G9, G21, H3, H27, J7, J23, K4,F17, L12,L14, L16, L18, M11, K25, L1, L11, L13, L15, L17, L19, M3, M4, M6, M19, M12, M13, M14, M15, M16, M17, M18, P11, M26, N2, N11, N12, N13, N14, N15, N16, N17, N18, N19, N28, P5, P19, P12, P13, P14, P15, P16, P17, P18, T11, P24, R3, R11, R12, R13, R14, R15, R16, R17, R18, R19, T6, T19, T12, T13, T14, T15, T16, T17, T18, V11, T27, U11, U12, U13, U14, U15, U16, U17, U18, U19, V4, V19, V12, V13, V14, V15, V16, V17, V18, W12, V27, W2, W4, W11, W13, W14, W15, W16, W17, W19, Y3, Y6, Y7, W18, Y13, Y17, Y25, AA6, AA23, AC3, AC10, AC20, AC24, AC28, AD3, AD6, AE9, AF20, AG3, AG5, AG7, AG24, AG27, AJ1, AJ29, AH10, AJ10, AD10 | _ | _ | _ |

Table 1-1. P2020 Pinout Listing⁽¹⁾ (Continued)

| Signal | Signal Name | Package Pin Number | Pin Type | Power Supply | Notes | | | | |
|---------------|------------------------------------|--------------------|----------|----------------------|-------|--|--|--|--|
| | Analog | | | | | | | | |
| SD_IMP_CAL_RX | SerDes Rx Impedance Calibration | AG11 | I | XV_{DD} | (27) | | | | |
| SD_IMP_CAL_TX | SerDes Tx Impedance Calibration | AF19 | I | XV_{DD} | (27) | | | | |
| SD_PLL_TPA | SerDes PLL Test Point Analog | AD16 | 0 | XV_{DD} | (12) | | | | |
| SD_PLL_TPD | SerDes PLL Test Point Digital | AE15 | 0 | XV_{DD} | (12) | | | | |
| MVREF | SSTL_1.5/1.8 Reference Voltage | R6 | - | GV _{DD} ÷ 2 | _ | | | | |
| Temp_Anode | Temp_Anode | E16 | I | Internal Diode | (35) | | | | |
| Temp_Cathode | Temp_Cathode | E15 | 0 | Internal Diode | (35) | | | | |

- Notes: 1. All multiplexed signals are listed only once and do not reoccur.
 - 2. It is recommended that a weak pull-up resistor (2–10 K Ω) be placed on this pin to OV_{DD}.
 - 3. Open drain signal. GPIO pins may be programmed to operate as open-drain outputs.
 - 4. This pin is a reset configuration pin. It has a weak internal pull-up P-FET which is enabled only when the processor is in the reset state. This pull-up is designed such that it can be overpowered by an external 4.7-k Ω pull-down resistor. If the signal is intended to be high after reset and if there is any device on the net which might pull down the value of the net at reset, a pull-up or active driver is needed.
 - 5. The value of LA[29:31] during reset sets the CCB clock to SYSCLK PLL ratio. These pins require 4.7-kΩ pull-up or pulldown resistors.
 - 6. The value of LALE, LGPL[02], LBCTL, LWE[00], UART SOUT[01], and READY P1, at reset set the e500 core0 clocks to CCB Clock PLL ratios. These pins require 4.7-k Ω pull-up or pull-down resistors.
 - 7. Functionally, this pin is an output, but structurally it is an I/O because it either samples configuration input during reset or because it has other manufacturing test functions. This pin is therefore described as an I/O for boundary scan.
 - 8. If this pin is configured for local bus controller use, pull up with 2–10 K Ω resistor to BV_{DD} to ensure there is no random chip select assertion due to possible noise or other causes.
 - 9. This output is actively driven during reset rather than being three-stated during reset.
 - 10. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
 - 11. If this pin is connected to a device that pulls down during reset, an external pull-up is required to drive this pin to a high state during reset.
 - 12. Do not connect.
 - 13. Independent supply derived from board V_{DD}.
 - 14. It is recommended that a pull-up resistor (~1 k Ω) be placed on this pin to OV_{DD}.
 - 15. The following pins must NOT be pulled down during power-on reset: DMA1 DACK[00], LA[17], USB STP, TSEC2 TXD[06], HRESET REQ, MSRCID[2:3], MDVAL, ASLEEP.
 - 16. TSEC2 TXD[05] is a POR configuration pin for eSDHC card-detect (cfg_sdhc_cd_pol_sel), and it also has an alternate function of TSEC3 TX EN. When eTSEC1 or eTSEC2 or eTSEC3 are used as parallel interfaces, the TSECx TX EN pins require an external 4.7-k pull-down resistor to prevent PHY from seeing a valid Transmit Enable before it is actively driven. However, the pull-down resistor on TSEC3 TX EN causes the eSDHC card-detect (cfg sdhc cd sel) to be inverted; the inversion should be overridden from the SDHCDCR[CD INV] debug control register. If the device is configured to boot from the eSDHC interface, the SDHC CD should be inverted on the board.
 - 17. TSEC2 TXD[01] is used as cfg dram type. It must be valid at powerup.

- 18. For DDR2 MDIC[00] is grounded through an $18.2-\Omega$ (full-strength mode) or $36.4-\Omega$ (half-strength mode) precision 1% resistor and MDIC[01] is connected to GV_{DD} through an $18.2-\Omega$ (full-strength mode) or $36.4-\Omega$ (half-strength mode) precision 1% resistor. These pins are used for automatic calibration of the DDR IOs. The calibration resistor value for DDR3 must be $20-\Omega$ (full-strength mode), or $40.2-\Omega$ (half-strength mode).
- 19. DDRCLK input is only required when the P2020 DDR controller is running in asynchronous mode. See Section 4.2.2, "Clock Signals", Section 4.4.3.2, "DDR PLL Ratio" and Table 4-10, "DDR Complex Clock PLL Ratio," in the P2020 QorlQ Integrated Communications Host Processor Family Reference Manual.
- 20. EC_GTX_CLK125 is a 125-MHz input clock shared among all eTSEC ports in the following modes: GMII, TBI, RGMII and RTBI. If none of the eTSEC ports is operating in these modes, the EC_GTX_CLK125 input can be tied off to GND. The EC_GTX_CLK125 signal high level is nominally LV_{DD}.
- 21. These POR configuration inputs may be used in the future to control functionality. It is advised that boards are built with the ability to pull-down these pins.LA[20:22], UART_SOUT[00], MSRCID[01], MSRCID[04], and DMA1_DDONE[00] are reserved for future reset configuration.
- 22. Incorrect settings can lead to irreversible device damage.
- 23. The value of LAD[0:15] during reset sets the upper 16 bits of the GPPORCR as a user option setting.
- 24. Used to set the DDR clock PLL settings; requires a 4.7-kΩ pull-up or pull-down resistor.
- 25. Used to determine CPU boot configuration; requires a 4.7-kΩ pull-up or pull-down resistor.
- 26. Pin must be the same voltage as V_{DD} .
- 27. SD_IMP_CAL_RX is grounded through an 200- Ω precision ±1% resistor and SD_IMP_CAL_TX is grounded through an 100- Ω precision ±1% resistor.
- 29. Pull up with a 4.7 k Ω resistor to OV_{DD}
- 31. 100K pull down needed if this signal is used as a CD pin for SD cards. The pull down is not needed for MMC cards.
- 32. All unused MCK pins must be disabled via DDRCLKDR register.
- 33. This pin requires a 1 k Ω pull up to OV_{DD}.
- 34. For systems that boot from local bus (GPCM)-controlled NOR flash or (FCM)-controlled NAND flash, a pull-up on LGPL4 is required.
- 35. These pins may be connected to a thermal diode monitoring device such as the ADT7461A. If a thermal diode monitoring device is not connected, these pins may be connected to test point or left as a no connect.
- 36. This pin, if not used, must be pulled high or low via individual 2–10 k Ω resistor.
- 37. This pin must be pulled high or low via a 2–10 k Ω resistor.

2. Electrical Characteristics

This section provides the AC and DC electrical specifications for the device. The device is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

2.1 Overall DC Electrical Characteristics

This section covers the DC ratings, conditions, and other characteristics.

2.1.1 **Absolute Maximum Ratings**

Table 2-1 provides the absolute maximum ratings.

Absolute Maximum Ratings⁽¹⁾ **Table 2-1.**

| Parameter | | Symbol | Max Value | Unit | Notes |
|--|------------------------------|---|--|------|--------|
| Core and platfor | m supply voltage | V_{DD} | -0.3 to 1.1 | V | _ |
| PLL supply voltage | | $\begin{array}{c} {\sf AV_{DD_CORE0}} \\ {\sf AV_{DD_CORE1}} \\ {\sf AV_{DD_DDR}}, \\ {\sf AV_{DD_LBIU}}, \\ {\sf AV_{DD_PLAT}}, \\ {\sf AV_{DD_SRDS}} \end{array}$ | –0.3 to 1.1 | V | (2) |
| Core power supp | oly for SerDes transceivers | SV _{DD} _SRDS | -0.3 to 1.1 | V | _ |
| Pad power supp | y for SerDes transceivers | XV _{DD} _SRDS | -0.3 to 1.1 | V | _ |
| DDR2/3 DRAM I/O voltage | | GV _{DD} | -0.3 to 1.98 -0.3 to 1.65 | ٧ | _ |
| Three-speed Ethernet I/O, MII management voltage | | LV _{DD} (eTSEC) | -0.3 to 3.63 -0.3 to 2.75 | ٧ | _ |
| DUART, system control and power management, I ² C, GPIOx8, and JTAG I/O voltage | | OV_DD | -0.3 to 3.63 | V | (3) |
| USB, eSPI, eSDHC | | CV _{DD} | -0.3 to 3.63 -0.3 to 2.75 -0.3 to 1.98 | V | (3) |
| Enhanced local I | ous I/O and GPIOx8 voltage | BV _{DD} | -0.3 to 3.63 -0.3 to 2.75 -0.3 to 1.98 | V | (3) |
| Input voltage | DDR2/DDR3 DRAM signals | MV _{IN} | -0.3 to (GV _{DD} + 0.3) | V | (3) |
| | DDR2/DDR3 DRAM reference | MV_REF | -0.3 to (GV _{DD/2} + 0.3) | V | (3) |
| | Three-speed Ethernet signals | LV _{IN} | -0.3 to (LV _{DD} + 0.3) | V | (3)(4) |
| Enhanced local bus signals | | BV _{IN} | -0.3 to (BV _{DD} + 0.3) | V | _ |
| DUART, SYSCLK, system control and power management, I ² C, and JTAG signals | | OV _{IN} | -0.3 to (OV _{DD} + 0.3) | ٧ | (3) |
| | SerDes | XV_{IN} | -0.3 to (XV _{DD} + 0.3) | V | _ |
| Storage tempera | ture range | T _{STG} | -55 to 150 | °C | _ |

- Notes: 1. Functional operating conditions are given in Table 2-2. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
 - 2. AV_{DD} is measured at the input to the filter and not at the pin of the device.
 - 3. Caution: $(B,M,L,O,C,X)V_{IN}$ must not exceed $(B,G,L,O,C,X)V_{DD}$ by more than 0.3V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
 - 4. (M,L,O)V_{IN} and MV_{REF} may overshoot/undershoot to a voltage and for a maximum duration as shown in Figure 2-1.

2.1.2 Recommended Operating Conditions

Table 2-2 provides the recommended operating conditions for this device. Note that the values in Table 2-2 are the recommended and tested operating conditions. Proper device operation outside these conditions is not guaranteed.

Table 2-2. Recommended Operating Conditions

| Parameter | | Symbol | Recommended Value | Unit | Notes |
|--|--|---|---|------|-------|
| Core and platform supply voltage | | V_{DD} | 1.05 ± 50 mV | V | (1) |
| PLL supply voltage | | $\begin{array}{c} {\rm AV_{DD_CORE0}} \\ {\rm AV_{DD_CORE1}} \\ {\rm AV_{DD_DDR}}, \\ {\rm AV_{DD_LBIU}}, \\ {\rm AV_{DD_PLAT}}, \\ {\rm AV_{DD_SRDS}} \end{array}$ | 1.05 ± 50 mV | V | - |
| Core power supply for SerDes transceivers | | SV _{DD} _SRDS | 1.05 ± 50 mV | V | _ |
| Pad power supply for SerDes transceivers a | and PCI Express | XV _{DD} _SRDS | 1.05 ± 50 mV | V | - |
| DDR2 DRAM I/O voltage | | GV _{DD} | 1.8V ± 100 mV | V | - |
| DDR3 DRAM I/O voltage | | GV _{DD} | 1.5V ± 75 mV | V | - |
| Three-speed Ethernet I/O voltage (eTSEC) | | LV _{DD} | 3.3V ± 165 mV 2.5V ± 125 mV | V | _ |
| DUART, system control and power management, I ² C, GPIOx8, and JTAG I/O voltage | | OV_DD | 3.3V ± 165 mV | V | - |
| Enhanced local bus I/O and GPIOx8 voltage | | BV _{DD} | 3.3V ± 165 mV 2.5V ± 125 mV 1.8V ± 90 mV | V | _ |
| USB, eSPI, eSDHC I/O voltage | | CV _{DD} | 3.3V ± 165 mV 2.5V ± 125 mV 1.8V ± 90 mV | V | (4) |
| Input voltage | DDR2/3 DRAM signals | MV _{IN} | GND to GV _{DD} | V | - |
| | DDR2 DRAM reference | MV_REF | GV _{DD} /2 | V | - |
| | DDR3 DRAM reference | MV _{REF} | GV _{DD} /2 | V | _ |
| | Three-speed Ethernet signals | LV _{IN} | GND to LV _{DD} | V | - |
| | Enhanced local bus signals | BV _{IN} | GND to BV _{DD} | V | - |
| | DUART, SYSCLK, system control and power management, I ² C, and JTAG signals | OV _{IN} | GND to OV _{DD} | V | - |
| | USB, eSPI, eSDHC | CV _{IN} | GND to CV _{DD} | V | _ |
| | SerDes signals | XV _{IN} | GND to XV _{DD} | V | _ |
| Operating Temperature range | Military | T _A T _J | $T_A = -55 \text{ (min) to}$ $T_J = 125 \text{ (max)}$ | °C | (3) |
| Operating Temperature range | Industrial | T _A T _J | $T_A = -40 \text{ (min) to}$ $T_J = 125 \text{ (max)}$ | °C | (3) |

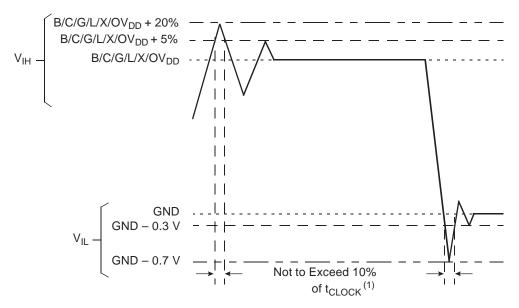
Notes: 1. **Caution:** (B,M,L,O,C, X)VIN must not exceed (B,G,L,O, C,X)VDD by more than 0.3V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.

Caution: Until V_{DD} reaches its recommended operating voltage, if L/C/B/G/OV_{DD} exceeds V_{DD} extra current may be drawn by the device.

- 3. Minimum temperature is specified with T_A; maximum temperature is specified with T_J.
- 4. CV_{DD} for eSDHC is limited for 3.3, 2.5, and 1.8V

Figure 2-1 shows the undershoot and overshoot voltages at the interfaces of the device.

Figure 2-1. Overshoot/Undershoot Voltage for BV_{DD}/CV_{DD}/GV_{DD}/LV_{DD}/XV_{DD}/OV_{DD}



Note: 1. t_{CLOCK} refers to the clock period associated with the respective interface:

For I²C and JTAG, t_{CLOCK} references SYSCLK.

For DDR, t_{CLOCK} references MCLK.

For eTSEC, t_{CLOCK} references EC_GTX_CLK125.

For eLBC, t_{CLOCK} references LCLK.

For SerDes XV_{DD}, t_{CLOCK} references SD_REF_CLK.

The core voltage must always be provided at nominal 1.05V (see Table 2-2 for actual recommended core voltage.) Voltage to the processor interface I/Os are provided through separate sets of supply pins and must be provided at the voltages shown in Table 2-2. The input voltage threshold scales with respect to the associated I/O supply voltage. OV_{DD} and LV_{DD} based receivers are simple CMOS I/O circuits and satisfy appropriate LVCMOS type specifications. The SDRAM interface uses a differential receiver referenced the externally supplied MV_{REF} signal (nominally set to $GV_{DD} \div 2$). The DDR DQS receivers cannot be operated in single-ended fashion. The complement signal must be properly driven and cannot be grounded.

2.1.3 Output Driver Characteristics

Table 2-3 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

Table 2-3. Output Drive Capability

| Driver Type | Output Impedance (Ω) | Supply Voltage | Notes |
|---|--|-----------------------------|-------|
| Expansed level bus interfere | 45 | BV _{DD} = 3.3V | |
| Enhanced local bus interface, GPIO[0:7] | 45 | $BV_{DD} = 2.5V$ | _ |
| Si io[o.i] | 45 | $BV_{DD} = 1.8V$ | |
| DDR2 signal (programmable) | 18 (full-strength mode) 36 (half-strength mode) | GV _{DD} = 1.8V | (1) |
| DDR 3 signal (programmable) | 20 (full-strength mode) 40 (half-strength mode) | GV _{DD} = 1.5V | (1) |
| eTSEC signals | 45 | LV _{DD} = 2.5/3.3V | _ |
| DUART, system control, JTAG | 45 | OV _{DD} = 3.3V | _ |
| I ² C | 45 | OV _{DD} = 3.3V | _ |
| | | CV _{DD} = 3.3V | |
| USB, eSPI, eSDHC | 45 | $CV_{DD} = 2.5V$ | _ |
| | | CV _{DD} = 1.8V | |

Note: 1. The drive strength of the DDR2/3 interface in half-strength mode is at $T_J = 105$ °C and at GV_{DD} (min).

2.2 Power Sequencing

The device requires its power rails to be applied in a specific sequence in order to ensure proper device operation. These requirements are as follows for power up:

- 1 V_{DD} , AV_{DD} , BV_{DD} , LV_{DD} , CV_{DD} , OV_{DD} , $SV_{DD\ SRDS}$, and $XV_{DD\ SRDS}$
- 2 GV_{DD}

All supplies must be at their stable values within 50 ms.

Items on the same line have no ordering requirement with respect to one another. Items on separate lines must be ordered sequentially such that voltage rails on a previous step must reach 90% of their value before the voltage rails on the current step reach 10% of theirs.

Note:

While V_{DD} is ramping, current may be supplied from V_{DD} through the device to GV_{DD} . Nevertheless, GV_{DD} from an external supply should follow the sequencing described above.

From a system standpoint, if any of the I/O power supplies ramp prior to the V_{DD} core supply, the I/Os associated with that I/O supply may drive a logic one or zero during power up, and extra current may be drawn by the device.

WARNING

Only 100,000 POR cycles are permitted per lifetime of a device.

2.3 **Power Characteristics**

The estimated typical core power consumption for the core complex bus (CCB) versus the core frequency for this family of QorlQ devices is shown in Table 2-4.

P2020 Core Power Consumption⁽¹⁾ **Table 2-4.**

| Power Mode | Core Frequency (MHz) | Platform Frequency (MHz) | V _{DD} (V) | Junction Temperature (°C) | Power (W) | Notes | | | |
|------------|-------------------------|-----------------------------|---------------------|------------------------------|-----------|--------|--------|-----|--------|
| Thermal | 000 | 400 | 4.05 | 405 | 5.0 | (2)(3) | | | |
| Maximum | 800 | 800 400 1.05 | 125 | 6.1 | (2)(4) | | | | |
| Thermal | 1000 | 500 | 4.05 | 405 | 5.3 | (2)(3) | | | |
| Maximum | 1000 | 500 | 1.05 | 125 | 6.5 | (2)(4) | | | |
| Thermal | 4000 | | 200 | 4.05 | 405 | 5.6 | (2)(3) | | |
| Maximum | 1200 | 600 | 1.05 | 125 | 6.9 | (2)(4) | | | |
| Thermal | 4000 | | | | | 4.05 | 405 | 5.8 | (2)(3) |
| Maximum | 1333 | 667 | 1.05 | 125 | 7.2 | (2)(4) | | | |

- Notes: 1. This table includes power numbers for the V_{DD} and AV_{DD} rails.
 - 2. These values specify the power consumption at nominal voltage and apply to all valid processor bus frequencies and configurations. The values do not include power dissipation for I/O supplies.
 - 3. Thermal power is the maximum power measured at nominal core voltage (VDD) and maximum operating junction temperature (see Table 2-2) while running the Dhrystone 2.1 benchmark and achieving 2.3 Dhrystone MIPs/MHz with one core at 100% efficiency and the second core at 50% efficiency.
 - 4. Maximum power is the maximum power measured at nominal core voltage (V_{DD}) and maximum operating junction temperature (see Table 2-2) while running a test which includes an entirely L1-cache-resident, contrived sequence of instructions which keep all the execution units busy at with one core at 100% efficiency and the second core at 50% efficiency and a typical workload on platform interfaces.

2.3.1 I/O DC Power Supply Recommendation

Table 2-5 provides estimated I/O power numbers for each block: DDR, PCI Express, eLBC, eTSEC, Serial RapidIO, SGMII, eSDHC, USB, eSPI, DUART, I²C and GPIO.

 Table 2-5.
 I/O Power Supply Estimated Values

| Interface | Parameter | Symbol | Typical | Maximum | Unit | Notes |
|------------------|---|--------------------------|---------|---------|------|--------------|
| | 400 MHz data rate | GV _{DD} (1.8V) | 0.7 | 1.0 | W | (1)(2)(3) |
| DDR2 | 533 MHz data rate | GV _{DD} (1.8V) | 0.9 | 1.25 | W | (1)(2)(3) |
| | 667 MHz data rate | GV _{DD} (1.8V) | 1.1 | 1.6 | W | (1)(2)(3) |
| 5556 | 667 MHz data rate | GV _{DD} (1.5V) | 0.7 | 1.1 | W | (1)(2)(3) |
| DDR3 | 800 MHz data rate | GV _{DD} (1.5V) | 0.8 | 1.2 | W | (1)(2)(3)(4) |
| | ×1, 2.5 G-baud | XV _{DD} (1.05V) | 0.15 | 0.15 | W | (1)(2)(3) |
| PCI Express | ×2, 2.5 G-baud | XV _{DD} (1.05V) | 0.21 | 0.21 | W | (1)(2)(3) |
| | ×4, 2.5 G-baud | XV _{DD} (1.05V) | 0.32 | 0.32 | W | (1)(2)(3) |
| 0 : 15 : 110 | ×1, 2.5 G-baud | XV _{DD} (1.05V) | 0.18 | 0.18 | W | (1)(2)(3) |
| Serial RapidIO | ×4, 2.5 G-baud | XV _{DD} (1.05V) | 0.39 | 0.39 | W | (1)(2)(3) |
| SGMII | ×1, 1.25G-baud | XV _{DD} (1.05V) | 0.1 | 0.2 | W | (1)(2)(3) |
| | | BV _{DD} (1.8V) | 0.05 | 0.09 | W | (1)(2)(3) |
| eLBC | 16-bit, 75 MHz | BV _{DD} (2.5V) | 0.08 | 0.13 | W | (1)(2)(3) |
| | | BV _{DD} (3.3V) | 0.11 | 0.20 | W | (1)(2)(3) |
| eTSEC | MII, GMII, RGMII, RTBI, RMII, TBI, 1588 | LV _{DD} (2.5V) | 0.07 | 0.15 | W | (1)(2)(3)(5) |
| | MII, GMII, TBI, RMII, 1588 | LV _{DD} (3.3V) | 0.11 | 0.20 | W | (1)(2)(3)(5) |
| | | CV _{DD} (3.3V) | 0.03 | 0.04 | W | (1)(2)(3) |
| eSDHC | _ | CV _{DD} (2.5V) | 0.02 | 0.03 | W | (1)(2)(3) |
| | | CV _{DD} (1.8V) | 0.01 | 0.02 | W | (1)(2)(3) |
| | | CV _{DD} (3.3V) | 0.05 | 0.06 | W | (1)(2)(3) |
| USB | _ | CV _{DD} (2.5V) | 0.04 | 0.05 | W | (1)(2)(3) |
| | | CV _{DD} (1.8V) | 0.02 | 0.03 | W | (1)(2)(3) |
| | | CV _{DD} (3.3V) | 0.03 | 0.04 | W | (1)(2)(3) |
| eSPI | _ | CV _{DD} (2.5V) | 0.02 | 0.03 | W | (1)(2)(3) |
| | | CV _{DD} (1.8V) | 0.01 | 0.02 | W | (1)(2)(3) |
| I ² C | _ | OV _{DD} (3.3V) | 0.01 | 0.02 | W | (1)(2)(3) |
| DUART | _ | OV _{DD} (3.3V) | 0.01 | 0.02 | W | (1)(2)(3) |
| GPIO [0:7] | ×8 | OV _{DD} (3.3V) | 0.01 | 0.02 | W | (1)(2)(3)(6) |
| | | BV _{DD} (1.8V) | 0.01 | 0.02 | W | (1)(2)(3)(6) |
| GPIO [8:15] | ×8 | BV _{DD} (2.5V) | 0.01 | 0.02 | W | (1)(2)(3)(6) |
| | | BV _{DD} (3.3V) | 0.01 | 0.02 | W | (1)(2)(3)(6) |

Notes:

- 1. The maximum value is dependent on actual use case such as what application, external components used, environmental conditions such as temperature voltage and frequency. This is not intended to be the maximum guaranteed current. Depending on use case different result is expected.
- 2. The typical value are estimates based on simulations at nominal recommended core voltage (VDD) and assuming 65 C junction temperature.
- 3. The maximum value are estimates based on simulations at nominal recommended core voltage (V_{DD}) and assuming 105 C junction temperature.
- 4. 800 Mbps data rate only supported on DDR3.
- 5. The current values are per each eTSEC used.
- 6. GPIO ×8 support on OV_{DD} and ×8 on BV_{DD} rail supply.

2.4 Input Clocks

This section discusses the parameters for the input clocks.

2.4.1 **System Clock Timing**

Table 2-6 provides the system clock (SYSCLK) DC specifications for the device.

SYSCLK DC Electrical Characteristics (OV_{DD} = 3.3V ± 165 mV) **Table 2-6.**

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|--|-----------------|-----|---------|-----|------|-------|
| High-level input voltage | V _{IH} | 2.0 | _ | _ | V | (1) |
| Low-level input voltage | V _{IL} | - | _ | 0.8 | V | (1) |
| Input capacitance | C _{IN} | _ | 7 | 15 | pf | _ |
| Input current (V _{IN} = 0V or V _{IN} = V _{DD}) | I _{IN} | _ | _ | ±50 | μA | (2) |

Notes: 1. The max V_{IH} , and min V_{IL} values can be found in Table 2-2.

2. The symbol V_{IN}, in this case, represents the OV_{IN} symbol referenced in Table 2-2.

Table 2-7 provides the system clock (SYSCLK) AC timing specifications for the device.

SYSCLK AC Timing Specifications (At Recommended Operating Conditions, see Table 2-**Table 2-7.** 2 with $OV_{DD} = 3.3V \pm 165 \text{ mV}$

| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Notes |
|--|---------------------------------------|-------|-----|------|------|--------|
| SYSCLK frequency | f _{SYSCLK} | 64.00 | ı | 100 | MHz | (1)(2) |
| SYSCLK cycle time | t _{sysclk} | 10 | _ | 15.6 | ns | (1)(2) |
| SYSCLK duty cycle | t _{KHK} /t _{SYSCLK} | 40 | _ | 60 | % | (2) |
| SYSCLK slew rate | _ | 1 | _ | 4 | V/ns | (3) |
| SYSCLK peak period jitter | _ | _ | _ | ±150 | ps | _ |
| SYSCLK jitter phase noise at –56 dBc | _ | _ | _ | 500 | KHz | (4) |
| AC input swing limits at 3.3V OV _{DD} | ΔV_{AC} | 1.9 | _ | _ | V | _ |

- Notes: 1. Caution: The CCB clk to SYSCLK ratio and e500 core to CCB clk ratio settings must be chosen such that the resulting SYSCLK frequency, e500 core frequency, and CCB clk frequency do not exceed their respective maximum or minimum operating frequencies.
 - 2. Measured at the rising edge and/or the falling edge at ${\rm OV_{DD}} \div 2$.
 - 3. Slew rate as measured from $\pm 0.3 \, \Delta V_{AC}$ at center of peak-to-peak voltage at clock input.
 - 4. Phase noise is calculated as FFT of TIE jitter.

2.4.2 SYSCLK and Spread Spectrum Source Recommendations

Spread spectrum clock sources are an increasingly popular way to control electromagnetic interference emissions (EMI) by spreading the emitted noise to a wider spectrum and reducing the peak noise magnitude in order to meet industry and government requirements. These clock sources intentionally add long-term jitter in order to diffuse the EMI spectral content. The jitter specification given in Table 2-7 considers short-term (cycle-to-cycle) jitter only and the clock generator's cycle-to-cycle output jitter should meet the device input cycle-to-cycle jitter requirement. Frequency modulation and spread are separate concerns, and the device is compatible with spread spectrum sources if the recommendations listed in Table 2-8 are observed.

Table 2-8. SYSCLK Spread Spectrum Clock Source Recommendations (At Recommended Operating Conditions, see Table 2-2)

| Parameter | Min | Max | Unit | Notes |
|----------------------|-----|-----|------|--------|
| Frequency modulation | - | 60 | kHz | _ |
| Frequency spread | _ | 1.0 | % | (1)(2) |

Notes:

- SYSCLK frequencies resulting from frequency spreading, and the resulting core and VCO frequencies, must meet the minimum and maximum specifications given in Table 2-7.
- Maximum spread spectrum frequency may not result in exceeding any maximum operating frequency of the device

CAUTION

The processor's minimum and maximum SYSCLK, core, and VCO frequencies must not be exceeded regardless of the type of clock source. Therefore, systems in which the processor is operated at its maximum rated e500 core frequency should avoid violating the stated limits by using down-spreading only.

2.4.3 Real Time Clock Timing

The RTC input is sampled by the platform clock (CCB clock). The output of the sampling latch is then used as an input to the counters of the PIC and the TimeBase unit of the e500. There is no jitter specification. The minimum pulse width of the RTC signal must be greater than $2\times$ the period of the CCB clock. That is, minimum clock high time is $2\times t_{CCB}$, and minimum clock low time is $2\times t_{CCB}$. There is no minimum RTC frequency; RTC may be grounded if not needed.

2.4.4 eTSEC Gigabit Reference Clock Timing

Table 2-9 provides the eTSEC gigabit reference clocks DC electrical characteristics for RGMII, GMII at $LV_{DD} = 2.5V$

Table 2-9. eTSEC Gigabit Reference Clock DC Electrical Characteristics RGMII, GMII at $LV_{DD} = 2.5V$

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|------|------|------|-------|
| High-level input voltage | V _{IH} | 1.70 | _ | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.70 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = V _{DD}) | I _{IN} | - | ±40 | μΑ | (2) |

Notes: 1. The max V_{IH} , and min V_{IL} values can be found in Table 2-2.

2. The symbol V_{IN}, in this case, represents the LV_{IN} symbol referenced in Table 2-2.

Table 2-10 provides the eTSEC gigabit reference clocks DC electrical characteristics for GMII $LV_{DD} = 3.3V$.

Table 2-10. eTSEC Gigabit Reference Clock DC Electrical Characteristics GMII LV_{DD} = 3.3V

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|------|------|------|-------|
| High-level input voltage | V _{IH} | 1.90 | - | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.90 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = V _{DD}) | I _{IN} | - | ±40 | μA | (2) |

Notes: 1. The max V_{IH} , and min V_{IL} values can be found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 2-2.

Table 2-11 provides the eTSEC gigabit reference clocks (EC_GTX_CLK125) AC timing specifications for the device.

Table 2-11. EC_GTX_CLK125 AC Timing Specifications

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|-------------------------------|--|-----|---------|------|------|-------|
| EC_GTX_CLK125 frequency | t _{G125} | _ | 125 | - | MHz | _ |
| EC_GTX_CLK125 cycle time | t _{G125} | _ | 8 | ı | ns | _ |
| EC_GTX_CLK rise and fall time | t _{G125R} /t _{G125F} | _ | - | | ns | (1) |
| LV _{DD} = 2.5V | | | | 0.75 | | |
| LV _{DD} = 3.3V | | | | 1.0 | | |
| EC_GTX_CLK125 duty cycle | t _{G125H} /t _{G125} | | - | | % | (2) |
| GMII, TBI | | 45 | | 55 | | |
| 1000Base-T for RGMII, RTBI | | 47 | | 53 | | |
| EC_GTX_CLK125 jitter | _ | _ | _ | ±150 | ps | (2) |

Notes: 1. Rise and fall times for EC_GTX_CLK125 are measured from 0.5 and 2.0V for LV_{DD} = 2.5V, and from 0.6 and 2.7V for LV_{DD} = 3.3V.

 EC_GTX_CLK125 is used to generate the GTX clock for the eTSEC transmitter with 2% degradation. EC_GTX_CLK125 duty cycle can be loosened from 47%/53% as long as the PHY device can tolerate the duty cycle generated by the eTSEC GTX_CLK. See Section 2.10.2.5 "RGMII and RTBI AC Timing Specifications" on page 52, for duty cycle for 10Base-T and 100Base-T reference clock.

2.4.5 DDR Clock Timing

Table 2-12 provides the system clock (DDRCLK) DC specifications for the device.

Table 2-12. DDRCLK DC Electrical Characteristics ($OV_{DD} = 3.3V \pm 165 \text{ mV}$)

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|---|-----------------|------|---------|------------------------|------|-------|
| High-level input voltage | V_{IH} | 2.0 | - | OV _{DD} + 0.3 | V | _ |
| Low-level input voltage | V_{IL} | -0.3 | _ | 0.8 | V | _ |
| Input capacitance | C _{IN} | - | 7 | 15 | pf | _ |
| Input current ($V_{IN} = 0V \text{ or } V_{IN} = V_{DD}$) | I _{IN} | - | _ | ±50 | μA | (1) |

Note: 1. The symbol V_{IN} , in this case, represents the OV_{IN} symbol referenced in Table 2-1 and Table 2-2.

Table 2-13 provides the DDR clock (DDRCLK) AC timing specifications for the device.

DDRCLK AC Timing Specifications (At Recommended Operating Conditions with OV_{DD} of $3.3V \pm 5\%$)

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|--|---------------------------------------|------|---------|------|------|--------|
| DDRCLK frequency | f _{DDRCLK} | 66.7 | _ | 100 | MHz | (1)(2) |
| DDRCLK cycle time | t _{DDRCLK} | 10 | _ | 15 | ns | (1)(2) |
| DDRCLK duty cycle | t _{KHK} /t _{DDRCLK} | 40 | _ | 60 | % | (2) |
| DDRCLK slew rate | _ | 1 | _ | 4 | V/ns | (3) |
| DDRCLK peak period jitter | _ | _ | _ | ±150 | ps | - |
| DDRCLK jitter phase noise at –56 dBc | _ | _ | _ | 500 | KHz | (4) |
| AC Input Swing Limits at 3.3V OV _{DD} | ΔV_{AC} | 1.9 | _ | _ | V | _ |

- Notes: 1. Caution: The DDR complex clock to DDRCLK ratio settings must be chosen such that the resulting DDR complex clock frequency does not exceed the maximum or minimum operating frequencies.
 - 2. Measured at the rising edge and/or the falling edge at $OV_{DD} \div 2$.
 - 3. Slew rate as measured from $\pm 0.3~\Delta V_{AC}$ at center of peak to peak voltage at clock input.
 - 4. Phase noise is calculated as FFT of TIE jitter.

Other Input Clocks 2.4.6

For information on the input clocks of other functional blocks of the platform such as SerDes and eTSEC, see their specific sections in this document.

2.5 **RESET Initialization**

This section describes the AC electrical specifications for the RESET initialization timing requirements of the device. Table 2-14 provides the RESET initialization AC timing specifications for the DDR SDRAM component(s).

Table 2-14. RESET Initialization Timing Specifications

| Parameter | Min | Max | Unit | Notes |
|--|-----|-----|---------|--------|
| Required assertion time of HREST | 100 | _ | μs | _ |
| Minimum assertion time for SRESET | 3 | _ | SYSCLKs | (1) |
| PLL input setup time with stable SYSCLK before HRESET negation | 100 | - | μs | - |
| Input setup time for POR configurations (other than PLL configuration) with respect to negation of HRESET | 4 | _ | SYSCLKs | (1) |
| Input hold time for all POR configurations (including PLL configuration) with respect to negation of HRESET | 2 | _ | SYSCLKs | (1) |
| Maximum valid-to-high impedance time for actively driven POR configurations with respect to negation of HRESET | - | 5 | SYSCLKs | (1)(2) |

Notes: 1. SYSCLK is the primary clock input for the device.

2. HRESET should have a rise time of no more than one SYSCLK cycle.

Table 2-15 provides the PLL lock times.

Table 2-15. PLL Lock Times

| Parameter | Min | Max | Unit | Notes |
|------------------------|-----|-----|------|-------|
| Core PLL lock times | I | 100 | μs | - |
| Platform PLL lock time | - | 100 | μs | - |
| DDR PLL lock times | _ | 100 | μs | - |
| Enhanced local bus PLL | - | 100 | μs | - |

2.6 Power-on Ramp Rate

This section describes the AC electrical specifications for the power-on ramp rate requirements. Controlling the maximum Power-On Ramp Rate is required to avoid falsely triggering the ESD circuitry. Table 2-16 provides the power supply ramp rate specifications.

 Table 2-16.
 Power Supply Ramp Rate

| Parameter | Min | Max | Unit | Notes |
|--|-----|-------|-----------|--------|
| Required ramp rate for all voltage supplies (including OVDD/CVDD/ GVDD/BVDD/SVDD/LVDD, All VDD supplies, MVREF and all AVDD supplies.) | _ | 36000 | Volts/Sec | (1)(2) |

Notes: 1. Ramp rate is specified as a linear ramp from 10 to 90%. If non-linear (e.g. exponential), the maximum rate of change from 200 to 500 mV is the most critical as this range might falsely trigger the ESD circuitry.

2. Over full recommended operating temperature range Table 2-2.

2.7 DDR2 and DDR3 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface of the device. DDR2 and DDR3 share the same AC timing specifications. Note that DDR2 SDRAM is $GV_{DD}(typ) = 1.8V$ and DDR3 SDRAM is $GV_{DD}(typ) = 1.5V$.

2.7.1 DDR2 and DDR3 SDRAM Interface DC Electrical Characteristics

Table 2-17 provides the recommended operating conditions for the DDR SDRAM controller when interfacing to DDR2 SDRAM.

Table 2-17. DDR2 SDRAM DC Electrical Characteristics for $GV_{DD}(typ) = 1.8V^{(1)}$

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|---------------------------|---------------------------|------|-----------|
| I/O reference voltage | MV_REF | 0.49 × GV _{DD} | 0.51 × GV _{DD} | V | (2)(3)(4) |
| Input high voltage | V _{IH} | MV _{REF} + 0.125 | - | V | (5) |
| Input low voltage | V _{IL} | _ | MV _{REF} – 0.125 | V | (5) |
| Output high current (V _{OUT} = 1.370V) | I _{OH} | _ | -13.4 | mA | (6) |
| Output low current (V _{OUT} = 0.330V) | I _{OL} | 13.4 | _ | mA | (6) |
| Output leakage current | I _{OZ} | – 50 | 50 | μA | (7) |

Notes: 1. GV_{DD} is expected to be within 50 mV of the DRAM GV_{DD} at all times. The DRAM's and memory controller's voltage supply may or may not be from the same source.

- 2. MV_{REF} is expected to be equal to 0.5 × GV_{DD} and to track GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MV_{REF} may not exceed the MV_{REF} DC level by more than ±1% of GV_{DD} (for example, ±18 mV).
- 3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to MV_{REF}. This rail should track variations in the DC level of MV_{REF}.
- The voltage regulator for MVREFn must be able to supply up to 1500 μA.
- 5. Input capacitance load for DQ, DQS, and DQS are available in the IBIS models.
- 6. Refer to the IBIS model for the complete output IV curve characteristics.
- Output leakage is measured with all outputs disabled, 0V ≤ V_{OUT} ≤ GV_{DD}.

Table 2-18 provides the recommended operating conditions for the DDR SDRAM controller when interfacing to DDR3 SDRAM.

Table 2-18. DDR3 SDRAM Interface DC Electrical Characteristics for $GV_{DD}(typ) = 1.5V^{(1)}$

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|-----------------------|-----------------|---------------------------|---------------------------|------|-----------|
| I/O reference voltage | MV_REF | 0.49 × GV _{DD} | 0.51 × GV _{DD} | V | (2)(3)(4) |
| Input high voltage | V_{IH} | MV _{REF} + 0.100 | GV _{DD} | V | (5) |
| Input low voltage | V_{IL} | GND | MV _{REF} – 0.100 | V | (5) |
| I/O leakage current | I _{OZ} | -50 | 50 | μA | (6) |

- Notes: 1. GV_{DD} is expected to be within 50 mV of the DRAM's voltage supply at all times. The DRAM's and memory controller's voltage supply may or may not be from the same source.
 - 2. MV_{RFF} is expected to be equal to $0.5 \times GV_{DD}$ and to track GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MV_{REF} may not exceed the MV_{REF} DC level by more than ±1% of GV_{DD} (for example, ±15 mV).
 - 3. VTT is not applied directly to the device. It is the supply to which far end signal termination is made, and it is expected to be equal to MVREFn with a min value of MVREFn - 0.04 and a max value of MVREFn + 0.04. VTT should track variations in the DC level of MVREFn.
 - 4. The voltage regulator for MVREFn must be able to supply up to 125 µA current.
 - 5. Input capacitance load for DQ, DQS, and DQS are available in the IBIS models.
 - 6. Output leakage is measured with all outputs disabled, 0V ≤ VOUT ≤ GV_{DD}.

Table 2-19 provides the DDR Controller interface capacitance for DDR2 and DDR3.

DDR2 DDR3 SDRAM Capacitance for GV_{DD}(typ) = 1.8V and 1.5V

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|--|------------------|-----|-----|------|--------|
| Input/output capacitance: DQ, DQS, DQS | C _{IO} | 6 | 8 | pF | (1)(2) |
| Delta input/output capacitance: DQ, DQS, DQS | C _{DIO} | - | 0.5 | pF | (1)(2) |

Notes:

- 1. This parameter is sampled. GV_{DD} = 1.8V ± 0.1V (for DDR2), f = 1 MHz, T_A =25°C, V_{OUT} = GV_{DD} ÷ 2, V_{OUT} (peak-to-peak) = 0.2V.
- 2. This parameter is sampled. $GV_{DD} = 1.5V \pm 0.075V$ (for DDR3), f = 1 MHz, TA =25°C, $V_{OUT} = GV_{DD} \div 2$, V_{OUT} (peak-to-peak) = 0.150V.

Table 2-20 provides the current draw characteristics for MV_{REF} .

Table 2-20. Current Draw Characteristics for MV_{REF}

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|---|----------|-----|------|------|-------|
| Current draw for DDR2 SDRAM for MV _{REF} | MV_REF | - | 1500 | μA | (1) |
| Current draw for DDR3 SDRAM for MV _{REF} | MV_REF | _ | 1250 | μA | (1) |

Note: 1. The voltage regulator for MV_{REF} must be able to supply up to 1500 μA current.

2.7.2 DDR2 and DDR3 SDRAM Interface AC Timing Specifications

This section provides the AC timing specifications for the DDR SDRAM controller interface. The DDR controller supports both DDR2 and DDR3 memories. Note that the required $GV_{DD}(typ)$ voltage is 1.8V or 1.5V when interfacing to DDR2 or DDR3 SDRAM respectively.

2.7.2.1 DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications

Table 2-21, Table 2-22, and Table 2-23 provide the input AC timing specifications for the DDR controller.

Table 2-21. DDR2 SDRAM Input AC Timing Specifications for 1.8V Interface (At Recommended Operating Conditions, see Table 2-2)

| Parameter | | Symbol | Min | Max | Unit | Notes |
|-----------------------|----------------------|-------------------|--------------------------|--------------------------|------|-------|
| | > 533 Mbps data rate | V_{ILAC} | _ | MV _{REF} – 0.20 | V | _ |
| AC input low voltage | ≤ 533 Mbps data rate | | _ | MV _{REF} – 0.25 | | - |
| | > 533 Mbps data rate | V _{IHAC} | MV _{REF} + 0.20 | _ | V | _ |
| AC input high voltage | ≤ 533 Mbps data rate | | MV _{REF} + 0.25 | _ | | _ |

Table 2-22. DDR3 SDRAM Input AC Timing Specifications for 1.5V Interface (At Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------|----------|---------------------------|---------------------------|------|-------|
| AC input low voltage | V_{IL} | _ | MV _{REF} – 0.175 | V | _ |
| AC input high voltage | V_{IH} | MV _{REF} + 0.175 | _ | V | _ |

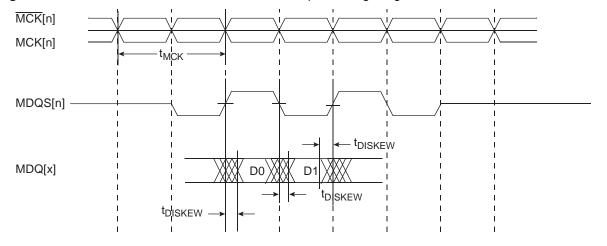
Table 2-23. DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications (At Recommended Operating Conditions, see Table 2-2)

| Parameter/Condition | Symbol | Min | Max | Unit | Notes |
|-----------------------------------|---------------------|--------------|------|------|--------|
| Controller Skew for MDQS-MDQ/MECC | | _ | - | ps | (1)(2) |
| 800 Mbps data rate | | -350 | -350 | ps | (1)(2) |
| 667 Mbps data rate | t _{CISKEW} | -390 | 390 | ps | (1)(2) |
| 533 Mbps data rate | | -450 | 450 | ps | (1)(2) |
| 400 Mbps data rate | | – 515 | 515 | ps | (1)(2) |
| Tolerated Skew for MDQS-MDQ/MECC | | _ | _ | ps | (1)(2) |
| 800 Mbps data rate | | -275 | 275 | ps | (1)(2) |
| 667 Mbps data rate | t _{DISKEW} | -360 | 360 | ps | (1)(2) |
| 533 Mbps data rate | | -488 | 488 | ps | (1)(2) |
| 400 Mbps data rate | | -735 | 735 | ps | (1)(2) |

Notes: 1. t_{CISKEW} represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit that is captured with MDQS[n]. This must be subtracted from the total timing budget.

Figure 2-2 shows the DDR2 and DDR3 SDRAM interface input timing diagram.

Figure 2-2. DDR2 and DDR3 SDRAM Interface Input Timing Diagram



^{2.} The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called t_{DISKEW} . This can be determined by the following equation: $t_{DISKEW} = \pm (T \div 4 - abs(t_{CISKEW}))$ where T is the clock period and $abs(t_{CISKEW})$ is the absolute value of t_{CISKEW} .

2.7.2.2 DDR2 and DDR3 SDRAM Interface Output AC Timing Specifications

Table 2-24 contains the output AC timing targets for the DDR SDRAM interface.

Table 2-24. DDR2 and DDR3 SDRAM Output AC Timing Specifications (At Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Notes |
|--|--|--------|-------|------|--------|
| MCK[n] cycle time | t _{MCK} | 2.5 | 5 | ns | (2) |
| ADDR/CMD output setup with respect to MCK | t _{DDKHAS} | | | ns | |
| 800 Mbps data rate | | 0.767 | _ | | (3)(7) |
| 667 Mbps data rate | | .950 | _ | | (3) |
| 533 Mbps data rate | | 1.33 | _ | | (3)(4) |
| 400 Mbps data rate | | 1.8 | _ | | (3)(4) |
| ADDR/CMD output hold with respect to MCK | t _{DDKHAX} | | | ns | |
| 800 Mbps data rate | | 0.767 | _ | | (3)(7) |
| 667 Mbps data rate | | .950 | _ | | (3) |
| 533 Mbps data rate | | 1.33 | _ | | (3)(4) |
| 400 Mbps data rate | | 1.8 | _ | | (3)(4) |
| MCS[n] output setup with respect to MCK | t _{DDKHCS} | | | ns | |
| 800 Mbps data rate | | 0.767 | _ | | (3)(7) |
| 667 Mbps data rate | | .950 | _ | | (3) |
| 533 Mbps data rate | | 1.33 | _ | | (3)(4) |
| 400 Mbps data rate | | 1.8 | _ | | (3)(4) |
| MCS[n] output hold with respect to MCK | t _{DDKHCX} | | | ns | |
| 800 Mbps data rate | | 0.767 | _ | | (3)(7) |
| 667 Mbps data rate | | .950 | _ | | (3) |
| 533 Mbps data rate | | 1.33 | _ | | (3)(4) |
| 400 Mbps data rate | | 1.8 | _ | | (3)(4) |
| MCK to MDQS Skew | t _{DDKHMH} | | | ns | |
| 800 Mbps data rate | | -0.525 | 0.525 | | (5)(7) |
| 667 Mbps data rate | | -0.600 | 0.600 | | (5) |
| 533 Mbps data rate | | -0.600 | 0.600 | | (4)(5) |
| 400 Mbps data rate | | -0.600 | 0.600 | | (4)(5) |
| MDQ/MECC/MDM output setup with respect to MDQS | t _{DDKHDS,} t _{DDKLDS} | | | ps | |
| 800 Mbps data rate | | 225 | _ | | (6)(7) |
| 667 Mbps data rate | | 300 | _ | | (6) |
| 533 Mbps data rate | | 388 | _ | | (4)(6) |
| 400 Mbps data rate | | 550 | _ | | (4)(6) |

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DDR2 and DDR3 SDRAM Output AC Timing Specifications (At Recommended Operating Conditions, see Table 2-24. Table 2-2) (Continued)

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Notes |
|---|--|------------------------|------------------------|------|--------|
| MDQ/MECC/MDM output hold with respect to MDQS | t _{DDKHDX,} t _{DDKLDX} | | | ps | |
| 800 Mbps data rate | | 225 | _ | | (6)(7) |
| 667 Mbps data rate | | 300 | - | | (6) |
| 533 Mbps data rate | | 388 | - | | (4)(6) |
| 400 Mbps data rate | | 550 | - | | (4)(6) |
| MDQS preamble | t _{DDKHMP} | 0.9 × t _{MCK} | _ | ns | - |
| MDQS postamble | t _{DDKHME} | 0.4 × t _{MCK} | 0.6 × t _{MCK} | ns | _ |

- Notes: 1. The symbols used for timing specifications follow the pattern of $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example, t_{DDKHAS} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also, t_{DDKLDX} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
 - 2. All MCK/MCK and MDQS/MDQS referenced measurements are made from the crossing of the two signals.
 - 3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ/MECC/MDM/MDQS.
 - 4. Note that minimum data rate for DDR3 is 667 MHz.
 - t_{DDKHMH} follows the symbol conventions described in note 1. For example, t_{DDKHMH} describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH). t_{DDKHMH} can be modified through control of the MDQS override bits (called WR DATA DELAY) in the TIMING CFG 2 register. This is typically set to the same delay as in DDR SDRAM CLK CNTL[CLK ADJUST]. The timing parameters listed in the table assume that these two parameters have been set to the same adjustment value. See the P2020 QorlQ Reference Manual for a description and understanding of the timing modifications enabled by use of these bits.
 - 6. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe must be centered inside of the data eye at the pins of the microprocessor.
 - 7. DDR3 only.

Note: For the ADDR/CMD setup and hold specifications in Table 2-24, it is assumed that the clock control register is set to adjust the memory clocks by ½ applied cycle.

Figure 2-3 shows the DDR2 and DDR3 SDRAM output timing for the MCK to MDQS skew measurement (t_{DDKHMH}) .

Figure 2-3. Timing Diagram for t_{DDKHMH}

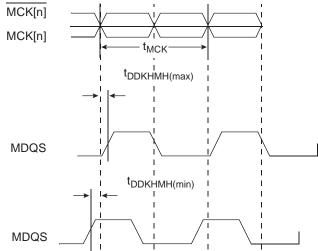


Figure 2-4 shows the DDR SDRAM output timing diagram.

Figure 2-4. DDR2 and DD3 SDRAM Output Timing Diagram

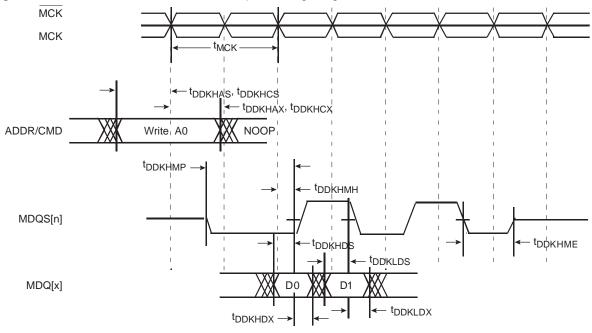
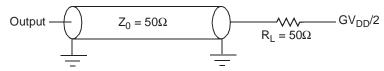


Figure 2-5 provides the AC test load for the DDR bus.

Figure 2-5. DDR AC Test Load



2.8 eSPI

This section describes the DC and AC electrical specifications for the eSPI.

2.8.1 eSPI DC Electrical Characteristics

Table 2-25 provides the DC electrical characteristics for the eSPI interface operating at CV_{DD} = 3.3V.

Table 2-25. SPI DC Electrical Characteristics (3.3V)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 2 | 1 | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.8 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±70 | μΑ | (2) |
| High-level output voltage (CV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | - | V | _ |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | - | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 2-2.

2. The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 "Recommended Operating Conditions" on page 26.

Table 2-26 provides the DC electrical characteristics for the eSPI interface operating at CV_{DD} = 2.5V.

Table 2-26. SPI DC Electrical Characteristics (2.5V)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 1.7 | _ | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.7 | ٧ | (1) |
| Input current (V _{IN} = 0V or V _{IN} = CV _{DD}) | I _{IN} | - | ±70 | μA | (2) |
| High-level output voltage ($CV_{DD} = min, I_{OH} = -1 mA$) | V _{OH} | 2.0 | _ | V | _ |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 1 mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table

2. The symbol V_{IN} , in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 on page 26.

Table 2-27 provides the DC electrical characteristics for the eSPI interface operating at CV_{DD} = 1.8V.

Table 2-27. SPI DC Electrical Characteristics (1.8V)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|------|-----|------|------|
| High-level input voltage | V _{IH} | 1.25 | _ | V | (1) |
| Low-level input voltage | V _{IL} | _ | 0.6 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±70 | μA | (2) |
| High-level output voltage (CV _{DD} = min, I _{OH} = -0.5 mA) | V _{OH} | 1.35 | _ | V | _ |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 0.5 mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 on page 26.

2.8.2 eSPI AC Timing Specifications

Table 2-28 provides the eSPI input and output AC timing specifications.

Table 2-28. eSPI AC Timing Specifications⁽¹⁾

| Characteristic | Symbol | Min | Max | Unit | Note |
|--|--|------------|-----------|------|-----------|
| SPI_MOSI output—Master data (internal clock) hold time | t _{NIKHOX} t _{NIKHOX} | 0.5 3.0 | - - | ns | (1)(2)(3) |
| SPI_MOSI output—Master data (internal clock) delay | t _{NIKHOV} t _{NIKHOV} | _ | 6.0 10 | ns | (1)(2)(3) |
| SPI_CS outputs—Master data (internal clock) hold time | t _{NIKHOX2} | 0 | _ | ns | (1)(2) |
| SPI_CS outputs—Master data (internal clock) delay | t _{NIKHOV2} | _ | 6.0 | ns | (1)(2) |
| SPI inputs—Master data (internal clock) input setup time | t _{NIIVKH} | 5.75 | _ | ns | (4) |
| SPI inputs—Master data (internal clock) input hold time | t _{NIIXKH} | 0 | _ | ns | (4) |

Notes: 1. Output specifications are measured from the 50% level of the CLK to the 50% level of the signal. Timings are measured at the pin.

- 2. The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).
- The greater of the two output timings for t_{NIKHOX} and t_{NIKHOV} are used when the SPCOM[RxDelay] bit of eSPI Command Register is set. For example, the t_{NIKHOX} is 3.0ns and t_{NIKHOV} is 10ns if SPCOM[RxDelay] is set.
- 4. For Windbond Flash dual-output mode both SPI_MOSI and SPI_MISO are inputs.

Figure 2-6 provides the AC test load for the eSPI.

Figure 2-6. eSPI AC Test Load

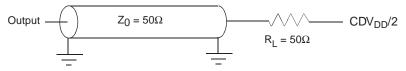
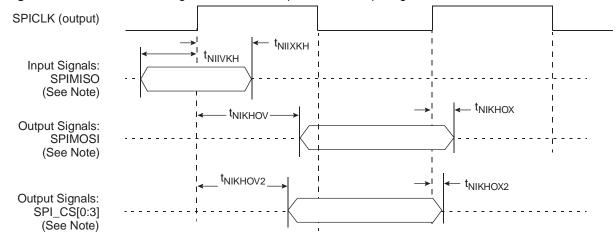


Figure 2-7 represents the AC timing from Table 2-28. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 2-7 shows the eSPI timing in master mode (internal clock).

Figure 2-7. eSPI AC Timing in Master Mode (Internal Clock) Diagram



Note: The clock edge is selectable on eSPI.

2.9 DUART

This section describes the DC and AC electrical specifications for the DUART interface of the device.

2.9.1 DUART DC Electrical Characteristics

Table 2-29 provides the DC electrical characteristics for the DUART interface.

Table 2-29. DUART DC Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Note |
|--|-----------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 2 | - | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.8 | V | (1) |
| Input current (OV _{IN} = GND or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μA | (2) |
| High-level output voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | |
| Low-level output voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 2-2.

2. The symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 2-1 and Table 2-2.

2.9.2 DUART AC Electrical Specifications

Table 2-30 provides the AC timing parameters for the DUART interface.

Table 2-30. DUART AC Timing Specifications

| Parameter | Value | Unit | Notes |
|-------------------|---------------------|------|--------|
| Minimum baud rate | CCB clock/1,048,576 | baud | (1) |
| Maximum baud rate | CCB clock/16 | baud | (1)(2) |

Notes: 1. CCB clock refers to the platform clock.

2. The actual attainable baud rate is limited by the latency of interrupt processing.

2.10 Ethernet: Enhanced Three-Speed Ethernet (eTSEC), MII Management

This section provides the AC and DC electrical characteristics for enhanced three-speed Ethernet controller, and MII management.

2.10.1 Enhanced Three-Speed Ethernet Controller (eTSEC) (10/100/1000 Mbps) – GMII/SGMII/MII/TBI/RGMII/RTBI/RMII Electrical Characteristics

The electrical characteristics specified here apply to the following interfaces:

- All gigabit media independent interface (GMII)
- Serial gigabit media independent interface (SGMII)
- Media independent interface (MII)
- Ten-bit interface (TBI)
- · Reduced gigabit media independent interface (RGMII)
- Reduced ten-bit interface (RTBI)
- Reduced media independent interface (RMII) signals except management data input/output (MDIO) and management data clock (MDC).

The RGMII and RTBI interfaces are defined for 2.5V, while the GMII, MII, RMII, and TBI interfaces can be operated at 3.3 or 2.5V. Whether the GMII, MII, or TBI interface is operated at 3.3 or 2.5V, the timing is compliant with IEEE Std 802.3[™].

The interfaces conform to specifications, as follows:

- SGMII interfaces conform (with exceptions) to the Serial Gigabit Media-Independent Interface (SGMII) Specification, Version 1.8.
- RGMII and RTBI interfaces conform to the *Reduced Gigabit Media-Independent Interface (RGMII)* Specification, Version 1.3 (12/10/2000).
- The RMII interface conforms to the RMII Consortium RMII Specification, Version 1.2 (3/20/1998).

The electrical characteristics for MDIO and MDC are specified in Section 2.10.7 "Ethernet Management Interface Electrical Characteristics" on page 60.

2.10.1.1 GMII, MII, TBI, RGMII, RMII, and RTBI DC Electrical Characteristics

All GMII, MII, TBI, RGMII, RMII, and RTBI drivers and receivers comply with the DC parametric attributes specified in Table 2-31 and Table 2-32. The RGMII and RTBI signals are based on a 2.5-V CMOS interface voltage as defined by JEDEC EIA/JESD8-5.

Table 2-31. IEEE 1588, GMII, MII, RMII, and TBI DC Electrical Characteristics at LV_{DD} = 3.3V

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|------|------|-------|
| Output high voltage (LV _{DD} = min, $I_{OH} = -4.0 \text{ mA}$) | V _{OH} | 2.40 | - | V | _ |
| Output low voltage (LV _{DD} = min, I _{OL} = 4.0 mA) | V _{OL} | - | 0.40 | V | _ |
| Input high voltage (IEEE 1588, MII, RMII and TBI) | V _{IH} | 2.0 | 1 | ٧ | - |
| Input high voltage (GMII) | V _{IH} | 1.90 | _ | V | - |
| Input low voltage | V _{IL} | _ | 0.90 | V | - |
| Input high current (V _{IN} = LV _{DD}) | I _{IH} | - | 40 | μΑ | (1) |
| Input low current (V _{IN} = GND) | I _{IL} | -40 | - | μΑ | (1) |

Note: 1. The symbol V_{IN}, in this case, represents the LV_{IN} symbols referenced in Table 2-1 and Table 2-2.

Table 2-32. IEEE 1588, GMII, MII, RMII, RGMII, RTBI, and TBI DC Electrical Characteristics at LV_{DD} = 2.5V

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|------|------|-------|
| Output high voltage (LV _{DD} = min, I _{OH} = -1.0 mA) | V _{OH} | 2.00 | - | V | _ |
| Output low voltage (LV _{DD} = min, I _{OL} = 1.0 mA) | V _{OL} | _ | 0.40 | V | _ |
| Input high voltage | V _{IH} | 1.70 | 1 | V | _ |
| Input low voltage | V _{IL} | _ | 0.70 | V | _ |
| Input high current (V _{IN} = LV _{DD}) | I _{IH} | _ | 40 | μA | _ |
| Input low current (V _{IN} = GND) | I _{IL} | -40 | - | μA | (1) |

Note: 1. The symbol V_{IN} , in this case, represents the LV_{IN} symbols referenced in Table 2-1 and Table 2-2.

2.10.2 GMII, MII, TBI, RGMII, RMII, and RTBI AC Timing Specifications

The AC timing specifications for GMII, MII, TBI, RGMII, RMII, and RTBI are presented in this section.

2.10.2.1 GMII AC Timing Specifications

This section describes the GMII transmit and receive AC timing specifications.

1. GMII Transmit AC Timing Specifications

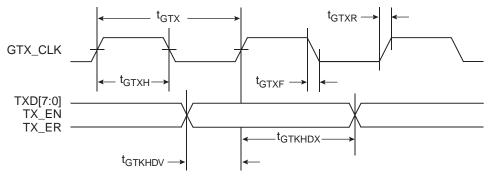
Table 2-33 provides the GMII transmit AC timing specifications.

Table 2-33. GMII Transmit AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|---|---------------------|-----|-----|-----|------|------|
| GTX_CLK clock period | t _{GTX} | _ | 8.0 | - | ns | - |
| GMII data TXD[7:0], TX_ER, TX_EN setup time | t _{GTKHDV} | 2.5 | _ | _ | ns | _ |
| GTX_CLK to GMII data TXD[7:0], TX_ER, TX_EN delay | t _{GTKHDX} | 0.5 | _ | 5.5 | ns | (1) |
| GTX_CLK data clock rise time (20%–80%) | t _{GTXR} | _ | _ | 1.0 | ns | _ |
| GTX_CLK data clock fall time (80%–20%) | t _{GTXF} | _ | _ | 1.0 | ns | _ |

Note: 1. Data valid minimum setup time, t_{atkhdv}, is a function of clock and maximum hold time (min setup = cycle time – max delay).

Figure 2-8. GMII Transmit AC Timing Diagram



2. GMII Receive AC Timing Specifications

Table 2-34 provides the GMII receive AC timing specifications.

Table 2-34. GMII Receive AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|---|-------------------------------------|-----|-----|-----|------|------|
| RX_CLK clock period | t _{GRX} | 7.5 | _ | - | ns | (1) |
| RX_CLK duty cycle | t _{GRXH} /t _{GRX} | 35 | _ | 65 | % | (2) |
| RXD[7:0], RX_DV, RX_ER setup time to RX_CLK | t _{GRDVKH} | 2.0 | _ | _ | ns | _ |
| RXD[7:0], RX_DV, RX_ER hold time to RX_CLK | t _{GRDXKH} | 0 | _ | _ | ns | _ |
| RX_CLK clock rise (20%–80%) | t _{GRXR} | - | _ | 1.0 | ns | (2) |
| RX_CLK clock fall time (80%–20%) | t _{GRXF} | - | _ | 1.0 | ns | (2) |

Notes: 1. The frequency of RX_CLK should not exceed frequency of gigabit Ethernet reference clock by more than 300 ppm.

2. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.

Figure 2-9 provides the AC test load for eTSEC.

Figure 2-9. eTSEC AC Test Load

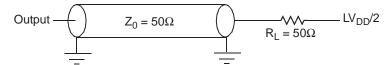
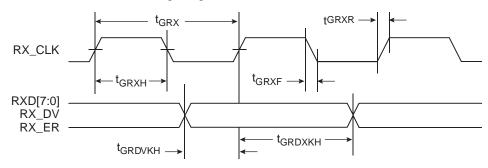


Figure 2-10 shows the GMII receive AC timing diagram.

Figure 2-10. GMII Receive AC Timing Diagram



2.10.2.2 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

1. MII Transmit AC Timing Specifications

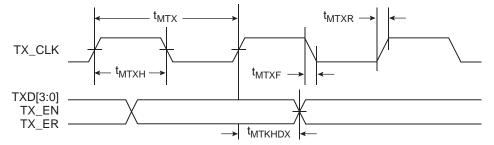
Table 2-35 provides the MII transmit AC timing specifications.

 Table 2-35.
 MII Transmit AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit |
|---|---------------------|-----|-----|-----|------|
| TX_CLK clock period 10 Mbps | t _{MTX} | ı | 400 | _ | ns |
| TX_CLK clock period 100 Mbps | t _{MTX} | - | 40 | _ | ns |
| TX_CLK duty cycle | t_{MTXH}/t_{MTX} | 35 | - | 65 | % |
| TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay | t _{MTKHDX} | 1 | 5 | 15 | ns |
| TX_CLK data clock rise (20%–80%) | t _{MTXR} | 1.0 | _ | 4.0 | ns |
| TX_CLK data clock fall (80%–20%) | t _{MTXF} | 1.0 | - | 4.0 | ns |

Figure 2-11 shows the MII transmit AC timing diagram.

Figure 2-11. MII Transmit AC Timing Diagram



2. MII Receive AC Timing Specifications

Table 2-36 provides the MII receive AC timing specifications.

Table 2-36. MII Receive AC Timing Specifications

| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Note |
|---|-------------------------------------|------|-----|-----|------|------|
| RX_CLK clock period 10 Mbps | t _{MRX} | _ | 400 | _ | ns | (1) |
| RX_CLK clock period 100 Mbps | t _{MRX} | _ | 40 | _ | ns | (1) |
| RX_CLK duty cycle | t _{MRXH} /t _{MRX} | 35 | _ | 65 | % | (2) |
| RXD[3:0], RX_DV, RX_ER setup time to RX_CLK | t _{MRDVKH} | 10.0 | _ | _ | ns | _ |
| RXD[3:0], RX_DV, RX_ER hold time to RX_CLK | t _{MRDXKH} | 10.0 | _ | _ | ns | _ |
| RX_CLK clock rise (20%–80%) | t _{MRXR} | 1.0 | _ | 4.0 | ns | (2) |
| RX_CLK clock fall time (80%–20%) | t _{MRXF} | 1.0 | _ | 4.0 | ns | (2) |

- Notes: 1. The frequency of RX_CLK should not exceed the frequency of TX_CLK by more than 300 ppm.
 - 2. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.

Figure 2-12 provides the AC test load for eTSEC.

Figure 2-12. eTSEC AC Test Load

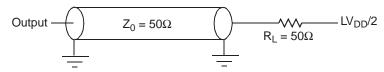
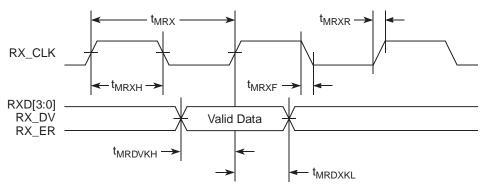


Figure 2-13 shows the MII receive AC timing diagram.

Figure 2-13. MII Receive AC Timing Diagram



2.10.2.3 TBI AC Timing Specifications

This section describes the TBI transmit and receive AC timing specifications.

1. TBI Transmit AC Timing Specifications

Table 2-37 provides the TBI transmit AC timing specifications.

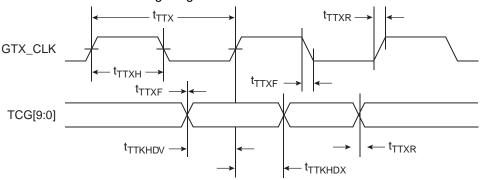
Table 2-37. TBI Transmit AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|--|---------------------|-----|-----|-----|------|------|
| GTX_CLK clock period | t _{GTX} | ı | 8.0 | ı | ns | 1 |
| TCG[9:0] setup time GTX_CLK going high | t _{TTKHDV} | 2.0 | _ | _ | ns | _ |
| GTX_CLK to TCG[9:0] delay time | t _{TTKHDX} | 1.0 | - | 5.0 | ns | (1) |
| GTX_CLK rise (20%–80%) | t _{TTXZ} | 0.7 | - | 1.0 | ns | _ |
| GTX_CLK fall time (80%–20%) | t _{TTXF} | 0.7 | _ | 1.0 | ns | _ |

Note: 1. Data valid t_{TTKHDV} to GTX_CLK minimum setup time is a function of clock and maximum hold time (min setup = cycle time – max delay).

Figure 2-14 shows the TBI transmit AC timing diagram.

Figure 2-14. TBI Transmit AC Timing Diagram



2. TBI Receive AC Timing Specifications

Table 2-38 provides the TBI receive AC timing specifications.

Table 2-38. TBI Receive AC Timing Specifications

| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Note |
|---|---------------------|-----|------|-----|------|------|
| TSECn_RX_CLK[0:1] clock period | t _{TRX} | _ | 16.0 | ı | ns | (1) |
| TSECn_RX_CLK[0:1] skew | t _{SKTRX} | 7.5 | _ | 8.5 | ns | ı |
| TSECn_RX_CLK[0:1] duty cycle | t_{TRXH}/t_{TRX} | 40 | _ | 60 | % | (2) |
| RCG[9:0] setup time to rising PMA_RX_CLK | t _{TRDVKH} | 2.5 | _ | - | ns | - |
| RCG[9:0] hold time to rising PMA_RX_CLK | t _{TRDXKH} | 1.5 | _ | ı | ns | ı |
| TSECn_RX_CLK[0:1] clock rise time (20%–80%) | t _{TRXR} | 0.7 | _ | 2.4 | ns | (2) |
| TSECn_RX_CLK[0:1] clock fall time (80%–20%) | t _{TRXF} | 0.7 | _ | 2.4 | ns | (2) |

Notes: 1. The frequency of RX_CLK should not exceed the frequency of TX_CLK by more than 300 ppm.

2. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.

Figure 2-15 shows the TBI receive AC timing diagram.

TSEC n_RX_CLK1 RCG[9:0]

Valid Data t_{TRXH} t_{TRXF} t_{TRXF} t_{TRXH} t_{TRXF} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH} t_{TRXH}

Figure 2-15. TBI Receive AC Timing Diagram

2.10.2.4 TBI Single-Clock Mode AC Specifications

When the eTSEC is configured for TBI modes, all clocks are supplied from external sources to the relevant eTSEC interface. In single-clock TBI mode, when a 125-MHz TBI receive clock is supplied on the TSECn pin (no receive clock is used in this mode, whereas for the dual-clock mode this is the PMA1 receive clock). The 125-MHz transmit clock is applied in all TBI modes.

tTRDVKH

A summary of the single-clock TBI mode AC specifications for receive is shown in Table 2-39.

| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Note |
|---|--------------------|-----|-----|-----|------|------|
| RX_CLK clock period | t _{TRR} | 7.5 | 8.0 | 8.5 | ns | (1) |
| RX_CLK duty cycle | t _{TRRH} | 40 | 50 | 60 | % | (2) |
| Rise time RX_CLK (20%–80%) | t _{TRRR} | _ | _ | 1.0 | ns | _ |
| Fall time RX_CLK (80%–20%) | t _{TRRF} | _ | _ | 1.0 | ns | _ |
| RCG[9:0] setup time to RX_CLK rising edge | t _{TRRDV} | 2.0 | _ | _ | ns | (2) |
| RCG[9:0] hold time to RX_CLK rising edge | t _{TRRDX} | 1.0 | _ | _ | ns | (2) |

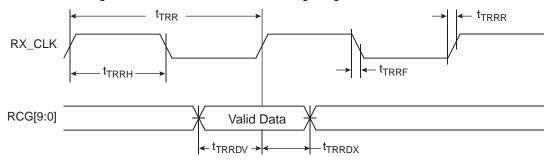
Table 2-39. TBI Single-Clock Mode Receive AC Timing Specifications

Notes:

- 1. The frequency of RX_CLK should not exceed the frequency of TX_CLK by more than 300 ppm.
- System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.

A timing diagram for TBI receive appears in Figure 2-16.

Figure 2-16. TBI Single-Clock Mode Receive AC Timing Diagram



2.10.2.5 RGMII and RTBI AC Timing Specifications

Table 2-39 presents the RGMII and RTBI AC timing specifications.

Table 2-40. RGMII and RTBI AC Timing Specifications

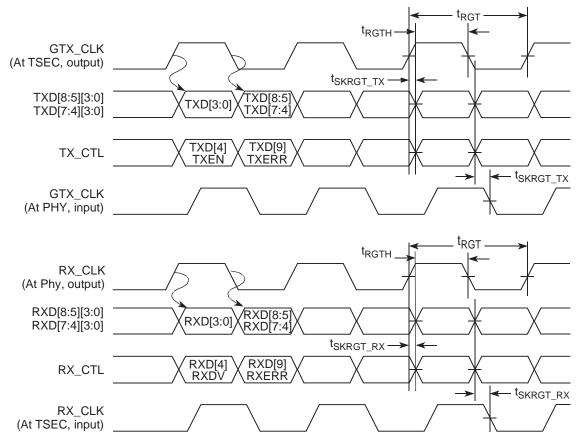
| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|--|-------------------------------------|------|-----|------|------|--------|
| Data to clock output skew (at transmitter) | t _{SKRGT_TX} | -500 | 0 | 500 | ps | (5) |
| Data to clock input skew (at receiver) | t _{SKRGT_RX} | 1.0 | _ | 2.8 | ns | (1) |
| Clock period duration | t _{RGT} | 7.2 | 8.0 | 8.8 | ns | (2) |
| Duty cycle for 10BASE-T and 100BASE-TX | t _{RGTH} /t _{RGT} | 40 | 50 | 60 | % | (2)(3) |
| Duty cycle for Gigabit | t _{RGTH} /t _{RGT} | 45 | 50 | 55 | % | 1 |
| Rise time (20%–80%) | t _{RGTR} | _ | _ | 0.75 | ns | (4) |
| Fall time (20%–80%) | t _{RGTF} | _ | _ | 0.75 | ns | (4) |

Notes: 1. This implies that PC board design requires clocks to be routed such that an additional trace delay of greater than 1.5 ns is added to the associated clock signal.

- 2. For 10 and 100 Mbps, t_{RGT} scales to 400 ns \pm 40 ns and 40 ns \pm 4 ns, respectively.
- 3. Duty cycle may be stretched/shrunk during speed changes or while transitioning to a received packet's clock domain as long as the minimum duty cycle is not violated and stretching occurs for no more than three t_{RGT} of the lowest speed transitioned between.
- 4. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.
- 5. The frequency of RX_CLK should not exceed the frequency of gigabit Ethernet reference clock by more than 300 ppm.

Figure 2-17 shows the RGMII and RTBI AC timing and multiplexing diagrams.

Figure 2-17. RGMII and RTBI AC Timing and Multiplexing Diagrams



2.10.2.6 RMII AC Timing Specifications

This section describes the RMII transmit and receive AC timing specifications.

1. RMII Transmit AC Timing Specifications

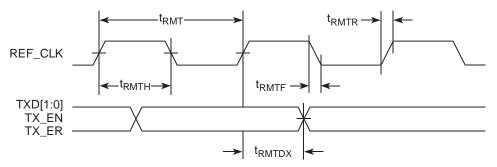
The RMII transmit AC timing specifications are in Table 2-41.

Table 2-41. RMII Transmit AC Timing Specifications

| Parameter/Condition | Symbol | Min | Тур | Max | Unit |
|---|--------------------|------|------|------|------|
| TSECn_TX_CLK (reference clock) clock period | t _{RMT} | 15.0 | 20.0 | 25.0 | ns |
| TSECn_TX_CLK duty cycle | t _{RMTH} | 35 | 50 | 65 | % |
| Rise time TSECn_TX_CLK (20%–80%) | t _{RMTR} | 1.0 | _ | 2.0 | ns |
| Fall time TSECn_TX_CLK (80%–20%) | t _{RMTF} | 1.0 | - | 2.0 | ns |
| TSECn_TX_CLK to RMII data TXD[1:0], TX_EN delay | t _{RMTDX} | 2.0 | _ | 10.0 | ns |

Figure 2-18 shows the RMII transmit AC timing diagram.

Figure 2-18. RMII Transmit AC Timing Diagram



2. RMII Receive AC Timing Specifications

Table 2-42 lists the RMII receive AC timing specifications.

Table 2-42. RMII Receive AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|---|--------------------|------|------|------|------|------|
| TSECn_TX_CLK (reference clock) clock period | t _{RMR} | 15.0 | 20.0 | 25.0 | ns | _ |
| TSECn_TX_CLK duty cycle | t _{RMRH} | 35 | 50 | 65 | % | (2) |
| Rise time TSECn_TX_CLK (20%–80%) | t _{RMRR} | 1.0 | _ | 4.0 | ns | (2) |
| Fall time TSECn_TX_CLK (80%–20%) | t _{RMRF} | 1.0 | _ | 4.0 | ns | (2) |
| RXD[1:0], CRS_DV, RX_ER setup time to TSEC <i>n</i> _TX_CLK rising edge | t _{RMRDV} | 4.0 | _ | ı | ns | - |
| RXD[1:0], CRS_DV, RX_ER hold time to TSECn_TX_CLK rising edge | t _{RMRDX} | 2.0 | _ | - | ns | _ |

Notes: 1. The frequency of RX_CLK should not exceed the frequency of gigabit Ethernet reference clock by more than 300 ppm.

2. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.

Figure 2-19 provides the AC test load for eTSEC.

Figure 2-19. eTSEC AC Test Load

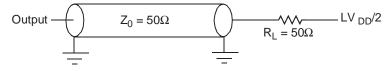
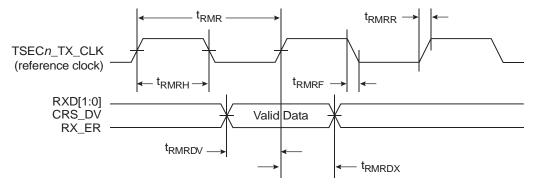


Figure 2-20 shows the RMII receive AC timing diagram.

Figure 2-20. RMII Receive AC Timing Diagram



2.10.3 SGMII Interface Electrical Characteristics

Each SGMII port features a 4-wire AC-Coupled serial link from the SerDes interface of device, as shown in Figure 2-21, where C_{TX} is the external (on board) AC-Coupled capacitor. Each output pin of the SerDes transmitter differential pair features 50Ω output impedance. Each input of the SerDes receiver differential pair features 50Ω on-die termination to SGND_SRDS2 (xcorevss). The reference circuit of the SerDes transmitter and receiver is shown in Figure 2-51.

2.10.3.1 DC Requirements for SGMII SD_REF_CLK and SD_REF_CLK

The characteristics and DC requirements of the separate SerDes reference clock are described in Section 2.18.2.3 "DC Level Requirement for SerDes Reference Clocks" on page 85.

2.10.3.2 AC Requirements for SGMII SD_REF_CLK and SD_REF_CLK

Note that the SGMII clock requirements for SD_REF_CLK and SD_REF_CLK are intended to be used within the clocking guidelines specified by Section 2.18.3 "AC Requirements for PCI Express SerDes Reference Clocks" on page 87.

2.10.4 SGMII Transmitter Electrical Characteristics

2.10.4.1 SGMII Transmit DC Timing Specifications

Table 2-43 and Table 2-44 describe the SGMII SerDes transmitter and receiver AC-Coupled DC electrical characteristics. Transmitter DC characteristics are measured at the transmitter outputs (SD_TX[n] and SD_TX[n]) as shown in Figure 2-22.

Table 2-43. SGMII DC Transmitter Electrical Characteristics

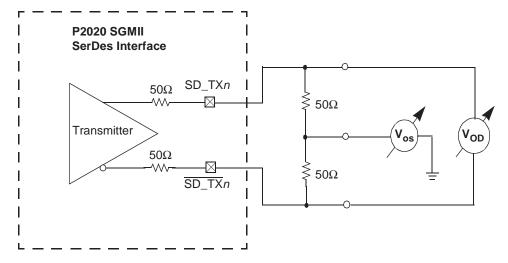
| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|--|-----------------|--|-----|---|------|-----------------------------|
| Output high voltage | V _{OH} | - | 1 | $XV_{DD_SRDS-Typ}/2 + V_{OD} _{-max}/2$ | mV | (1) |
| Output low voltage | V _{OL} | $XV_{DD_SRDS-Typ}/2 - V_{OD} _{max}/2$ | - | - | mV | (1) |
| | | 342 | 525 | 756 | | Equalization setting: 1.0× |
| | | 313 | 481 | 693 | | Equalization setting: 1.09× |
| | | 285 | 437 | 630 | | Equalization setting: 1.2× |
| Output differential voltage ⁽²⁾⁽³⁾⁽⁴⁾ (XV _{DD-Typ} at 1.05V) | | 257 | 394 | 568 | | Equalization setting: 1.33× |
| (ББ-Тур | | 228 | 350 | 504 | | Equalization setting: 1.5× |
| | V _{OD} | 200 | 307 | 442 | mV | Equalization setting: 1.71× |
| | | 171 | 262 | 378 | | Equalization setting: 2.0× |
| Output impedance (single-ended) | Ro | 40 | 50 | 60 | Ω | _ |

Notes: 1. This does not align to DC-coupled SGMII. $XV_{DD_SRDS2-Typ}$ = 1.05V.

- 2. $|VOD| = |VSDn_TXn V_{\overline{SDn} TXn}|$. |VOD| is also referred to as output differential peak voltage. $V_{TX-DIFFp-p} = 2 \times \square |VOD|$.
- 3. The |Vop| value shown in the table assumes the following transmit equalization setting in the TXEQ0/1 (for SerDes lanes 0 and 1) or TXEQ2/3 (for SerDes lanes 2 and 3) bit field of device's SerDes Control Register:
 - The MSB (bit 0) of the above bit field is cleared (selecting the full $V_{DD\text{-}DIFF\text{-}p\text{-}p}$ amplitude power up default).
 - The LSB (bit [1:3]) of the above bit field is set based on the equalization setting shown in table.
- 4. The |VoD| value shown in the Typ column is based on the condition of $XV_{DD_SRDS-Typ} = 1.05V$, no common mode offset variation (Vos = 500 mV), SerDes transmitter is terminated with 100Ω differential load between SD_TX[n] and SD_TX[n].

Figure 2-21. 4-Wire AC-Coupled SGMII Serial Link Connection Example

Figure 2-22. SGMII Transmitter DC Measurement Circuit



2.10.4.2 SGMII DC Receiver Timing Specification

Table 2-44 lists the SGMII DC receiver electrical characteristics. Source synchronous clocking is not supported. Clock is recovered from the data.

Table 2-44. SGMII DC Receiver Electrical Characteristics

| Parameter | | Symbol | Min | Тур | Max | Unit | Notes |
|-----------------------------|------------|----------------------|-----|-----|------|------|--------|
| DC Input voltage range | | - | | N/A | | - | (1) |
| lancet differential values | LSTS = 001 | V | 100 | _ | 1200 | \ | (2)(3) |
| Input differential voltage | LSTS = 100 | $V_{RX_DIFFp-p}$ | 175 | - | 1200 | mV | (=)(=) |
| | LSTS = 001 | \/I OC | 30 | - | 100 | \/ | (3)(4) |
| Loss of signal threshold | LSTS = 100 | VLOS | 65 | - | 175 | mV | |
| Receiver differential input | impedance | Z _{RX_DIFF} | 80 | _ | 120 | Ω | _ |

Notes: 1. Input must be externally AC-coupled.

- 2. $V_{\text{RX DIFFp-p}}$ is also referred to as peak-to-peak input differential voltage.
- The LSTS shown in the table refers to the LSTS2 or LSTS3 bit field of device's SerDes Control Register SRDSCR4.
- 4. The concept of this parameter is equivalent to the Electrical Idle Detect Threshold parameter in PCI Express. Refer to PCI Express Differential Receiver (Rx) Input Specifications section for further explanation.

2.10.5 SGMII AC Timing Specifications

This section discusses the AC timing specifications for the SGMII interface.

2.10.5.1 SGMII Transmit AC Timing Specifications

Table 2-45 provides the SGMII transmit AC timing specifications. A source synchronous clock is not supported. The AC timing specifications do not include RefClk jitter.

Table 2-45. SGMII Transmit AC Timing Specifications (At Recommended Operating Conditions with $XV_{DD\ SRDS2} = 1.1V \pm 5\%$)

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|-----------------------|-----------------|--------|-----|--------|--------|-------|
| Deterministic Jitter | JD | - | - | 0.17 | UI p-p | _ |
| Total Jitter | JT | - | - | 0.35 | UI p-p | (1) |
| Unit Interval | UI | 799.92 | 800 | 800.08 | ps | (2) |
| AC coupling capacitor | C _{TX} | 10 | 100 | 200 | nF | (3) |

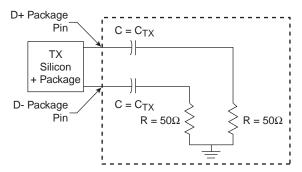
Notes: 1. See Figure 2-54 for single frequency sinusoidal jitter limits.

- 2. Each UI is 800 ps ± 100 ppm.
- 3. The external AC coupling capacitor is required. It is recommended that it be placed near the device transmitter outputs.

2.10.6 SGMII AC Measurement Details

<u>Transmitter</u> and receiver AC characteristics are measured at the transmitter outputs (SD_TX[n] and SD_TX[n]) or at the receiver inputs (SD_RX[n] and SD_RX[n]) as depicted in Figure 2-23, respectively.

Figure 2-23. SGMII AC Test/Measurement Load



2.10.6.1 SGMII Receiver AC Timing Specification

Table 2-46 provides the SGMII receiver AC timing specifications. The AC timing specifications do not include RefClk jitter.

Table 2-46. SGMII Receive AC Timing Specifications (At Recommended Operating Conditions with $XV_{DD_SRDS2} = 1.1V \pm 5\%$)

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|--|--------|--------|--------|-------------------|--------|--------|
| Deterministic Jitter Tolerance | JD | 0.37 | _ | _ | UI p-p | (1)(2) |
| Combined Deterministic and Random Jitter Tolerance | JDR | 0.55 | _ | _ | UI p-p | (1)(2) |
| Total Jitter Tolerance | JT | 0.65 | _ | _ | UI p-p | (1)(2) |
| Bit Error Ratio | BER | _ | _ | 10 ⁻¹² | _ | _ |
| Unit Interval | UI | 799.92 | 800.00 | 800.08 | ps | (3) |

Notes: 1. Measured at receiver.

- 2. Refer to RapidIO[™] 1×/4× LP Serial Physical Layer Specification for interpretation of jitter specifications.
- 3. Each UI is 800 ps ± 100 ppm.

The sinusoidal jitter in the total jitter tolerance may have any amplitude and frequency in the unshaded region of Figure 2-24.

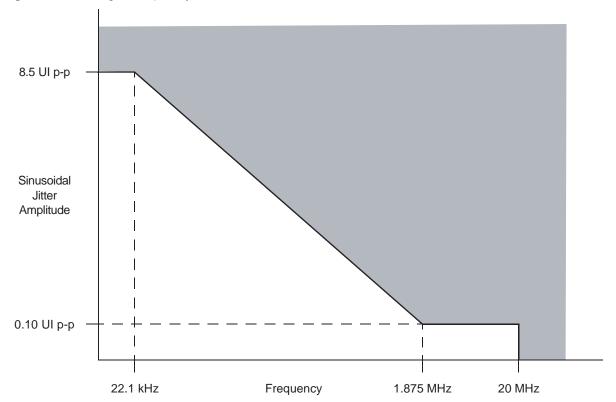


Figure 2-24. Single Frequency Sinusoidal Jitter Limits

2.10.7 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals MDIO (management data input/output) and MDC (management data clock). The electrical characteristics for GMII, RGMII, RMII, TBI, and RTBI are specified in Section 2.10.1 "Enhanced Three-Speed Ethernet Controller (eTSEC) (10/100/1000 Mbps) –GMII/SGMII/MII/TBI/RGMII/RTBI/RMII Electrical Characteristics" on page 45.

2.10.7.1 MII Management DC Electrical Characteristics

The MDC and MDIO are defined to operate at a supply voltage of 3.3V or 2.5V. The DC electrical characteristics for MDIO and MDC are provided in Table 2-47 and Table 2-48.

Table 2-47 provides the electrical characteristics at 3.3V.

Table 2-47. MII Management DC Electrical Characteristics ($LV_{DD} = 3.3V$)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|------|------|-------|
| Input high voltage | V _{IH} | 2.0 | - | V | (1) |
| Input low voltage | V _{IL} | - | 0.90 | V | (1) |
| Input high current (LV _{DD} = Max, V_{IN} = 2.1V) | I _{IH} | _ | 40 | μA | (2) |
| Input low current (LV _{DD} = Max, V_{IN} = 0.5V) | I _{IL} | -40 | ı | μA | _ |
| Output high voltage (LV _{DD} = min, I_{OH} = -1.0 mA) | V _{OH} | 2.10 | _ | V | _ |
| Output low voltage (LV _{DD} = min, I _{OL} = 1.0 mA) | V _{OL} | _ | 0.50 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max LV_{IN} values found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 2-1.

Table 2-48 shows the electrical characteristics at 2.5V.

Table 2-48. MII Management DC Electrical Characteristics ($LV_{DD} = 2.5V$)

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----------------|------|------|-------|
| Input high voltage | V_{IH} | 1.70 | _ | V | (1) |
| Input low voltage | V _{IL} | - | 0.70 | V | (1) |
| Input high current (V _{IN} = LV _{DD}) | I _{IH} | ı | 40 | μΑ | (2) |
| Input low current (V _{IN} = GND) | I _{IL} | -4 0 | _ | μΑ | _ |
| Output high voltage (LV _{DD} = min, I_{OH} = -1.0 mA) | V _{OH} | 2.00 | - | V | - |
| Output low voltage (LV _{DD} = min, I_{OL} = 1.0 mA) | V _{OL} | _ | 0.40 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max LV_{IN} values found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the LV_{IN} symbol referenced in Table 2-1.

2.10.7.2 MII Management AC Electrical Specifications

Table 2-49 provides the MII management AC timing specifications.

Table 2-49. MII Management AC Timing Specifications

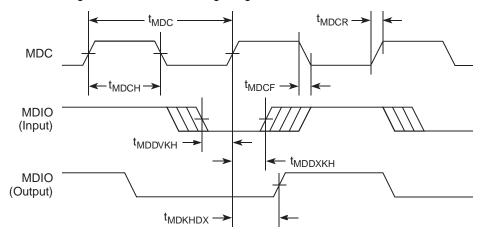
| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Notes |
|----------------------------|---------------------|---|-----|----------------------------------|------|-----------|
| MDC frequency | f _{MDC} | - | 2.5 | - | MHz | (1) |
| MDC period | t _{MDC} | - | 400 | - | ns | _ |
| MDC clock pulse width high | t _{MDCH} | 160 | ı | ı | ns | _ |
| MDC to MDIO valid | t _{MDKHDV} | $2 \times (t_{\text{plb_clk}} \times 8)$ | _ | - | ns | (2) |
| MDC to MDIO delay | t _{MDKHDX} | $(16 \times t_{plb_clk}) - 3$ | ı | (16 × t _{plb_clk}) + 3 | ns | (2)(3)(4) |
| MDIO to MDC setup time | t _{MDDVKH} | 5 | ı | ı | ns | _ |
| MDIO to MDC hold time | t _{MDDXKH} | 0 | _ | - | ns | _ |
| MDC rise time | t _{MDCR} | - | _ | 10 | ns | _ |
| MDC fall time | t _{MDHF} | _ | _ | 10 | ns | _ |

Notes: 1. This parameter is dependent on the system clock speed. (The maximum frequency is the maximum platform frequency divided by 64).

- 2. tplb_clk is the platform (CCB) clock.
- 3. This parameter is dependent on the platform clock frequency. The delay is equal to 16 platform clock periods ±3 ns. For example, with a platform clock of 333 MHz, the min/max delay is 48 ns ± 3 ns. Similarly, if the platform clock is 400 MHz, the min/max delay is 40 ns ± 3 ns).
- 4. MDC to MDIO Data valid t_{MDKHDV} is a function of clock period and max delay time (t_{MDKHDX}). (Min setup = cycle time max delay).

Figure 2-25 shows the MII management interface timing diagram.

Figure 2-25. MII Management Interface Timing Diagram



2.10.8 eTSEC IEEE Std 1588 AC Specifications

Table 2-50 provides the IEEE 1588 AC timing specifications.

Table 2-50. eTSEC IEEE 1588 AC Timing Specifications

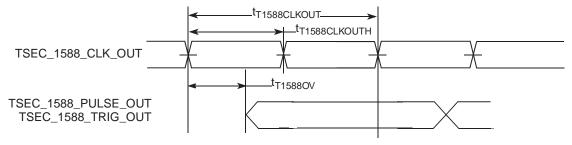
| Parameter/Condition | Symbol | Min | Тур | Max | Unit | Notes |
|------------------------------------|--|-------------------------------|-----|-------------------------|------|--------|
| TSEC_1588_CLK clock period | t _{T1588CLK} | 3.3 | _ | T _{RX_CLK} × 7 | ns | (1)(2) |
| TSEC_1588_CLK duty cycle | t _{T1588CLKH} / t _{T1588CLK} | 40 | 50 | 60 | % | (3) |
| TSEC_1588_CLK peak-to-peak jitter | t _{T1588CLKINJ} | _ | _ | 250 | ps | _ |
| Rise time eTSEC_1588_CLK (20%-80%) | t _{T1588CLKINR} | 1.0 | _ | 2.0 | ns | _ |
| Fall time eTSEC_1588_CLK (80%-20%) | t _{T1588CLKINF} | 1.0 | _ | 2.0 | ns | _ |
| TSEC_1588_CLK_OUT clock period | t _{T1588CLKOUT} | 2 × t _{T1588CLK} | _ | _ | ns | _ |
| TSEC_1588_CLK_OUT duty cycle | t _{T1588CLKOTH} / t _{T1588CLKOUT} | 30 | 50 | 70 | % | _ |
| TSEC_1588_PULSE_OUT | t _{T1588OV} | 0.5 | _ | 3.0 | ns | _ |
| TSEC_1588_TRIG_IN pulse width | t _{T1588TRIGH} | 2 × t _{T1588CLK_MAX} | _ | _ | ns | (2) |

Notes:

- T_{RX_CLK} is the maximum clock period of eTSEC receiving clock selected by TMR_CTRL[CKSEL]. See the P2020QorlQ Integrated Processor Reference Manual, for a description of TMR_CTRL registers.
 - 2. The maximum value of $t_{T1588CLK}$ is not only defined by the value of t_{RX_CLK} , but also defined by the recovered clock. For example, for 10/100/1000 Mbps modes, the maximum value of $t_{T1588CLK}$ will be 2800, 280, and 56 ns, respectively.
 - 3. It needs to be at least two times the clock period of the clock selected by TMR_CTRL[CKSEL]. See the P2020 QorlQ Integrated Processor Reference Manual, for a description of TMR_CTRL registers.

Figure 2-26 shows the data and command output AC timing diagram.

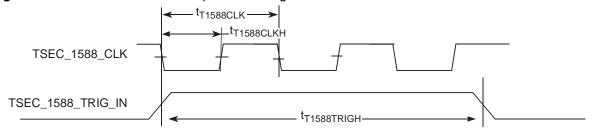
Figure 2-26. eTSEC IEEE 1588 Input AC Timing



Note: eTSEC IEEE 1588 Output AC timing: The output delay is counted starting at the rising edge if t_{T1588CLKOUT} is noninverting. Otherwise, it is counted starting at the falling edge.

Figure 2-27 shows the data and command input AC timing diagram.

Figure 2-27. eTSEC IEEE 1588 Input AC Timing



2.11 USB

This section provides the AC and DC electrical specifications for the USB interface of the device.

2.11.1 **USB DC Electrical Characteristics**

Table 2-51, Table 2-52 and Table 2-53 provides the DC electrical characteristics for the USB interface.

USB DC Electrical Characteristics (CV_{DD} = 3.3V) Table 2-51.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| High-level input voltage ⁽¹⁾ | V _{IH} | 2.0 | - | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.8 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±70 | μΑ | (2) |
| High-level output voltage (CV _{DD} = min, I _{OH} = −2 mA) | V _{OH} | 2.8 | _ | V | (3) |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.3 | V | _ |

- Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table
 - 2. The symbol V_{IN} , in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 "Recommended" Operating Conditions" on page 26.
 - 3. Not applicable for open drain signals.

Table 2-52. USB DC Electrical Characteristics ($CV_{DD} = 2.5V$)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| High-level input voltage ⁽¹⁾ | V _{IH} | 1.7 | _ | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.7 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±70 | μA | (2) |
| High-level output voltage (CV _{DD} = min, I _{OH} = -1 mA) | V _{OH} | 2.0 | _ | V | (3) |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 1mA) | V _{OL} | _ | 0.4 | V | _ |

Notes:

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table
- 2. The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 on page 26.
- 3. Not applicable for open drain signals.

Table 2-53. USB DC Electrical Characteristics ($CV_{DD} = 1.8V$)

| • | , | | | | |
|---|-----------------|------|-----|------|-------|
| Parameter | Symbol | Min | Max | Unit | Notes |
| High-level input voltage ⁽¹⁾ | V _{IH} | 1.25 | _ | V | (1) |
| Low-level input voltage | V _{IL} | - | 0.6 | ٧ | (1) |
| Input current ($V_{IN} = 0V$ or $V_{IN} = CV_{DD}$) | I _{IN} | - | ±70 | μA | (2) |
| High-level output voltage (CV_{DD} = min, I_{OH} = -0.5 mA) | V _{OH} | 1.35 | _ | V | (3) |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 0.5 mA) | V _{OL} | _ | 0.4 | V | _ |

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table
- 2. The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2 on page 26.
- 3. Not applicable for open drain signals.

2.11.2 **USB AC Electrical Specifications**

Table 2-54 describes the general timing parameters of the USB interface of the device.

USB General Timing Parameters⁽⁶⁾ (ULPI Mode Only) Table 2-54.

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Note |
|--|-----------------------|-----|-----|------|--------------|
| USB clock cycle time | t _{USCK} | 15 | _ | ns | (2)(3)(4)(5) |
| Input setup to USB clock-all inputs | t _{usivkh} | 4 | - | ns | (2)(3)(4)(5) |
| input hold to USB clock-all inputs | t _{usixkh} | 1 | _ | ns | (2)(3)(4)(5) |
| USB clock to output valid–all outputs | t _{USKHOV} | _ | 7 | ns | (2)(3)(4)(5) |
| Output hold from USB clock–all outputs | t _{uskhox} | 2 | _ | ns | (2)(3)(4)(5) |

- Notes: 1. The symbols for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)}}$ $_{(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{USIXKH} symbolizes USB timing (US) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also, t_{USKHOX} symbolizes USB timing (US) for the USB clock reference (K) to go high (H) with respect to the output (O) going invalid (X) or output hold time.
 - 2. All timings are in reference to USB clock.
 - 3. All signals are measured from $CV_{DD} \div 2$ of the rising edge of the USB clock to $0.4 \times CV_{DD}$ of the signal in question for 3.3V signaling levels.
 - 4. Input timings are measured at the pin.
 - 5. For active/float timing measurements, the high impedance or off state is defined to be when the total current delivered through the component pin is less than or equal to that of the leakage current specification.
 - 6. When switching the data pins from outputs to inputs using the USB DIR pin, the output timings is violated on that cycle because the output buffers are tristated asynchronously. This should not be a problem, because the PHY should not be functionally looking at these signals on that cycle as per ULPI specifications.

Figure 2-28 and Figure 2-29 provide the AC test load and signals for the USB, respectively.

Figure 2-28. USB AC Test Load

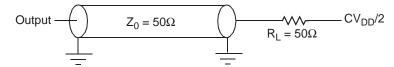


Figure 2-29. USB Signals

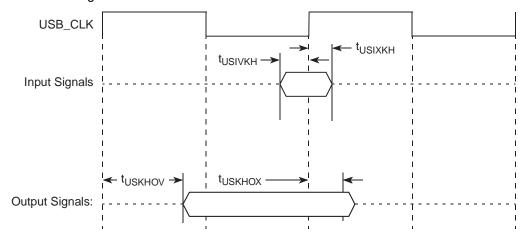


Table 2-55 provides the USB clock input (USB_CLK_IN) AC timing specifications.

Table 2-55. USB_CLK_IN AC Timing Specifications

| Parameter | Condition | Symbol | Min | Тур | Max | Unit |
|--|--|-------------------------|-------|-----|-------|------|
| Frequency range | Steady state | f _{USB_CLK_IN} | 59.97 | 60 | 60.03 | MHz |
| Clock frequency tolerance | _ | t _{CLK_TOL} | -0.05 | 0 | 0.05 | % |
| Reference clock duty cycle | Measured at 1.6V | t _{CLK_DUTY} | 40 | 50 | 60 | % |
| Total input jitter/time interval error | Peak-to-peak value measured with a second- order, high-pass filter of 500-kHz bandwidth | t _{CLK_PJ} | 1 | - | 200 | ps |

2.12 Enhanced Local Bus

This section describes the DC and AC electrical specifications for the enhanced local bus interface.

2.12.1 Enhanced Local Bus DC Electrical Characteristics

Table 2-56 provides the DC electrical characteristics for the enhanced local bus interface operating at $BV_{DD} = 3.3V$ DC.

Table 2-56. Enhanced Local Bus DC Electrical Characteristics (3.3V DC) (For Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol | Min | Max | Unit | Note |
|--|-----------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 2 | _ | V | (1) |
| Low-level input voltage | V _{IL} | _ | 0.8 | V | (1) |
| Input current (V _{IN} ⁽¹⁾ = 0V or V _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μA | (2) |
| High-level output voltage (BV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the BV_{IN} symbol referenced in Section 2.1.2 "Recommended Operating Conditions" on page 26.

Table 2-57 provides the DC electrical characteristics for the enhanced local bus interface operating at $BV_{DD} = 2.5V$ DC.

Table 2-57. Enhanced Local Bus DC Electrical Characteristics (2.5V DC) (For Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|------|-----|------|------|
| High-level input voltage | V _{IH} | 1.70 | - | V | (1) |
| Low-level input voltage | V _{IL} | _ | 0.7 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μA | (2) |
| High-level output voltage (BV _{DD} = min, I _{OH} = -1 mA) | V _{OH} | 2.0 | - | V | |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 1 mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 2-2.

2. The symbol V_{IN} , in this case, represents the BV_{IN} symbol referenced in Section 2.1.2 "Recommended Operating Conditions" on page 26.

Table 2-58 provides the DC electrical characteristics for the enhanced local bus interface operating at $BV_{DD} = 1.8V DC$.

Table 2-58. Enhanced Local Bus DC Electrical Characteristics (1.8V DC) (For Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|------|-----|----------|------|
| High-level input voltage | V _{IH} | 1.25 | _ | V | (1) |
| Low-level input voltage | V_{IL} | _ | 0.6 | V | (1) |
| Input current (V _{IN} = 0V or V _{IN} = BV _{DD}) | I _{IN} | ı | ±40 | μA | (2) |
| High-level output voltage (BV _{DD} = min, I_{OH} = -0.5 mA) | V _{OH} | 1.35 | ı | V | _ |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 0.5 mA) | V _{OL} | - | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table

2. The symbol V_{IN}, in this case, represents the BV_{IN} symbol referenced in Section 2.1.2 on page 26.

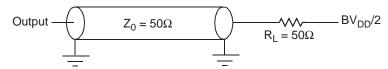
2.12.2 Enhanced Local Bus AC Electrical Specifications

This section describes the AC timing specifications for the enhanced local bus interface.

2.12.2.1 Test Condition

Figure 2-30 provides the AC test load for the enhanced local bus.

Figure 2-30. Enhanced Local Bus AC Test Load



2.12.2.2 Local Bus AC Timing Specifications for PLL Enable Mode

For PLL enable mode, all timings are relative to the rising edge of LSYNC IN.

Table 2-59 describes the general timing parameters of the enhanced local bus interface.

Table 2-59. Enhanced Local Bus Timing Specifications (BV_{DD} = 3.3V, 2.5V, and 1.8V)–PLL Enabled Mode⁽¹⁾

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-------------------------------------|--|-----|---|-------|
| Local bus cycle time | t _{LBK} | 6.67 | 12 | ns | _ |
| Local bus duty cycle | t _{LBKH} /t _{LBK} | 45 | 55 | % | _ |
| LCLK[n] skew to LCLK[m] or LSYNC_OUT | t _{LBKSKEW} | - | 150 | ps | (2) |
| Input setup | t _{LBIVKH} | 2 | 1 | ns | _ |
| Input hold | t _{LBIXKH} | 0.5 | 1 | ns | - |
| Output delay (Except LALE) | t _{LBKHOV} | - | 3.8 | ns | _ |
| Output hold (Except LALE) | t _{LBKHOX} | 0.7 | 1 | ns | _ |
| Local bus clock to output high impedance for LAD/LDP | t _{LBKHOZ} | - | 3.8 | ns | (3) |
| LALE output negation to LAD/LDP output transition (LATCH hold time) | t _{LBONOT} | 1 (LBCR[AHD] = 0) 1/2 (LBCR[AHD] = 1) | - | eLBC controller clock cycle (=1 platform clock cycles) | (4) |

Notes

- 1. All signals are measured from $BV_{DD} \div 2$ of the rising edge of LSYNC_IN to $BV_{DD} \div 2$ of the signal in question.
- 2. Skew measured between different LCLK signals at $BV_{DD} \div 2$.
- 3. For purposes of active/float timing measurements, the high impedance or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 4. t_{LBONOT} is a measurement of the minimum time between the negation of LALE and any change in LAD. t_{LBONOT} is determined by LBCR[AHD]. The unit is the eLBC controller clock cycle. The eLBC controller clock refers to the internal clock that runs the local bus controller, not the external LCLK. LCLK cycle = eLBC controller clock cycle × LCRR[CLKDIV]. After power on reset, LBCR[AHD] defaults to 0 and eLBC runs at maximum hold time.

Figure 2-31 shows the AC timing diagram for PLL-enabled mode.

Figure 2-31. Local Bus AC Timing Diagram (PLL Enabled)

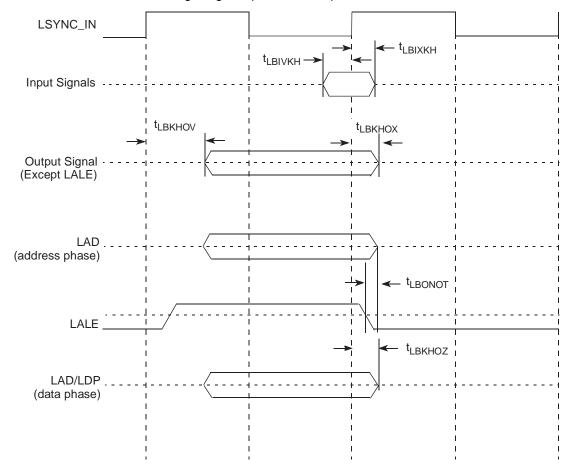


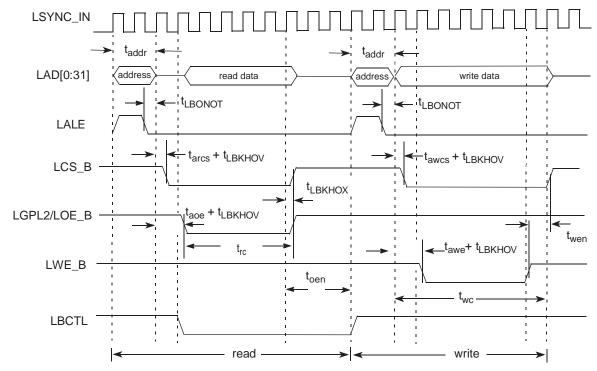
Figure 2-31 applies to all three controllers that eLBC supports: GPCM, UPM, and FCM.

For input signals, the AC timing data is used directly for all three controllers.

For output signals, each type of controller provides its own unique method to control the signal timing. The final signal delay value for output signals is the programmed delay plus the AC timing delay. For example, for GPCM, LCS can be programmed to delay by t_{acs} (0, $\frac{1}{4}$, $\frac{1}{4}$, 1 + $\frac{1}{4}$, 1 + $\frac{1}{4}$, 2, 3 cycles), so the final delay is $t_{acs} + t_{LBKHOV}$.

Figure 2-32 shows how the AC timing diagram applies to GPCM. The same principle applies to UPM and FCM.

Figure 2-32. GPCM Output Timing diagram (PLL Enabled)



Notes: 1. t_{addr} is programmable and determined by LCRR[EADC] and ORx[EAD].

 $2. \ \ t_{\text{arcs}}, t_{\text{awcs}}, t_{\text{aoe}}, t_{\text{rc}}, t_{\text{oen}}, t_{\text{awe}}, t_{\text{wc}}, t_{\text{wen}} \text{ are determined by ORx. See the P2020 reference manual.}$

2.12.2.3 Local Bus AC Timing Specifications for PLL Bypass Mode

All output signal timings are relative to the falling edge of any LCLKs. The external circuit must use the rising edge of the LCLKs to latch the data.

All input timings except LGTA/LUPWAIT/LFRB are relative to the rising edge of LCLKs. LGTA/LUPWAIT/LFRB are relative to the falling edge of LCLKs.

Table 2-60 describes the timing specifications of the local bus interface.

Table 2-60. Enhanced Local Bus Timing Specifications (BV_{DD} = 3.3V, 2.5V, and 1.8V) – PLL Bypassed (For Recommended Operating Conditions, see Table 2-2)

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Notes |
|---|-------------------------------------|--|-----|---|-------|
| Local bus cycle time | t _{LBK} | 12 | _ | ns | - |
| Local bus duty cycle | t _{LBKH} /t _{LBK} | 45 | 55 | % | - |
| LCLK[n] skew to LCLK[m] | t _{LBKSKEW} | - | 150 | ps | (2) |
| Input setup (except LGTA/LUPWAIT/LFRB) | t _{LBIVKH} | 6 | _ | ns | - |
| Input hold (except LGTA/LUPWAIT/LFRB) | t _{LBIXKH} | 1 | _ | ns | - |
| Input setup (for LGTA/LUPWAIT/LFRB) | t _{LBIVKL} | 6 | _ | ns | - |
| Input hold (for LGTA/LUPWAIT/LFRB) | t _{LBIXKL} | 1 | _ | ns | - |
| Output delay (Except LALE) | t _{LBKLOV} | - | 1.5 | ns | _ |
| Output hold (Except LALE) | t _{LBKLOX} | -3.5 | _ | ns | (3) |
| Local bus clock to output high impedance for LAD/LDP | t _{LBKLOZ} | - | 2 | ns | (4) |
| LALE output negation to LAD/LDP output transition (LATCH hold time) | t _{lbonot} | 1 (LBCR[AHD] = 0) 1/2 (LBCR[AHD] = 1) | - | eLBC controller clock cycle (= 1 platform clock cycles) | (5) |

- Notes: 1. All signals are measured from $BV_{DD}/2$ of rising/falling edge of LCLK to $BV_{DD}/2$ of the signal in question.
 - 2. Skew measured between different LCLK signals at BV_{DD}/2.
 - 3. Output hold is negative. This means that output transition happens earlier than the falling edge of LCLK.
 - 4. For purposes of active/float timing measurements, the high impedance or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
 - 5. t_{LBONOT} is a measurement of the minimum time between the negation of LALE and any change in LAD. t_{LBONOT} is determined by LBCR[AHD]. The unit is the eLBC controller clock cycle, which is the internal clock that runs the local bus controller, not the external LCLK. LCLK cycle = eLBC controller clock cycle × LCRR[CLKDIV]. After power on reset, LBCR[AHD] defaults to 0 and eLBC runs at maximum hold time.

Figure 2-33 shows the enhanced local bus signals in PLL-bypass mode.

Figure 2-33. Enhanced Local Bus Signals (PLL Bypass Mode)

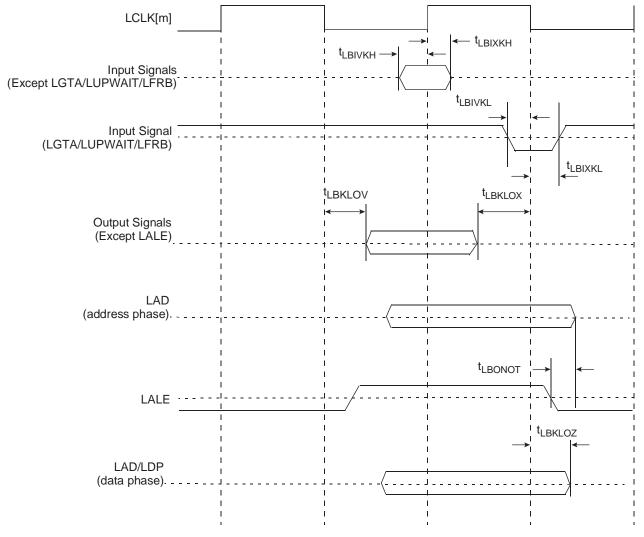


Figure 2-33 applies to all three controllers that eLBC supports: GPCM, UPM, and FCM.

For input signals, the AC timing data is used directly for all three controllers.

For output signals, each type of controller provides its own unique method to control the signal timing. The final signal delay value for output signals is the programmed delay plus the AC timing delay. For example, for GPCM, LCS can be programmed to delay by t_{acs} (0, $\frac{1}{4}$, $\frac{1}{4}$, 1 + $\frac{1}{4}$, 1 + $\frac{1}{4}$, 2, 3 cycles), so the final delay is $t_{acs} + t_{LBKHOV}$.

Figure 2-34 shows how the AC timing diagram applies to GPCM. The same principle applies to UPM and FCM.

LCLK taddr LAD[0:31] address read data address write data **t**LBONOT $\mathsf{t}_\mathsf{LBONOT}$ LALE tarcs + tLBKHOV t_{awcs} + t_{LBKHOV} LCS_B **t**LBKHOX + t_{LBKHOV} LGPL2/LOE_B tawe + tLBKHOV t_{rc} LWE_B t_{oen} **LBCTL** read

Figure 2-34. GPCM Output Timing Diagram

- 1. t_{addr} is programmable and determined by LCRR[EADC] and ORx[EAD].
- 2. t_{arcs} , t_{awcs} , t_{aoe} , t_{rc} , t_{oen} , t_{awe} , t_{wc} , t_{wen} are determined by ORx. See the P2020 reference manual.

2.13 **Enhanced Secure Digital Host Controller (eSDHC)**

This section describes the DC and AC electrical specifications for the eSDHC (SDIO) interface.

2.13.1 **eSDHC DC Electrical Characteristics**

Table 2-61 provides the DC electrical characteristics for the eSDHC (SDIO) interface.

Table 2-61. eSDHC Interface DC Electrical Characteristics ($CV_{DD} = 3.3V$)

| Parameter | Symbol | Condition | Min | Max | Unit | Note |
|-----------------------|-----------------|---|--------------------------|--------------------------|----------|------|
| Input high voltage | V _{IH} | - | 0.625 × CV _{DD} | _ | V | (1) |
| Input low voltage | V_{IL} | - | ı | 0.25 × CV _{DD} | ٧ | (1) |
| Output high voltage | V _{OH} | I _{OH} = –100 μA at OV _{DD} min | 0.75 × CV _{DD} | _ | V | _ |
| Output low voltage | V _{OL} | I _{OL} = 100 μA at OV _{DD} min | ı | 0.125 × CV _{DD} | ٧ | ı |
| Output high voltage | V _{OH} | I _{OH} = -100 μA | CV _{DD} -0.2 | ı | V | (2) |
| Output low voltage | V _{OL} | I _{OL} = 2 mA | ı | 0.3 | V | (2) |
| Input leakage current | I _{IN} | _ | – 70 | 70 | μA | |

Notes: 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 2-2.

2. Open drain mode for MMC cards only.

2.13.2 eSDHC AC Timing Specifications

This section describes the AC electrical specifications for the eSDHC (SDIO) interface.

Table 2-62 provides the eSDHC AC timing specifications for full speed mode as defined in Figure 2-35 and Figure 2-36.

Table 2-62. eSDHC AC Timing Specifications

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Notes |
|---|--|------|----------------|------|-----------|
| SD_CLK clock frequency | _ | | | | (0)(2) |
| SD Full-speed/High-speed mode MMC Full-speed/High-speed mode | f _{sнsск} | 0 | 25/50 20/52 | MHz | (2)(3) |
| SD_CLK clock low time-Full-speed mode/High-speed mode | t _{SHSCKL} | 10/7 | _ | ns | (3) |
| SD_CLK clock high time-Full-speed mode/High-speed mode | t _{shsckh} | 10/7 | _ | ns | (3) |
| SD_CLK clock rise and fall times | t _{shsckr} / t _{shsckr} | - | 3 | ns | (3) |
| Input setup times: SD_CMD, SD_DATX, SD_CD to SD_CLK | t _{SHSIVKH} | 3.7 | _ | ns | (3)(4)(5) |
| Input hold times: SD_CMD, SD_DATX, SD_CD to SD_CLK | t _{SHSIXKH} | 2.5 | _ | ns | (3) |
| Output delay time: SD_CLK to SD_CMD, SD_DATx valid | t _{SHSKHOV} | -3 | 3 | ns | (3)(5) |

Notes: 1. The symbols used for timing specifications herein follow the pattern of t_{(first three letters of functional block)(signal)(state)} for inputs and t_{(first three letters of functional block)(reference)(state)(signal)(state)} for outputs. For example, t_{FHSKHOV} symbolizes eSDHC high speed mode device timing (SHS) clock reference (K) going to the high (H) state, with respect to the output (O) reaching the invalid state (X) or output hold time. Note that, in general, the clock reference symbol representation is based on five letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

- 2. In full speed mode, clock frequency value can be 0–25 MHz for a SD/SDIO card and 0–20 MHz for a MMC card. In high speed mode, clock frequency value can be 0–50 MHz for a SD/SDIO card and 0–52 MHz for a MMC card.
- 3. $C_{CARD} \le 10$ pF, (1 card), and $C_{L} = C_{BUS} + C_{HOST} + C_{CARD} \le 40$ pF
- 4. To satisfy setup timing, one way board routing delay between Host and Card, on SD_CLK, SD_CMD, and SD_DATx should not exceed 0.65 ns.
- 5. The parameter values apply to both full speed and high speed modes.

Figure 2-35 provides the eSDHC clock input timing diagram.

Figure 2-35. eSDHC Clock Input Timing Diagram

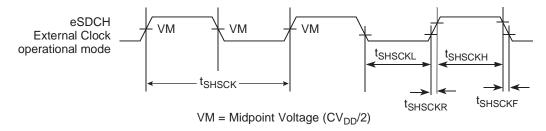
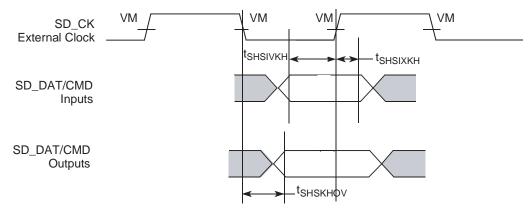


Figure 2-36 provides the data and command input/output timing diagram.

Figure 2-36. eSDHC Data and Command Input/Output Timing Diagram Referenced to Clock



VM = Midpoint Voltage (CV_{DD}/2)

2.14 Programmable Interrupt Controller

In IRQ edge trigger mode, when an external interrupt signal is asserted (according to the programmed polarity), it must remain the assertion for at least 3 system clocks (SYSCLK periods).

2.14.1 PIC DC Electrical Characteristics

Table 2-63 provides the DC electrical characteristics for the PIC interface.

Table 2-63. PIC DC Electrical Characteristics

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Note |
|---|-----------------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 2 | _ | V | (1) |
| Low-level input voltage | V _{IL} | _ | 0.8 | V | (1) |
| Input current ($OV_{IN} = 0V$ or $OV_{IN} = OV_{DD}$) | I _{IN} | 1 | ±40 | μA | (2) |
| High-level output voltage (OV _{DD} = min, $I_{OH} = -2$ mA) | V _{OH} | 2.4 | _ | V | _ |
| Low-level output voltage (OV $_{\rm DD}$ = min, I $_{\rm OL}$ = 2 mA) | V _{OL} | _ | 0.4 | V | - |

Notes: 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 2-2.

2. Note that the symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 2-2.

2.14.2 PIC AC Electrical Characteristics

Table 2-64 shows the PIC AC timing specifications.

Table 2-64. PIC Input AC Timing Specifications

| Parameter | Symbol | Min | Max | Unit | Notes |
|--------------------------------|--------------------|-----|-----|--------|-------|
| PIC inputs-minimum pulse width | t _{PIWID} | 3 | _ | SYSCLK | (1) |

Note: 1. PIC inputs and outputs are asynchronous to any visible clock. PIC outputs must be synchronized before use by any external synchronous logic. PIC inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation when working in edge-triggered mode.

2.15 JTAG

This section discusses the JTAG interface.

2.15.1 JTAG DC Electrical Characteristics

Table 2-65 provides the DC electrical characteristics for the JTAG interface.

Table 2-65. JTAG DC Electrical Characteristics

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Note |
|--|-----------------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 2 | _ | V | (1) |
| Low-level input voltage | V _{IL} | _ | 0.8 | V | (1) |
| Input current (V _{IN} ⁽¹⁾ = 0V or V _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μA | (2) |
| High-level output voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | - | V | _ |
| Low-level output voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 2-2.

2. Note that the symbol V_{IN} , in this case, represents the OV_{IN} symbol found in Table 2-2

2.15.2 JTAG AC Electrical Specifications

This section describes the AC electrical specifications for the IEEE Std 1149.1[™] (JTAG) interface of the device. Table 2-66 provides the JTAG AC timing specifications as defined in Figure 2-38 through Figure 2-40.

Table 2-66. JTAG AC Timing Specifications (Independent of SYSCLK) (At Recommended Operating Conditions, See Table 2-2)

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Notes |
|---|---------------------------------------|-----|------|------|-------|
| JTAG external clock frequency of operation | f_{JTG} | 0 | 33.3 | MHz | _ |
| JTAG external clock cycle time | t _{JTG} | 30 | - | ns | - |
| JTAG external clock pulse width measured at OV _{DD} /2 | t _{JTKHKL} | 15 | - | ns | - |
| JTAG external clock rise and fall times | t _{JTGR} & t _{JTGF} | 0 | 2 | ns | - |
| TRST assert time | t _{TRST} | 25 | _ | ns | (2) |
| Input setup times | t _{JTDVKH} | 4 | - | ns | - |
| Input hold times | t _{JTDXKH} | 10 | - | ns | _ |
| Output valid times | t _{JTKLDV} | 0 | 10 | ns | (3) |
| Output hold times | t _{JTKLDX} | 0 | _ | ns | (3) |

Notes: 1. The symbols used for timing specifications follow the pattern $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{JTDVKH} symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{JTG} clock reference (K) going to the high (H) state or setup time. Also, t_{JTDXKH} symbolizes JTAG timing (JT) with respect to the time data input signals (D) reaching the invalid state (X) relative to the t_{JTG} clock reference (K) going to the high (H) state. Note that in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

- 2. TRST is an asynchronous level sensitive signal. The setup time is for test purposes only.
- All outputs are measured from the midpoint voltage of the falling/rising edge of t_{TCLK} to the midpoint of the signal in question.
 The output timings are measured at the pins. All output timings assume a purely resistive 50Ω load. Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.

Figure 2-37 provides the AC test load for TDO and the boundary-scan outputs.

Figure 2-37. AC Test Load for the JTAG Interface

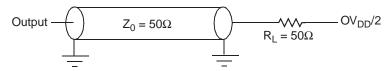


Figure 2-38 provides the JTAG clock input timing diagram.

Figure 2-38. JTAG Clock Input Timing Diagram

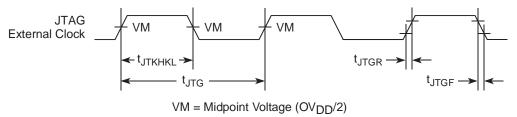


Figure 2-39 provides the TRST timing diagram.

Figure 2-39. TRST Timing Diagram

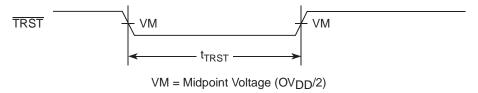
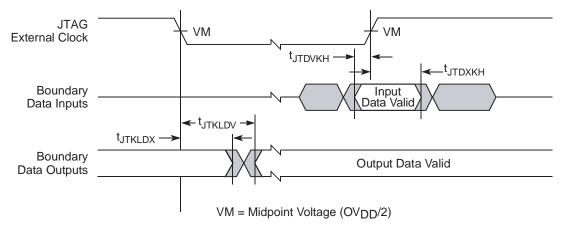


Figure 2-40 provides the boundary-scan timing diagram.

Figure 2-40. Boundary-Scan Timing Diagram



I²C 2.16

This section describes the DC and AC electrical characteristics for the I²C interfaces of the device.

I²C DC Electrical Characteristics 2.16.1

Table 2-67 provides the DC electrical characteristics for the I²C interfaces.

I²C DC Electrical Characteristics Table 2-67.

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|-------|
| Input high voltage level | V _{IH} | 2 | - | V | (1) |
| Input low voltage level | V _{IL} | - | 0.8 | V | (1) |
| Output Low voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | 0 | 0.4 | V | (2) |
| Pulse width of spikes which must be suppressed by the input filter | t _{I2KHKL} | 0 | 50 | ns | (3) |
| Input current each I/O pin (input voltage is between 0.1 × OV _{DD} and 0.9 × OV _{DD} (max) | I | -40 | 40 | μΑ | (4) |
| Capacitance for each I/O pin | Cı | _ | 10 | pF | _ |

- Notes: 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in
 - 2. Output voltage (open drain or open collector) condition = 3 mA sink current.
 - 3. See the P2020 QorlQ Integrated Communications Host Processor Family Reference Manual for information on the digital filter used.
 - 4. I/O pins obstruct the SDA and SCL lines if ${\rm OV_{DD}}$ is switched off.

2.16.2 I²C AC Electrical Specifications

Table 2-68 provides the AC timing parameters for the I²C interfaces.

Table 2-68. I²C AC Electrical Specifications (At Recommended Operating Conditions with OV_{DD} of 3.3V ± 5%. All Values Refer to V_{IH} (min) and V_{IL} (max) Levels, See Table 2-67)

| Parameter | Symbol ⁽¹⁾ | Min | Max | Unit | Note |
|--|-----------------------|------------------------|--------|--------------------|------|
| SCL clock frequency | f _{I2C} | 0 | 400 | kHz ⁽⁴⁾ | (2) |
| Low period of the SCL clock | t _{I2CL} | 1.3 | _ | μs | _ |
| High period of the SCL clock | t _{I2CH} | 0.6 | _ | μs | _ |
| Setup time for a repeated START condition | t _{I2SVKH} | 0.6 | - | μs | _ |
| Hold time (repeated) START condition (after this period, the first clock pulse is generated) | t _{i2SXKL} | 0.6 | - | μs | ı |
| Data setup time | t _{I2DVKH} | 100 | _ | ns | _ |
| Data input hold time: CBUS compatible masters I ² C bus devices | t _{I2DXKL} | _ 0 | _ _ | μs | (3) |
| Data output delay time | t _{I2OVKL} | _ | 0.9 | μs | (4) |
| Set-up time for STOP condition | t _{I2PVKH} | 0.6 | _ | μs | - |
| Bus free time between a STOP and START condition | t _{I2KHDX} | 1.3 | _ | μs | _ |
| Noise margin at the LOW level for each connected device (including hysteresis) | V _{NL} | 0.1 × OV _{DD} | _ | V | 1 |
| Noise margin at the HIGH level for each connected device (including hysteresis) | V _{NH} | 0.2 × OV _{DD} | _ | V | ı |
| Capacitive load for each bus line | Cb | _ | 400 | pF | _ |

Notes:

- 1. The symbols used for timing specifications herein follow the pattern $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{I2DVKH} symbolizes I^2C timing (I2) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. Also, t_{I2SXKL} symbolizes I^2C timing (I2) for the time that the data with respect to the START condition (S) went invalid (X) relative to the t_{I2C} clock reference (K) going to the low (L) state or hold time. Also, t_{I2PVKH} symbolizes I^2C timing (I2) for the time that the data with respect to the STOP condition (P) reaches the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time.
- The requirements for I²C frequency calculation must be followed. Refer to Freescale application note AN2919, "Determining the I²C Frequency Divider Ratio for SCL."
- 3. As a transmitter, the device provides a delay time of at least 300 ns for the SDA signal (referred to as the V_{IHmin} of the SCL signal) to bridge the undefined region of the falling edge of SCL to avoid unintended generation of a START or STOP condition. When the device acts as the I²C bus master while transmitting, it drives both SCL and SDA. As long as the load on SCL and SDA are balanced, the device does not generate an unintended START or STOP condition. Therefore, the 300 ns SDA output delay time is not a concern. If under some rare condition, the 300 ns SDA output delay time is required for the device as transmitter, application note AN2919, referred to in note 2 above, is recommended.
- 4. The maximum ti20VKL must be met only if the device does not stretch the LOW period (t_{12CL}) of the SCL signal.

Figure 2-41 provides the AC test load for the I²C.

Figure 2-41. I²C AC Test Load

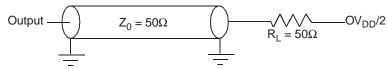
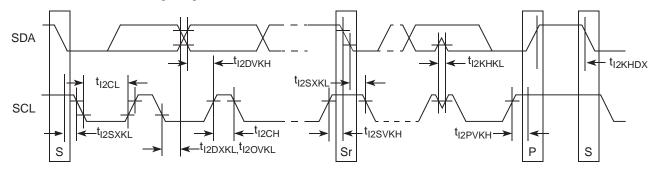


Figure 2-42 shows the AC timing diagram for the I²C bus.

Figure 2-42. I²C Bus AC Timing Diagram



2.17 **GPIO**

This section describes the DC and AC electrical specifications for the GPOUT and GPIN interface of the device.

2.17.1 GPIO DC Electrical Characteristics

Table 2-69 provides the DC electrical characteristics for the GPIO interface.

Table 2-69. PIO[0:7] DC Electrical Characteristics (3.3V)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|--------|
| High-level input voltage | V_{IH} | 2 | _ | V | (1)(2) |
| Low-level input voltage | V_{IL} | - | 0.8 | V | (1)(2) |
| Input current (V _{IN} ⁽¹⁾ = 0V or V _{IN} = V _{DD}) | I _{IN} | ı | ±40 | μA | _ |
| High-level output voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Low-level output voltage (OV _{DD} = min, I _{OL} = 2mA) | V _{OL} | _ | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the min and max OV_{IN} respective values found in Table 2-1.

2. The symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 2-1.

Table 2-70. GPIO[8:15] DC Electrical Characteristics (3.3V)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|--------|
| High-level input voltage | V _{IH} | 2 | - | V | (1)(2) |
| Low-level input voltage | V _{IL} | - | 0.8 | V | (1)(2) |
| Input current (V _{IN} ⁽¹⁾ = 0V or V _{IN} = V _{DD}) | I _{IN} | _ | ±40 | μA | _ |
| High-level output voltage (BV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | - | V | - |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 2mA) | V _{OL} | - | 0.4 | ٧ | - |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the min and max OV_{IN} respective values found in Table 2-1.

2. The symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 2-1.

Table 2-71. GPIO[8:15] DC Electrical Characteristics (2.5V)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|--------|
| High-level input voltage | V _{IH} | 1.7 | _ | V | (1)(2) |
| Low-level input voltage | V_{IL} | _ | 0.7 | V | (1)(2) |
| Input current (V _{IN} ⁽¹⁾ = 0V or V _{IN} = V _{DD}) | I _{IN} | ı | ±40 | μA | _ |
| High-level output voltage (BV _{DD} = min, I_{OH} = -1 mA) | V _{OH} | 1.7 | _ | V | _ |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 1 mA) | V _{OL} | _ | 0.7 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the min and max OV_{IN} respective values found in Table 2-1.

2. The symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 2-1.

Table 2-72. GPIO[8:15] DC Electrical Characteristics (1.8V)

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|-----|------|--------|
| High-level input voltage | V _{IH} | 1.2 | _ | V | (1)(2) |
| Low-level input voltage | V _{IL} | - | 0.6 | V | (1)(2) |
| Input current $(V_{IN}^{(1)} = 0V \text{ or } V_{IN} = V_{DD})$ | I _{IN} | ı | ±40 | μA | _ |
| High-level output voltage (BV _{DD} = min, I _{OH} = -0.5 mA) | V _{OH} | 1.35 | _ | V | - |
| Low-level output voltage (BV _{DD} = min, I _{OL} = 0.5 mA) | V _{OL} | - | 0.4 | V | _ |

Notes: 1. The min V_{IL} and max V_{IH} values are based on the min and max OV_{IN} respective values found in Table 2-1.

2. The symbol ${\rm OV_{IN}}$ represents the input voltage of the supply. It is referenced in Table 2-1.

2.17.2 GPIO AC Electrical Specifications

Table 2-73 provides the GPIO input and output AC timing specifications.

Table 2-73. GPIO Input and Output AC Timing Specifications⁽¹⁾

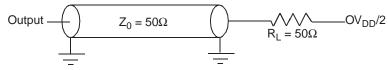
| Characteristic | Symbol | Min | Unit | Notes |
|---------------------------------|--------------------|----------------|------|-------|
| GPIO inputs-minimum pulse width | t _{PIWID} | 1.5 × plat ÷ 2 | ns | (1) |

Note:

 GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs must be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation.

Figure 2-43 provides the AC test load for the GPIO.

Figure 2-43. GPIO AC Test Load



2.18 High-Speed Serial Interfaces (HSSI)

The device features one Serializer/Deserializer (SerDes) interfaces to be used for high-speed serial interconnect applications. The SerDes interface can be used for PCI Express SGMII and/or Serial RapidIO data transfers.

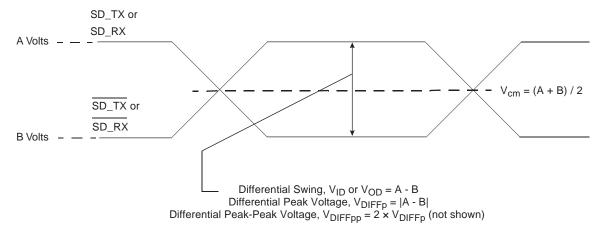
This section describes the common portion of SerDes DC electrical specifications, which is the DC requirement for SerDes Reference Clocks. The SerDes data lane's transmitter and receiver reference circuits are also shown.

2.18.1 Signal Terms Definition

The SerDes utilizes differential signaling to transfer data across the serial link. This section defines terms used in the description and specification of differential signals.

Figure 2-44 shows how the signals are defined. For illustration purposes, only one SerDes <u>lane is</u> used for description. Figure 2-44 shows the waveform for either a transmitter output (SD_TX and $\overline{SD_TX}$) or a receiver input (SD_RX and $\overline{SD_RX}$). Each signal swings between A Volts and B Volts where A > B.

Figure 2-44. Differential Voltage Definitions for Transmitter or Receiver



Using this waveform, the definitions are as follows. To simplify the illustration, the following definitions assume that the SerDes transmitter and receiver operate in a fully symmetrical differential signaling environment:

Single-Ended Swing

The transmitter output signals and the receiver input signals SD_TX, SD_TX, SD_RX and SD_RX each have a peak-to-peak swing of A – B Volts. This is also referred as each signal wire's Single-Ended Swing.

Differential Output Voltage, V_{OD} (or Differential Output Swing)

The Differential Output Voltage (or Swing) of the transmitter, V_{OD} , is defined as the difference of the two complimentary output voltages: $V_{SDn_TX} - V_{\overline{SDn_TX}}$. The V_{OD} value can be either positive or negative.

Differential Input Voltage, V_{ID} (or Differential Input Swing)

The Differential Input Voltage (or Swing) of the receiver, V_{ID} , is defined as the difference of the two complimentary input voltages: $V_{SDn\ RX} - V_{\overline{SDn\ RX}}$. The V_{ID} value can be either positive or negative.

• Differential Peak Voltage, V_{DIFFp}

The peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak Voltage, $V_{DIFFD} = |A - B|$ Volts.

Differential Peak-to-Peak, V_{DIFFp-p}

Since the differential output signal of the transmitter and the differential input signal of the receiver each range from A – B to –(A – B) Volts, the peak-to-peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak-to-Peak Voltage, $V_{DIFFp-p} = 2 \times V_{DIFFp} = 2 \times |(A - B)|$ Volts, which is twice of differential swing in amplitude, or twice of the differential peak. For example, the output differential peak-peak voltage can also be calculated as $V_{TX-DIFFp-p} = 2 \times |V_{OD}|$.

Differential Waveform

The differential waveform is constructed by subtracting the inverting signal (SD_TX, for example) from the non-inverting signal (SD_TX, for example) within a differential pair. There is only one signal trace curve in a differential waveform. The voltage represented in the differential waveform is not referenced to ground. Refer to Figure 2-44 as an example for differential waveform.

Common Mode Voltage, V_{cm}

The Common Mode Voltage is equal to one half of the sum of the voltages between each conductor of a balanced interchange circuit and ground. In this example, for SerDes output, $V_{cm_out} = (V_{SDn_TX} + V_{\overline{SDn_TX}}) \div 2 = (A + B) \div 2$, which is the arithmetic mean of the two complimentary output voltages within a differential pair. In a system, the common mode voltage may often differ from one component's output to the other's input. It may be different between the receiver input and driver output circuits within the same component. It is also referred to as the DC offset on some occasions.

To illustrate these definitions using real values, consider the case of a current mode logic (CML) transmitter that has a common mode voltage of 2.25V and each of its outputs, TD and $\overline{\text{TD}}$, has a swing that goes between 2.5V and 2.0V. Using these values, the peak-to-peak voltage swing of each signal (TD or $\overline{\text{TD}}$) is 500 mV p-p, which is referred to as the single-ended swing for each signal. In this example, because the differential signaling environment is fully symmetrical, the transmitter output's differential swing (V_{OD}) has the same amplitude as each signal's single-ended swing. The differential output signal ranges between 500 mV and –500 mV. In other words, V_{OD} is 500 mV in one phase and –500 mV in the other phase. The peak differential voltage (V_{DIFFp}) is 500 mV. The peak-to-peak differential voltage (VD_{IFFp-D}) is 1000 mV p-p.

2.18.2 SerDes Reference Clocks

The SerDes reference clock inputs are applied to an internal PLL whose output creates the clock used by the corresponding SerDes lanes. The SerDes reference clocks inputs are SD_REF_CLK and SD_REF_CLK for PCI Express and Serial RapidIO, or SD_REF_CLK and SD_REF_CLK for the SGMII interface respectively.

The following sections describe the SerDes reference clock requirements and some application information.

2.18.2.1 SerDes Spread Spectrum Clock Source Recommendations

SD_REF_CLK/SD_REF_CLK are designed to work with spread spectrum clock for PCI Express protocol only with the spreading specification defined in Table 2-74. When using spread spectrum clocking for PCI Express, both ends of the link partners should use the same reference clock. For best results, a source without significant unintended modulation should be used.

The spread spectrum clocking cannot be used if the same SerDes reference clock is shared with other non-spread spectrum supported protocols. For example, if the spread spectrum clocking is desired on a SerDes reference clock for PCI Express and the same reference clock is used for any other protocol such as SGMII/SRIO due to the SerDes lane usage mapping option, spread spectrum clocking cannot be used at all.

Table 2-74. SerDes Spread Spectrum Clock Source Recommendations (At Recommended Operating Conditions, see Table 2-2)

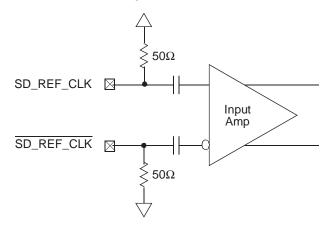
| Parameter | Min | Max | Unit | Notes |
|----------------------|-----|------|------|-------|
| Frequency modulation | 30 | 33 | kHz | - |
| Frequency spread | +0 | -0.5 | % | (1) |

Note: 1. Only down spreading is allowed.

2.18.2.2 SerDes Reference Clock Receiver Characteristics

Figure 2-45 shows a receiver reference diagram of the SerDes reference clocks.

Figure 2-45. Receiver of SerDes Reference Clocks



The characteristics are as follows:

- The supply voltage requirements for XV_{DD SRDS2} are specified in Table 2-1 and Table 2-2.
- The SerDes reference clock receiver reference circuit structure is as follows:
 - The SD_REF_CLK and SD_REF_CLK are internally AC-coupled differential inputs as shown in Figure 2-45. Each differential clock input (SD_REF_CLK or SD_REF_CLK) has on-chip 50Ω termination to SGND_SRDSn (xcorevss) followed by on-chip AC-coupling.
 - The external reference clock driver must be able to drive this termination.
 - The SerDes reference clock input can be either differential or single-ended. Refer to the Differential Mode and Single-ended Mode description below for further detailed requirements.
- The maximum average current requirement that also determines the common mode voltage range is the following:
 - When the SerDes reference clock differential inputs are DC coupled externally with the clock driver chip, the maximum average current allowed for each input pin is 8 mA. In this case, the exact common mode input voltage is not critical as long as it is within the range allowed by the maximum average current of 8 mA (refer to the following bullet for more detail), because the input is AC-coupled on-chip.
 - This current limitation sets the maximum common mode input voltage to be less than 0.4V (0.4V/50 = 8 mA) while the minimum common mode input level is 0.1V above SGND_SRDSn (xcorevss). For example, a clock with a 50/50 duty cycle can be produced by a clock driver with output driven by its current source from 0 mA to 16 mA (0–0.8V), such that each phase of the differential input has a single-ended swing from 0V to 800 mV with the common mode voltage at 400 mV.
 - If the device driving the SD_REF_CLK and $\overline{\text{SD}}_{\text{REF}}$ inputs cannot drive 50 Ω to SGND_SRDSn (xcorevss) DC, or it exceeds the maximum input current limitations, then it must be AC-coupled off-chip.
- The input amplitude requirement is as follows:
 - This requirement is described in detail in the following sections.

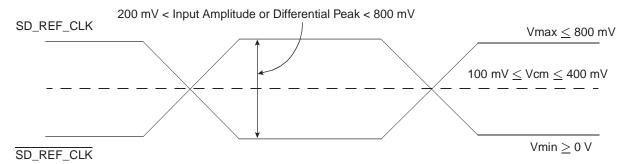
2.18.2.3 DC Level Requirement for SerDes Reference Clocks

The DC level requirement for the device SerDes reference clock inputs is different depending on the signaling mode used to connect the clock driver chip and SerDes reference clock inputs as described below:

Differential Mode

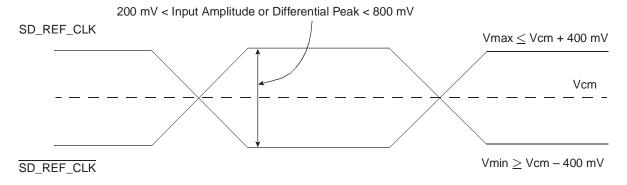
- The input amplitude of the differential clock must be between 400 mV and 1600 mV differential peak-peak (or between 200 mV and 800 mV differential peak). In other words, each signal wire of the differential pair must have a single-ended swing less than 800 mV and greater than 200 mV. This requirement is the same for both external DC-coupled or AC-coupled connection.
- For external DC-coupled connection, as described in Section 2.18.2.2 "SerDes Reference Clock Receiver Characteristics" on page 84, the maximum average current requirements sets the requirement for average voltage (common mode voltage) to be between 100 mV and 400 mV. Figure 2-46 shows the SerDes reference clock input requirement for DC-coupled connection scheme.

Figure 2-46. Differential Reference Clock Input DC Requirements (External DC-Coupled)



- For external AC-coupled connection, there is no common mode voltage requirement for the clock driver. Since the external AC-coupling capacitor blocks the DC level, the clock driver and the SerDes reference clock receiver operate in different command mode voltages. The SerDes reference clock receiver in this connection scheme has its common mode voltage set to SGND_SRDSn. Each signal wire of the differential inputs is allowed to swing below and above the command mode voltage (SGND_SRDSn). Figure 2-47 shows the SerDes reference clock input requirement for AC-coupled connection scheme.

Figure 2-47. Differential Reference Clock Input DC Requirements (External AC-Coupled)



Single-ended Mode

- The reference clock can also be single-ended. The SD_REF_CLK input amplitude (single-ended swing) must be between 400 mV and 800 mV peak-peak (from V_{MIN} to V_{MAX}) with SD_REF_CLK either left unconnected or tied to ground.
- The SD_REF_CLK input average voltage must be between 200 and 400 mV. Figure 2-48 shows the SerDes reference clock input requirement for single-ended signaling mode.
- To meet the input amplitude requirement, the reference clock inputs might need to be DC or AC-coupled externally. For the best noise performance, the reference of the clock could be DC or AC-coupled into the unused phase (SD_REF_CLK) through the same source impedance as the clock input (SD_REF_CLK) in use.

400 mV ≤ SD_REF_CLK Input Amplitude ≤ 800 mV SD_REF_CLK 0 V SD_REF_CLK

Figure 2-48. Single-Ended Reference Clock Input DC Requirements

2.18.3 **AC Requirements for PCI Express SerDes Reference Clocks**

Table 2-75 lists AC requirements for the PCI Express, SGMII, and SRIO SerDes reference clocks to be guaranteed by the customer's application design.

SD REF CLK and SD REF CLK Input Clock Requirements Table 2-75.

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|--|--|------|---------|------|------|-----------|
| SD_REF_CLK/ SD_REF_CLK frequency range | t _{CLK_REF} | _ | 100/125 | _ | MHz | (1) |
| SD_REF_CLK/ SD_REF_CLK clock frequency tolerance | t _{CLK_TOL} | -350 | _ | +350 | ppm | _ |
| SD_REF_CLK/ SD_REF_CLK reference clock duty cycle | t _{CLK_DUTY} | 40 | 50 | 60 | % | (7) |
| SD_REF_CLK/ SD_REF_CLK max deterministic peak-peak Jitter @ 10 ⁻⁶ BER | t _{CLK_DJ} | _ | _ | 42 | ps | (6) |
| SD_REF_CLK/ SD_REF_CLK total reference clock jitter @ 10 ⁻⁶ BER (Peak-to-peak jitter at refClk input) | t _{CLK_TJ} | - | - | 86 | ps | (2)(6) |
| SD_REF_CLK/SD_REF_CLK rising/falling edge rate | t _{CLKRR} /t _{CLKFR} | 1 | _ | 4 | V/ns | (3)(6) |
| Differential input high voltage | V _{IH} | 200 | _ | - | mV | (3) |
| Differential input low voltage | V _{IL} | _ | _ | -200 | mV | (3) |
| Rising edge rate (SDn_REF_CLK) to falling edge rate (SDn_REF_CLK) matching | Rise-Fall Matching | _ | _ | 20 | % | (4)(5)(6) |

- Notes: 1. Caution: Only 100 and 125 have been tested. In-between values do not work correctly with the rest of the system.
 - 2. Limits from PCI Express CEM Rev 2.0
 - 3. Measured from -200 mV to +200 mV on the differential waveform (derived from SD REF CLK minus SD REF CLK). The signal must be monotonic through the measurement region for rise and fall time. The 400 mV measurement window is centered on the differential zero crossing. See Figure 2-49.
 - 4. Measurement taken from single-ended waveform
 - 5. Matching applies to rising edge for SD_REF_CLK and falling edge rate for SD_REF_CLK. It is measured using a 200 mV window centered on the median cross point where SD_REF_CLK rising meets SD_REF_CLK falling. The median cross point is used to calculate the voltage thresholds that the oscilloscope uses for the edge rate calculations. The rise edge rate of SD_REF_CLK must be compared to the fall edge rate of SD_REF_CLK, the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 2-50.
 - 6. System/board must be designed to ensure the input requirement to the device is achieved. Proper device operation is guaranteed for inputs meeting this requirement by design, simulation, characterization, or functional testing.
 - 7. Measurement taken from the differential waveform.

Figure 2-49 shows the differential measurement points for rise and fall time.

Figure 2-49. Differential Measurement Points for Rise and Fall Time

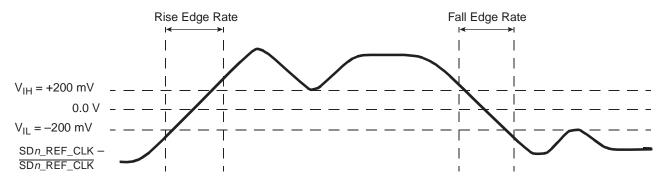
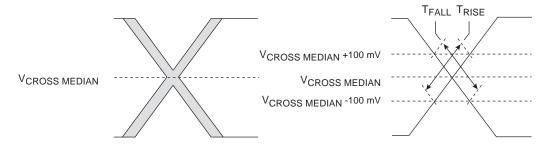


Figure 2-50 shows the single-ended measurement points for rise and fall time matching.

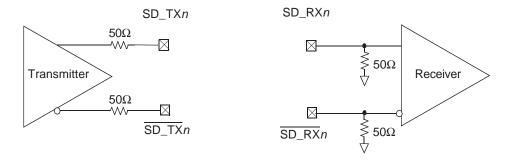
Figure 2-50. Single-Ended Measurement Points for Rise and Fall Time Matching



2.18.4 SerDes Transmitter and Receiver Reference Circuits

Figure 2-51 shows the reference circuits for SerDes data lane's transmitter and receiver.

Figure 2-51. SerDes Transmitter and Receiver Reference Circuits



The DC and AC specification of SerDes data lanes are defined in each interface protocol section below (PCI Express, Serial Rapid IO or SGMII) in this document based on the application usage:

- Section 2.10.3 "SGMII Interface Electrical Characteristics" on page 55
- Section 2.19 "PCI Express" on page 89
- Section 2.20 "Serial RapidIO (SRIO)" on page 92

Note that external AC Coupling capacitor is required for the above three serial transmission protocols per the protocol's standard requirements.

2.18.5 Clocking Dependencies

The ports on the two ends of a link must transmit data at a rate that is within 600 parts per million (ppm) of each other at all times. This is specified to allow bit rate clock sources with a ± 300 ppm tolerance.

2.19 PCI Express

This section describes the DC and AC electrical specifications for the PCI Express bus of the P2020.

2.19.1 PCI Express DC Requirements for SD_REF_CLK and SD_REF_CLK

For more information, see Section 2.18.2.3 "DC Level Requirement for SerDes Reference Clocks" on page 85.

2.19.2 PCI Express DC Physical Layer Specifications

This section contains the DC specifications for the physical layer of PCI Express on this device.

2.19.2.1 PCI Express DC Physical Layer Transmitter Specifications

Table 2-76 defines the PCI Express (2.5 Gb/s) DC specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins.

Table 2-76. PCI Express (2.5Gb/s) Differential Transmitter (TX) Output DC Specifications

| Parameter | Symbol | Min | Typical | Max | Units | Comments |
|--|--------------------------|-----|---------|------|-------|--|
| Differential Peak-to-Peak Output Voltage | V _{TX-DIFFp-p} | 800 | 1000 | 1200 | mV | $V_{TX-DIFFp-p} = 2 \div V_{TX-D} + -V_{TX-D} - $ See Note (1). |
| De-emphasized Differential Output Voltage (Ratio) | V _{TX-DE-RATIO} | 3.0 | 3.5 | 4.0 | dB | Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note $^{(1)}$. |
| DC Differential TX Impedance | Z _{TX-DIFF-DC} | 80 | 100 | 120 | Ω | TX DC Differential mode Low Impedance |
| Transmitter DC Impedance | Z _{TX-DC} | 40 | 50 | 60 | Ω | Required TX D+ as well as D– DC Impedance during all states |

Note: 1. Specified at the measurement point into a timing and voltage compliance test load as shown in Figure 2-52 and measured over any 250 consecutive Tx UIs.

Table 2-78 defines the PCI Express (2.5 Gb/s) AC specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins. The AC timing specifications do not include RefClk jitter.

2.19.2.2 PCI Express DC Physical Layer Receiver Specifications

Table 2-77 defines the DC specifications for the PCI Express (2.5 Gb/s) differential input at all receivers (RXs). The parameters are specified at the component pins.

Table 2-77. PCI Express (2.5 Gb/s) Differential Receiver (RX) Input DC Specifications

| Parameter | Symbol | Min | Typical | Max | Units | Comments | | |
|--|------------------------------|-----|---------|------|-------|---|--|--|
| Differential Input Peak-to-Peak Voltage | $V_{RX-DIFFp-p}$ | 175 | - | 1200 | mV | $V_{RX-DIFFp-p} = 2 \times V_{RX-D+} - V_{RX-D-} $ See Note ⁽¹⁾ . | | |
| DC Differential Input Impedance | Z _{RX-DIFF-DC} | 80 | 100 | 120 | Ω | RX DC Differential mode impedance. See Note (2) | | |
| DC Input Impedance | Z _{RX-DC} | 40 | 50 | 60 | Ω | Required RX D+ as well as D– DC Impedance (50 ± 20% tolerance). See Notes ⁽¹⁾ and ⁽²⁾ . | | |
| Powered Down DC Input Impedance | Z _{RX-HIGH-IMP-DC} | 50 | _ | _ | kΩ | Required RX D+ as well as D– DC Impedance when the Receiver terminations do not have power. See Note ⁽³⁾ . | | |
| Electrical Idle Detect Threshold | V _{RX-IDLE-DET-DIF} | 65 | _ | 175 | mV | $V_{\text{RX-IDLE-DET-DIFFp-p}}$ = 2 × $ V_{\text{RX-D+}} - V_{\text{RX-D-}} $ Measured at the package pins of the Receiver | | |

Notes:

- 1. Specified at the measurement point and measured over any 250 consecutive UIs. The test load in Figure 2-52 must be used as the Rx device when taking measurements. If the clocks to the Rx and Tx are not derived from the same reference clock, the Tx UI recovered from 3500 consecutive UI must be used as a reference for the eye diagram.
- 2. Impedance during all LTSSM states. When transitioning from a fundamental reset to detect (the initial state of the LTSSM) there is a 5 ms transition time before receiver termination values must be met on all unconfigured lanes of a port.
- 3. The Rx DC common mode impedance that exists when no power is present or fundamental reset is asserted. This helps ensure that the receiver detect circuit does not falsely assume a receiver is powered on when it is not. This term must be measured at 300 mV above the Rx ground.

2.19.3 PCI Express AC Physical Layer Specifications

This section contains the DC specifications for the physical layer of PCI Express on this device.

2.19.3.1 PCI Express AC Physical Layer Transmitter Specifications

This section discusses the PCI Express AC physical layer transmitter specification for 2.5 Gb/s.

Table 2-78 defines the PCI Express (2.5 Gb/s) AC specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins. The AC timing specifications do not include RefClk jitter.

Table 2-78. PCI Express (2.5Gb/s) Differential Transmitter (TX) Output AC Specifications

| Parameter | Symbol | Min | Typical | Max | Units | Comments |
|---|--|--------|---------|--------|-------|--|
| Unit Interval | UI | 399.88 | 400.00 | 400.12 | ps | Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations. See Note ⁽¹⁾ . |
| Minimum TX Eye Width | T _{TX-EYE} | 0.70 | - | - | UI | The maximum Transmitter jitter can be derived as $T_{TX\text{-MAX-JITTER}} = 1 - T_{TX\text{-EYE}} = 0.3 \text{ UI}.$ See Notes $^{(2)}$ and $^{(3)}$. |
| Maximum time between the jitter median and maximum deviation from the median. | T _{TX-EYE-MEDIAN-} to-MAX-JITTER | ı | - | 0.15 | UI | Jitter is defined as the measurement variation of the crossing points ($V_{TX-DIFFp-p} = 0V$) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes $^{(2)}$ and $^{(3)}$. |
| AC Coupling Capacitor | C_{TX} | 75 | _ | 200 | nF | All transmitters are AC coupled. The AC coupling is required either within the media or within the transmitting component itself. See Note ⁽⁴⁾ . |

Notes: 1. No test load is necessarily associated with this value.

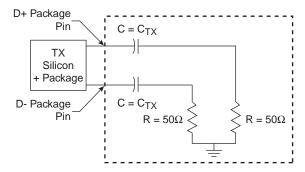
- Specified at the measurement point into a timing and voltage compliance test load as shown in Figure 2-52 and measured over any 250 consecutive Tx UIs.
- 3. A T_{TX-EYE} = 0.70 UI provides for a total sum of deterministic and random jitter budget of T_{TX-JITTER-MAX} = 0.30 UI for the Transmitter collected over any 250 consecutive Tx UIs. The T_{TX-EYE-MEDIAN-to-MAX-JITTER} median is less than half of the total Tx jitter budget collected over any 250 consecutive Tx UIs. It must be noted that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value.
- 4. P2020 SerDes transmitter does not have C_{TX} built-in. An external AC Coupling capacitor is required.

2.19.3.2 Test and Measurement Load

The AC timing and voltage parameters must be verified at the measurement point. The package pins of the device must be connected to the test/measurement load within 0.2 inches of that load, as shown in Figure 2-52.

Note: The allowance of the measurement point to be within 0.2 inches of the package pins is meant to acknowledge that package/board routing may benefit from D+ and D- not being exactly matched in length at the package pin boundary. If the vendor does not explicitly state where the measurement point is located, the measurement point is assumed to be the D+ and D- package pins.

Figure 2-52. Test/Measurement Load



2.19.3.3 PCI Express AC Physical Layer Receiver Specifications

This section discusses the PCI Express AC physical layer receiver specifications for 2.5 Gb/s.

Table 2-79 defines the AC specifications for the PCI Express (2.5 Gb/s) differential input at all receivers. The parameters are specified at the component pins. The AC timing specifications do not include RefClk jitter.

Table 2-79. PCI Express (2.5 Gb/s) Differential Receiver (RX) Input AC Specifications

| Parameter | Symbol | Min | Typical | Max | Units | Comments |
|---|---|--------|---------|--------|-------|--|
| Unit Interval | UI | 399.88 | 400.00 | 400.12 | ps | Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations. See Note ⁽¹⁾ . |
| Minimum Receiver Eye Width | T _{RX-EYE} | 0.4 | ı | - | UI | The maximum interconnect media and Transmitter jitter that can be tolerated by the Receiver can be derived as $T_{RX-MAX-JITTER} = 1 - T_{RX-EYE} = 0.6$ UI. See Notes $^{(2)}$ and $^{(3)}$. |
| Maximum time between the jitter median and maximum deviation from the median. | T _{RX-EYE-MEDIAN-to-MAX-} JITTER | - | - | 0.3 | UI | Jitter is defined as the measurement variation of the crossing points (V _{RX-DIFFp-p} = 0V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes ⁽²⁾ , ⁽³⁾ and ⁽⁴⁾ . |

Notes: 1. No test load is necessarily associated with this value.

- 2. Specified at the measurement point and measured over any 250 consecutive UIs. The test load in Figure 2-52 must be used as the Rx device when taking measurements. If the clocks to the Rx and Tx are not derived from the same reference clock, the Tx UI recovered from 3500 consecutive UI must be used as a reference for the eye diagram.
- 3. A T_{RX-EYE} = 0.40 UI provides for a total sum of 0.60 UI deterministic and random jitter budget for the Transmitter and interconnect collected any 250 consecutive UIs. The T_{RX-EYE-MEDIAN-to-MAX-JITTER} specification ensures a jitter distribution in which the median and the maximum deviation from the median is less than half of the total. UI jitter budget collected over any 250 consecutive Tx UIs. It must be noted that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value. If the clocks to the Rx and Tx are not derived from the same reference clock, the Tx UI recovered from 3500 consecutive UI must be used as the reference for the eye diagram.
- 4. It is recommended that the recovered Tx UI is calculated using all edges in the 3500 consecutive UI interval with a fit algorithm using a minimization merit function. Least squares and median deviation fits have worked well with experimental and simulated data.

2.20 Serial RapidIO (SRIO)

This section describes the DC and AC electrical specifications for the RapidIO interface for the LP-Serial physical layer. The electrical specifications cover both single and multiple-lane links. Two transmitters (short run and long run) and a single receiver are specified for each of three baud rates, 1.25, 2.50, and 3.125 GBaud.

Two transmitter specifications allow for solutions ranging from simple board-to-board interconnect to driving two connectors across a backplane. A single receiver specification is given that accepts signals from both the short run and long run transmitter specifications.

The short run transmitter must be used mainly for chip-to-chip connections on either the same printed circuit board or across a single connector. This covers the case where connections are made to a mezzanine (daughter) card. The minimum swings of the short run specification reduce the overall power used by the transceivers.

The long run transmitter specifications use larger voltage swings that are capable of driving signals across backplanes. This allows a user to drive signals across two connectors and a backplane. The specifications allow a distance of at least 50 cm at all baud rates.

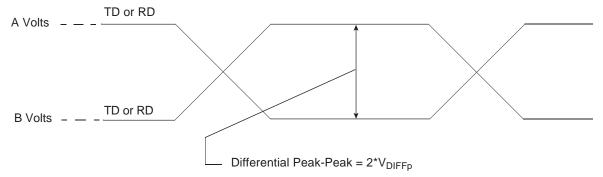
All unit intervals are specified with a tolerance of ±100 ppm. The worst case frequency difference between any transmit and receive clock is 200 ppm.

2.20.1 Signal Definitions

To ensure interoperability between drivers and receivers of different vendors and technologies, AC coupling at the receiver input must be used.

LP-Serial links use differential signaling. This section defines terms used in the description and specification of differential signals. Figure 2-53 shows how the signals are defined. The figures show waveforms for either a transmitter output (TD and $\overline{\text{TD}}$) or a receiver input (RD and $\overline{\text{RD}}$). Each signal swings between A Volts and B Volts where A > B.

Figure 2-53. Differential Peak-Peak Voltage of Transmitter or Receiver



Using these waveforms, the definitions are as follows:

- The transmitter output signals and the receiver input signals TD, $\overline{\text{TD}}$, RD and $\overline{\text{RD}}$ each have a peak-to-peak swing of A B Volts.
- The differential output signal of the transmitter, V_{OD} , is defined as $V_{TD} V_{\overline{TD}}$
- The differential input signal of the receiver, V_{ID} , is defined as $V_{RD} V_{\overline{RD}}$
- The differential output signal of the transmitter and the differential input signal of the receiver each range from A B to –(A B) Volts
- The peak value of the differential transmitter output signal and the differential receiver input signal is A –B Volts.
- The peak-to-peak value of the differential transmitter output signal and the differential receiver input signal is 2 × (A B) Volts.

To illustrate these definitions using real values, consider the case of a CML (Current Mode Logic) transmitter that has a common mode voltage of 2.25V and each of its outputs, TD and $\overline{\text{TD}}$, has a swing that goes between 2.5V and 2.0V. Using these values, the peak-to-peak voltage swing of the signals TD and $\overline{\text{TD}}$ is 500 mV p-p. The differential output signal ranges between 500 mV and -500 mV. The peak differential voltage is 500 mV. The peak-to-peak differential voltage is 1000 mV p-p.

2.20.2 Equalization

With the use of high speed serial links, the interconnect media causes degradation of the signal at the receiver. Effects such as Inter-Symbol Interference (ISI) or data dependent jitter are produced. This loss can be large enough to degrade the eye opening at the receiver beyond what is allowed in the specification. To negate a portion of these effects, equalization can be used. The most common equalization techniques that can be used are as follows:

- · Pre-emphasis on the transmitter
- A passive high pass filter network placed at the receiver. This is often referred to as passive equalization.
- The use of active circuits in the receiver. This is often referred to as adaptive equalization.

2.20.3 DC Requirements for Serial RapidIO

This section explains the DC requirements for the Serial RapidIO interface.

2.20.3.1 DC Requirements for Serial RapidIO SD_REF_CLK and SD_REF_CLK

The characteristics and DC requirements of the separate SerDes reference clocks of the Serial RapidIO interface are described in Section 2.18.2.3 "DC Level Requirement for SerDes Reference Clocks" on page 85.

2.20.4 DC Serial RapidIO Timing Transmitter Specifications

LP-Serial transmitter electrical and timing specifications are stated in the text and tables of this section.

The differential return loss, S11, of the transmitter in each case is better than

- -10 dB for (Baud Frequency)/10 < Freq(f) < 625 MHz, and
- -10 dB + 10log(f/625 MHz) dB for 625 MHz ≤ Freq(f) ≤ Baud Frequency

The reference impedance for the differential return loss measurements is 100Ω resistive. Differential return loss includes contributions from on-chip circuitry, chip packaging and any off-chip components related to the driver. The output impedance requirement applies to all valid output levels.

It is recommended that the 20%–80% rise/fall time of the transmitter, as measured at the transmitter output, have a minimum value 60 ps in each case.

It is recommended that the timing skew at the output of an LP-Serial transmitter between the two signals that comprise a differential pair not exceed 25 ps at 1.25 GBaud, 20 ps at 2.50 GBaud and 15 ps at 3.125 GBaud.

Table 2-80 defines the Transmitter DC specifications for the Serial RapidIO interface.

Table 2-80. SRIO Transmitter DC Timing Specifications: 1.25 GBaud, 2.5 GBaud, 3.125 GBaud

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|---------------------------------------|---------------------|-------|---------|------|--------|-------|
| Output Voltage, | Vo | -0.40 | _ | 2.30 | V | (1) |
| Long Run Differential Output Voltage | V _{DIFFPP} | 800 | - | 1600 | mV p-p | _ |
| Short Run Differential Output Voltage | V _{DIFFPP} | 500 | _ | 1000 | mV p-p | _ |

Note: 1. Voltage relative to COMMON of either signal comprising a differential pair.

2.20.5 DC Serial RapidIO Receiver Specifications

LP-Serial receiver electrical and timing specifications are stated in the text and tables of this section.

Receiver input impedance results in a differential return loss better that 10 dB and a common mode return loss better than 6 dB from 100 MHz to $(0.8) \times (Baud Frequency)$. This includes contributions from on-chip circuitry, the chip package and any off-chip components related to the receiver. AC coupling components are included in this requirement. The reference impedance for return loss measurements is 100Ω resistive for differential return loss and 25Ω resistive for common mode.

Table 2-81 defines the Receiver DC specifications for the Serial RapidIO interface.

Table 2-81. SRIO Receiver DC Timing Specifications: 1.25 GBaud, 2.5 GBaud, 3.125 GBaud

| Characteristic | Symbol | Min | Typical | Max | Unit | Notes |
|----------------------------|----------|-----|---------|------|--------|----------------------|
| Differential Input Voltage | V_{IN} | 200 | _ | 1600 | mV p-p | Measured at receiver |

2.20.6 AC Requirements for Serial RapidIO

This section explains the AC requirements for the Serial RapidIO interface.

2.20.6.1 AC Requirements for Serial RapidIO SD_REF_CLK and SD_REF_CLK

Please note that the Serial RapidIO clock requirements for SD_REF_CLK and SD_REF_CLK are intended to be used within the clocking guidelines specified by Section 2.18.3 "AC Requirements for PCI Express SerDes Reference Clocks" on page 87.

2.20.6.2 AC Requirements for Serial RapidIO Transmitter and Receiver

Table 2-82 defines the transmitter AC specifications for the Serial RapidIO interface. The AC timing specifications do not include RefClk jitter.

Table 2-82. SRIO Transmitter AC Timing Specifications

| Parameter | Symbol | Min | Typical | Max | Unit |
|----------------------------|--------|------------|---------|--------------|--------|
| Deterministic Jitter | J_D | - | _ | 0.17 | UI p-p |
| Total Jitter | J_T | - | _ | 0.35 | UI p-p |
| Unit Interval: 1.25 GBaud | UI | 800–100ppm | 800 | 800 + 100ppm | ps |
| Unit Interval: 2.5 GBaud | UI | 400–100ppm | 400 | 400 + 100ppm | ps |
| Unit Interval: 3.125 GBaud | UI | 320–100ppm | 320 | 320 + 100ppm | ps |

Table 2-83 defines the receiver AC specifications for the Serial RapidIO interface. The AC timing specifications do not include RefClk jitter.

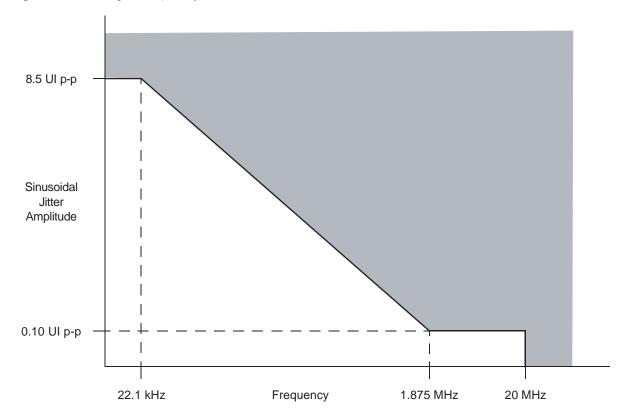
Table 2-83. SRIO Receiver AC Timing Specifications

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|--|----------|------------|---------|-------------------|--------|----------------------|
| Deterministic Jitter Tolerance | J_{D} | 0.37 | _ | 1 | UI p-p | Measured at receiver |
| Combined Deterministic and Random Jitter Tolerance | J_{DR} | 0.55 | _ | _ | UI p-p | Measured at receiver |
| Total Jitter Tolerance ⁽¹⁾ | J_{T} | 0.65 | _ | _ | UI p-p | Measured at receiver |
| Bit Error Rate | BER | _ | _ | 10 ⁻¹² | - | _ |
| Unit Interval: 1.25 GBaud | UI | 800–100ppm | 800 | 800+100ppm | ps | _ |
| Unit Interval: 2.5 GBaud | UI | 400–100ppm | 400 | 400+100ppm | ps | _ |
| Unit Interval: 3.125 GBaud | UI | 320–100ppm | 320 | 320+100ppm | ps | _ |

Note: 1. Total jitter is composed of three components: deterministic jitter, random jitter, and single frequency sinusoidal jitter. The sinusoidal jitter may have any amplitude and frequency in the unshaded region of Figure 2-54. The sinusoidal jitter component is included to ensure margin for low frequency jitter, wander, noise, crosstalk and other variable system effects.

Figure 2-54 shows the single frequency sinusoidal jitter limits.

Figure 2-54. Single Frequency Sinusoidal Jitter Limits



3. **Thermal**

This section describes the thermal specifications of the device.

3.1 **Thermal Characteristics**

Table 3-1 provides the package thermal characteristics.

Table 3-1. Package Thermal Characteristics

| Characteristic | JEDEC Board | Symbol | Value | Unit | Notes |
|---|-------------------------|-----------------|-------|------|--------|
| Junction-to-ambient Natural Convection | Single layer board (1s) | $R_{	hetaJA}$ | 21 | °C/W | (1)(2) |
| Junction-to-ambient Natural Convection | Four layer board (2s2p) | $R_{	heta JA}$ | 14 | °C/W | (1)(2) |
| Junction-to-ambient (at 200 ft/min) | Single layer board (1s) | $R_{\theta JA}$ | 16 | °C/W | (1)(2) |
| Junction-to-ambient (at 200 ft/min) | Four layer board (2s2p) | $R_{\theta JA}$ | 12 | °C/W | (1)(2) |
| Junction-to-board thermal | _ | $R_{\theta JB}$ | 7 | °C/W | (3) |
| Junction-to-case thermal (Top) | _ | $R_{	heta JC}$ | 5 | °C/W | (4) |

- Notes: 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
 - 2. Per JEDEC JESD51-2 and JESD51-6 with the board (JESD51-9) horizontal.
 - 3. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
 - 4. Junction-to-case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer.

3.2 **Temperature Diode**

The device has a temperature diode on the microprocessor that can be used in conjunction with other system temperature monitoring devices (such as Analog Devices, ADT7461[™]). These devices use the negative temperature coefficient of a diode operated at a constant current to determine the temperature of the microprocessor and its environment.

The following are the specifications of the P2020 on-board temperature diode:

Operating range: 10 - 230 µA

Ideality factor over $13.5 - 220 \mu A$; n = 1.011 ± 0.008

4. Package Information

This section provides the package parameters and ordering information.

4.1 Package Parameters for the P2020 WB-TePBGA

The package parameters are provided in the following list. The package type is 31 mm × 31 mm, 689 plastic ball grid array (WB-TePBGA).

Package outline 31 mm × 31 mm

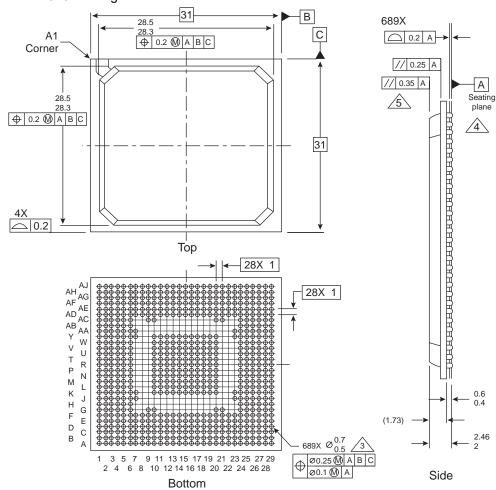
Interconnects 689
Pitch 1.00 mm

Module height (typical) 2.0 mm to 2.46 mm (Maximum)

Solder Balls (RoHs, package type =2) 3.5% Ag, 96.5% Sn Solder Balls (SnPb, package type =4) 63% Sn, 37% Pb

Ball diameter (typical) 0.60 mm

Figure 4-1. P2020 Package



Notes: 1. All dimensions are in millimeters.

- 2. Dimensioning and tolerancing per ASME Y14. 5M-1994.
- 3. Maximum solder ball diameter measured parallel to Datum A.
- 4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
- 5. Parallelism measurement excludes any effect of mark on top surface of package.

4.2 Ordering Information

Table 4-1 provides the e2v part numbering nomenclature for the P2020. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local e2v sales office. Each part number also contains a revision code which refers to the die mask revision number.

Table 4-1. Ordering Information

| р | 2 | 02 or 01 | 0 | У | е | n | С | d | r |
|-----------------------------|----------|---|------------|--------------------------|--|--------------------------------------|---|----------------------------------|-----------------|
| Generation ⁽¹⁾ | Platform | Number of Cores | Derivative | Temperatur e Range | Encryption | Package Type | CPU Frequency | DDR Speed | Die Revision |
| P(X) ⁽²⁾ = 45 nm | 2 | 01 = Single core 02 = Dual core | 0 - 9 | F: -40/125 M: -55/125 | E = SEC Present N = SEC Not Present | 4 = TEPBGA2 Pb 2 = TEPBGA2 Pb free | H = 800 MHz K = 1000 MHz M = 1200 MHz N = 1333 MHZ | F = 667 MHz H = 800 MHz | C = 2.1 |

Notes: 1. For availability of the different versions, contact your local e2v sales office.

- 2. The letter X in the part number designates a "Prototype" product that has not been qualified by e2v. Reliability of a PCX part-number is not guaranteed and such part-number shall not be used in Flight Hardware. Product changes may still occur while shipping prototypes.
- 3. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by part number specifications may support other maximum core frequencies.

5. Definitions

5.1 Life Support Applications

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. e2v customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify e2v for any damages resulting from such improper use or sale.

6. Document Revision History

Table 6-1 provides a revision history for the P2020 hardware specification.

 Table 6-1.
 Document Revision History

| Rev. No | Date | Substantive Change(s) |
|---------|---------|---|
| 1073D | 11/2019 | In Table 1-1, note 15, changed "USB1_STP" to "USB_STP". In Table 2-9, updated the high-level input voltage min and the low-level input voltage max and added "RGMII, GMII at LV_{DD} = 2.5V" to the title. Added Table 2-10 for GMII LV_{DD} = 3.3V. In Table 2-11, added the frequency min and max formulas and added a row with jitter data. |
| 1073C | 04/2014 | In the features list, removed "Operating Junction Temperature (Tj) Range: -40°C/125°C (Industrial Specification) and -55°C/125°C (Military Specification)" bullet point. In the features list, changed the 36-bit physical addressing clock frequency from 1.2 GHz to 1.33 GHz. In Table 1-1, added overbar to the signal TEST_SEL. In Table 2-2, modified the recommended value for DDR2 and DDR3 DRAM reference inputbvoltages. In Table 2-4, added rows for core frequency = 1333. In Table 2-17 and Table 2-18, updated footnote 2. In Table 4-1, added CPU frequency N = 1333. |
| 1073B | 03/2012 | • In Table 1-1, updated the text corresponding to footnote 16 from: "WheneTSEC1 and eTSEC2 are used as parallel interfaces, pins TSEC1_TX_EN and TSEC2_TX_EN require an external 4.7-kΩ pull-down resistor to prevent PHY from seeing a valid Transmit Enable before it is actively driven. TSEC2_TXD[05] is a POR configuration pin for eSDHC card-detect (cfg_sdhc_cd_pol_sel) and also has an alternate function as TSEC3_TX_EN. When using eTSEC3 as a parallel interface, the TSEC3_TX_EN requires a pull down. However, because the pull-down resistor on TSEC2_TXD[05]/TSEC3_TX_EN signal causes the eSDHC card-detect (cfg_sdhc_cd_pol_sel) to be inverted, the inversion must be overridden from the SDHCDCR [CD_INV] debug control register." to: "TSEC2_TXD[05] is a POR configuration pin for eSDHC card-detect (cfg_sdhc_cd_pol_sel), and it also has an alternate function of TSEC3_TX_EN. When eTSEC1 or eTSEC2 or eTSEC3 are used as parallel interfaces, the TSECx_TX_EN pins require an external 4.7-k pull-down resistor to prevent PHY from seeing a valid Transmit Enable before it is actively driven. However, the pull-down resistor on TSEC3_TX_EN causes the eSDHC card-detect (cfg_sdhc_cd_sel) to be inverted; the inversion should be overridden from the SDHCDCR[CD_INV] debug control register. If the device is configured to boot from the eSDHC interface, the SDHC_CD should be inverted on the board." |
| | | • In Table 2-1, for DDR2/DDR3 DRAM signals and reference rows, updated the value in the "Maximum" column from "-0.3 to (GV _{DD} + 0.3)" to "-0.3 to (GV _{DD} + 0.3)" and "-0.3 to (GV _{DD} /2 + 0.3)," respectively. • In Table 2-1, for the SerDes row, updated the value in the "Maximum" column from "-0.3 to (OV _{DD} + 0.3)" to "-0.3 to (XV _{DD} + 0.3)." • In Table 2-5, added "RMII" to the "Parameters" column for the eTSEC row that corresponds to LV _{DD} (2.5V), and added "MII, GMII, TBI, RMII, and 1588" to the "Parameters" column for the eTSEC row that corresponds to LV _{DD} (3.3V). • In Section 2.10.1.1 "GMII, MII, TBI, RGMII, RMII, and RTBI DC Electrical Characteristics" on page 46, Table 2-31 on page 46 and Table 2-32, added "IEEE 1588" to the cell containing the "Input high voltage" parameter. • In Table 2-31, added "IEEE 1588" to the cell containing the "Input high voltage" parameter. • In Table 2-42, updated the parameter "RXD[1:0], CRS_DV, RX_ER setup time to TSECn_RX_CLK rising edge" to "RXD[1:0], CRS_DV, RX_ER setup time to TSECn_RX_CLK rising edge." • In Figure 2-20, changed "TSECn_RX_CLK" to "TSECn_TX_CLK." • In Table 2-58, in the "Parameters" column, changed "Low-level output voltage (BV _{DD} = min, I _{OH} = -0.5 mA)" to "Low-level output voltage (BV _{DD} = min, I _{OH} = 0.5 mA)." • In Table 2-61, changed the minimum value of parameter "Input leakage current" from "-40" to "-70." • In Figure 2-36, changed "tHSIVKH" to "t _{SHSIVKH} " and changed "t _{HSIXKH} " to "t _{SHSIXKH} ." • In Table 2-66, changed parameter "JTAG external clock pulse width measured at 1.4V" to "JTAG external clock pulse width measured at 0V _{DD} /2." |

 Table 6-1.
 Document Revision History (Continued)

| Rev. No | Date | Substantive Change(s) |
|---------|---------|--|
| | | • In Figure 2-75, removed "(Measure at 1.6V)" from parameter "SD_REF_CLK/SD_REF_CLK reference clock duty cycle." |
| | | In Figure 2-53, changed "Differential Peak-Peak = 2 R× (A,Ä" to "Differential Peak-Peak = 2*VDIFFp." In Section 2.2 "Power Sequencing" on page 28, added the following warning: "Only 100,000 POR cycles are permitted per lifetime of a device." |
| | | In Table 2-45, updated the minimum value for the AC coupling capacitor parameter from 5 to 10. In Table 2-42, removed note from "TSECn TX CLK (reference clock) clock period" row. |
| | | In Table 2-58, changed parameter from "Low-level output voltage (BV_{DD} = min, I_{OH} = 0.5 mA)" to "Low-level output voltage (BV_{DD} = min, I_{OL} = 0.5 mA)." |
| | | In Figure 2-36, updated text from "VM = Midpoint Voltage (OV_{DD}/2)" to "VM = Midpoint Voltage (CV_{DD}/2)." In Figure 2-35, updated the text from "VM = Midpoint Voltage (OV_{DD}/2)" to "VM = Midpoint Voltage (CV_{DD}/2)." |
| 1073A | 09/2011 | Initial revision |

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